

## TPS65094 Intel™ Apollo Lake プラットフォーム用 PMIC

### 1 特長

- 5.6V～21V の広い  $V_{IN}$  範囲
- D-CAP2™ トポロジを採用した 3 つの可変出力電圧同期整流降圧型コントローラ
  - 一般的なアプリケーションの場合、外部 FET を使用して BUCK1 (VNN) で 5A、BUCK6 (VDDQ) で 7A、BUCK2 (VCCGI) で 21A
  - BUCK1、BUCK2 の  $I^2C$  動的電圧スケールリング (DVS) 制御 (10mV 刻みで 0.5V～1.45V)
  - BUCK6 (VDDQ) のデフォルト出力電圧を OTP でプログラム可能
- 出力電圧可変の 3 つの同期整流降圧型コンバータ (DCS-Control トポロジ使用および  $I^2C$  DVS 機能搭載)
  - $V_{IN}$  範囲: 4.5V～5.5V
  - BUCK3 (VCCRAM) で 3A の出力電流
  - 一般的なアプリケーションの場合、BUCK4 (V1P8A) と BUCK5 (V1P24A) で 2A の出力電流
- 出力電圧可変の 3 つの LDO レギュレータ
  - LDOA1:  $I^2C$  により、出力電圧を 1.35V～3.3V の範囲で選択可能、最大出力電流 200mA
  - LDOA2 および LDOA3:  $I^2C$  により、出力電圧を 0.7V～1.5V の範囲で選択可能、最大出力電流 600mA
- DDR メモリ終端用の VTT LDO
- スルー レート制御付きの 3 つの負荷スイッチ
  - 最大 400mA の出力電流、電圧降下は公称入力電圧の 1.5% 未満
  - 入力電圧 1.8V において  $R_{DS(on)} < 96m\Omega$
- $I^2C$  インターフェイス (デバイス アドレス 0x5E) により次のモードをサポート
  - Standard mode (100 kHz)
  - Fast mode (400kHz)
  - Fast mode plus (1 MHz)

### 2 アプリケーション

- 2、3、4 直列セルのリチウムイオン バッテリ駆動製品 (NVDC または非 NVDC)
- 壁面電源を使用する設計、特に 12V 電源を使用する場合
- タブレット、ウルトラブック™、ノートブック コンピュータ
- モバイル PC およびモバイル インターネット デバイス

### 3 概要

TPS65094 デバイスは、特に最新の Intel™ プロセッサ向けに設計されたシングル チップ ソリューションのパワー マネージメント IC (PMIC) であり、2S、3S、4S のリチウムイオン バッテリ パック (NVDC または非 NVDC 電源アーキテクチャ) を使用するタブレット、Ultrabook、ノート PC、産業用 PC、モノのインターネット (IOT) アプリケーションや、壁面電源を使用するアプリケーションを対象としています。TPS65094 デバイスは、最小フットプリント、最低コストのシステム電源ソリューション向けに低電圧レールを統合した基本的なシステムに使用されます。TPS65094 デバイスは、Intel のリファレンス デザインを基礎として、完全な電源ソリューションを提供します。6 つの高効率降圧型レギュレータ (VR)、1 つのシンクまたはソース LDO (VTT)、1 つの負荷スイッチを電源オン シーケンス ロジックで制御し、DDR3 および DDR4 メモリの電源も含めて、適切な電源レール、シーケンシング、保護を実現します。最大限の効率を得るため、2 つのレギュレータ (BUCK1 および BUCK2) は動的電圧スケールリング (DVS) をサポートしています (接続スタンバイもサポートしています)。高周波数 VR は、小さなインダクタとコンデンサを使用できるため、ソリューションを小型化できます。 $I^2C$  インターフェイスにより、組み込みコントローラ (EC) またはシステム オン チップ (SoC) を使用して簡単に制御できます。

この PMIC は、8mm × 8mm、単一列の VQFN パッケージで供給され、放熱特性改善と基板配線の簡略化のためにサーマル パッドが付属します。

#### 製品情報

| 部品番号     | パッケージ (1) | 本体サイズ (公称)      |
|----------|-----------|-----------------|
| TPS65094 | VQFN (64) | 8.00mm × 8.00mm |

- (1) 利用可能なすべてのパッケージについては、データシートの末尾にある注文情報を参照してください。



## Table of Contents

|  |           |  |           |
|--|-----------|--|-----------|
| <b>1 特長</b> .....  | <b>1</b>  | 6.15 Switching Characteristics.....                              | <b>22</b> |
| <b>2 アプリケーション</b> .....  | <b>1</b>  | 6.16 Typical Characteristics.....                                | <b>23</b> |
| <b>3 概要</b> .....  | <b>1</b>  | <b>7 Detailed Description</b> .....                              | <b>25</b> |
| <b>4 Device Options</b> .....  | <b>3</b>  | 7.1 Overview.....  | <b>25</b> |
| 4.1 OTP Comparison.....  | <b>3</b>  | 7.2 Functional Block Diagram.....                                | <b>26</b> |
| <b>5 Pin Configuration and Functions</b> .....   | <b>4</b>  | 7.3 Feature Description.....                                     | <b>28</b> |
| <b>6 Specifications</b> .....  | <b>8</b>  | 7.4 Device Functional Modes.....                                 | <b>43</b> |
| 6.1 Absolute Maximum Ratings.....  | <b>8</b>  | 7.5 Programming.....   | <b>44</b> |
| 6.2 ESD Ratings.....   | <b>8</b>  | 7.6 Register Maps.....   | <b>48</b> |
| 6.3 Recommended Operating Conditions.....  | <b>8</b>  | <b>8 Application and Implementation</b> .....                    | <b>69</b> |
| 6.4 Thermal Information.....   | <b>9</b>  | 8.1 Typical Application.....                                     | <b>69</b> |
| 6.5 Electrical Characteristics: Total Current Consumption.....                                     | <b>9</b>  | 8.2 Specific Application for TPS650944.....                      | <b>77</b> |
| 6.6 Electrical Characteristics: Reference and Monitoring System.....                               | <b>9</b>  | 8.3 Dos and Don'ts.....  | <b>77</b> |
| 6.7 Electrical Characteristics: Buck Controllers.....  | <b>10</b> | 8.4 Power Supply Recommendations.....                            | <b>77</b> |
| 6.8 Electrical Characteristics: Synchronous Buck Converters.....                                   | <b>14</b> | 8.5 Layout.....  | <b>78</b> |
| 6.9 Electrical Characteristics: LDOs.....  | <b>17</b> | <b>9 Device and Documentation Support</b> .....                  | <b>79</b> |
| 6.10 Electrical Characteristics: Load Switches.....  | <b>20</b> | 9.1 Device Support.....  | <b>79</b> |
| 6.11 Digital Signals: I <sup>2</sup> C Interface.....  | <b>21</b> | 9.2 Documentation Support.....                                   | <b>79</b> |
| 6.12 Digital Input Signals (LDOLS_EN, SWA1_EN, THERMTRIPB, PMICEN, SLP_S3B, SLP_S4B, SLP_S0B)..... | <b>22</b> | 9.3 ドキュメントの更新通知を受け取る方法.....                                      | <b>79</b> |
| 6.13 Digital Output Signals (IRQB, RSMRSTB, PCH_PWROK, PROCHOT).....                               | <b>22</b> | 9.4 サポート・リソース.....   | <b>79</b> |
| 6.14 Timing Requirements.....  | <b>22</b> | 9.5 Trademarks.....  | <b>79</b> |
|  |           | 9.6 静電気放電に関する注意事項.....   | <b>79</b> |
|  |           | 9.7 用語集.....   | <b>79</b> |
|  |           | <b>10 Revision History</b> .....                                 | <b>79</b> |
|  |           | <b>11 Mechanical, Packaging, and Orderable Information</b> ..... | <b>81</b> |

## 4 Device Options

### 4.1 OTP Comparison

表 4-1 summarizes the differences between the various TPS65094x family OTPs.

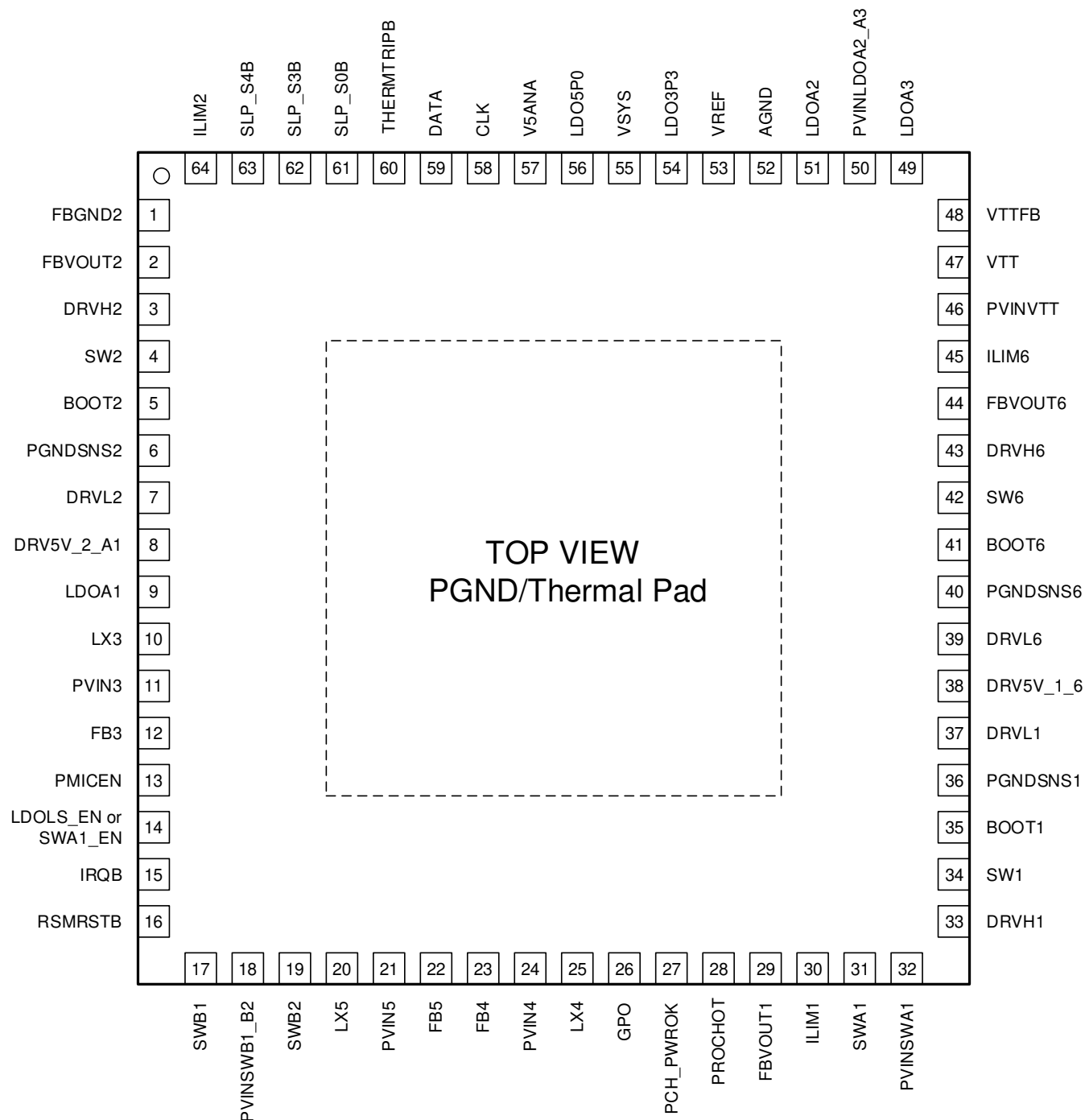
**表 4-1. Summary of TPS65094x OTP Differences**

|                                      | TPS650940 | TPS650941 | TPS650942 | TPS650944 | TPS650945  | TPS650947  |
|--------------------------------------|-----------|-----------|-----------|-----------|------------|------------|
| DDR                                  | LPDDR4    | LPDDR3    | DDR3L     | LPDDR4    | LPDDR4     | DDR3L      |
| BUCK6 Voltage                        | 1.1 V     | 1.2 V     | 1.35 V    | 1.1 V     | 1.1 V      | 1.35 V     |
| VTT Disabled                         | Yes       | No        | No        | Yes       | Yes        | No         |
| VTT I <sub>OC</sub> P (minimum)      | 0.95 A    | 0.95 A    | 1.8 A     | 1.8 A     | 0.95 A     | 1.8 A      |
| SWB1_2 controlled by SLP_S4B (V1P8U) | Yes       | Yes       | No        | Yes       | Yes        | No         |
| SWB1_2 controlled by SLP_S3B         | No        | No        | Yes       | No        | No         | Yes        |
| Pin 14 Usage                         | LDOLS_EN  | LDOLS_EN  | LDOLS_EN  | SWA1_EN   | LDOLS_EN   | LDOLS_EN   |
| LDOA1 Always On                      | No        | No        | No        | Yes       | No         | No         |
| LDOA1 Default Voltage                | 3.3 V     | 3.3 V     | 3.3 V     | 1.8 V     | 3.3 V      | 3.3 V      |
| LDOA2 Default Voltage                | 1.2 V     | 1.2 V     | 1.2 V     | 0.7 V     | 1.2 V      | 1.2 V      |
| LDOA3 Default Voltage                | 1.25 V    | 1.25 V    | 1.25 V    | 0.7 V     | 1.25 V     | 1.25 V     |
| PMICEN Low Forces Reset              | Yes       | Yes       | Yes       | No        | Yes        | Yes        |
| DEVICEID Register                    | 8h        | 29h       | 1Ah       | Ch        | Dh         | Fh         |
| BUCK3-5 Mode                         | Auto      | Auto      | Auto      | Auto      | Forced PWM | Forced PWM |

#### 注

Using OTP parts *TPS650945* & *TPS650947* with Forced PWM mode for Bucks 3-5 is strongly recommended to avoid abnormal frequency switching and minimize noise at light loads . Voltage undershoot or overshoot may be observed when operating with light load in Auto mode, and can lead to shutdown.

## 5 Pin Configuration and Functions



The thermal pad must be connected to the system power ground plane.

**RSK Package 64-Pin VQFN With Thermal Pad Top View**

**表 5-1. Pin Functions**

| PIN             |            | I/O | SUPPLY, OP<br>VOLTAGE<br>LEVEL | DESCRIPTION   |
|-----------------|------------|-----|--------------------------------|---|
| NO.             | NAME       |     |                                |   |
| SMPS REGULATORS |            |     |                                |   |
| 1               | FBGND2     | I   |                                | Remote negative feedback sense for BUCK2 controller. Connect to VCCGI VSS SENSE sent from the SoC to the PMIC.                          |
| 2               | FBVOUT2    | I   |                                | Remote positive feedback sense for BUCK2 controller. Connect to VCCGI VCC SENSE sent from the SoC to the PMIC.                          |
| 3               | DRVH2      | O   | VSYS + 5 V                     | High-side gate driver output for BUCK2 controller   |
| 4               | SW2        | I   |                                | Switch node connection for BUCK2 controller   |
| 5               | BOOT2      | I   | VSYS + 5 V                     | Bootstrap pin for BUCK2 controller. Connect a 100-nF ceramic capacitor between this pin and SW2 pin.                                    |
| 6               | PGNDSNS2   | I   |                                | Power GND connection for BUCK2. Connect to ground terminal of external low-side FET.  |
| 7               | DRVL2      | O   | 5 V                            | Low-side gate driver output for BUCK2 controller  |
| 8               | DRV5V_2_A1 | I   | 5 V                            | 5-V supply to BUCK2 gate driver and LDOA1. Bypass to ground with a 2.2-μF (typical) ceramic capacitor. Shorted on board to LDO5P0 pin.  |
| 10              | LX3        | O   |                                | Switch node connection for BUCK3 converter. Connect to a 0.47-μH (typical) inductor with less than 50-mΩ DCR.                           |
| 11              | PVIN3      | I   | 5 V                            | Power input to BUCK3 converter. Bypass to ground with a 10-μF (typical) ceramic capacitor.  |
| 12              | FB3        | I   |                                | Remote feedback sense for BUCK3 converter. Connect to positive terminal of output capacitor.  |
| 20              | LX5        | O   |                                | Switch node connection for BUCK5 converter. Connect to a 0.47-μH (typical) inductor with less than 50-mΩ DCR.                           |
| 21              | PVIN5      | I   | 5 V                            | Power input to BUCK5 converter. Bypass to ground with a 10-μF (typical) ceramic capacitor.  |
| 22              | FB5        | I   |                                | Remote feedback sense for BUCK5 converter. Connect to positive terminal of output capacitor.  |
| 23              | FB4        | I   |                                | Remote feedback sense for BUCK4 converter. Connect to positive terminal of output capacitor.  |
| 24              | PVIN4      | I   | 5 V                            | Power input to BUCK4 converter. Bypass to ground with a 10-μF (typical) ceramic capacitor.  |
| 25              | LX4        | O   |                                | Switch node connection for BUCK4 converter. Connect to a 0.47-μH (typical) inductor with less than 50-mΩ DCR.                           |
| 29              | FBVOUT1    | I   |                                | Remote feedback sense for BUCK1 controller. Connect to VNN VCC SENSE sent from the SoC to the PMIC.                                     |
| 30              | ILIM1      | I   |                                | Current limit set pin for BUCK1 controller. Fit a resistor from this pin to ground to set current limit of external low-side FET.       |
| 33              | DRVH1      | O   | VSYS + 5 V                     | High-side gate driver output for BUCK1 controller   |
| 34              | SW1        | I   |                                | Switch node connection for BUCK1 controller   |
| 35              | BOOT1      | I   | VSYS + 5 V                     | Bootstrap pin for BUCK1 controller. Connect a 100-nF ceramic capacitor between this pin and SW1 pin.                                    |
| 36              | PGNDSNS1   | I   |                                | Power GND connection for BUCK1. Connect to ground terminal of external low-side FET.  |
| 37              | DRVL1      | O   | 5 V                            | Low-side gate driver output for BUCK1 controller  |
| 38              | DRV5V_1_6  | I   | 5 V                            | 5-V supply to BUCK1 and BUCK6 gate drivers. Bypass to ground with a 2.2-μF (typical) ceramic capacitor. Shorted on board to LDO5P0 pin. |
| 39              | DRVL6      | O   | 5 V                            | Low-side gate driver output for BUCK6 controller  |
| 40              | PGNDSNS6   | I   |                                | Power GND connection for BUCK6. Connect to ground terminal of external low-side FET.  |
| 41              | BOOT6      | I   | VSYS + 5 V                     | Bootstrap pin for BUCK6 controller. Connect a 100-nF ceramic capacitor between this pin and SW6 pin.                                    |

表 5-1. Pin Functions (続き)

| PIN                          |              | I/O | SUPPLY, OP<br>VOLTAGE<br>LEVEL  | DESCRIPTION  |
|------------------------------|--------------|-----|---------------------------------|--|
| NO.                          | NAME         |     |                                 |  |
| 42                           | SW6          | I   |                                 | Switch node connection for BUCK6 controller  |
| 43                           | DRVH6        | O   | VSYS + 5 V                      | High-side gate driver output for BUCK6 controller  |
| 44                           | FBVOUT6      | I   |                                 | Remote feedback sense for BUCK6 controller. Connect to positive terminal of output capacitor.  |
| 45                           | ILIM6        | I   |                                 | Current limit set pin for BUCK6 controller. Fit a resistor from this pin to ground to set current limit of external low-side FET.  |
| 64                           | ILIM2        | I   |                                 | Current limit set pin for BUCK2 controller. Fit a resistor from this pin to ground to set current limit of external low-side FET.  |
| <b>LDO and LOAD SWITCHES</b> |              |     |                                 |  |
| 9                            | LDOA1        | O   | 1.35–3.3 V                      | LDOA1 output. Bypass to ground with a 4.7-μF (typical) ceramic capacitor. Leave floating when not in use.  |
| 17                           | SWB1         | O   | 0.5–3.3 V<br>(1.8-V<br>Typical) | Output of load switch B1. Bypass to ground with a 0.1-μF (typical) ceramic capacitor. Short with SWB2.   |
| 18                           | PVINSWB1_B2  | I   | 0.5–3.3 V<br>(1.8-V<br>Typical) | Power supply to load switch B1 and B2. Bypass to ground with a 1-μF (typical) ceramic capacitor to improve transient performance. Connect to ground when not in use.         |
| 19                           | SWB2         | O   | 0.5–3.3 V<br>(1.8-V<br>Typical) | Output of load switch B2. Bypass to ground with a 0.1-μF (typical) ceramic capacitor. Short with SWB1. Leave floating when not in use.                                       |
| 31                           | SWA1         | O   | 0.5–3.3 V                       | Output of load switch A1. Bypass to ground with a 0.1-μF (typical) ceramic capacitor. Leave floating when not in use.  |
| 32                           | PVINSWA1     | I   | 0.5–3.3 V                       | Power supply to load switch A1. Bypass to ground with a 1-μF (typical) ceramic capacitor to improve transient performance. Connect to ground when not in use.                |
| 46                           | PVINVT       | I   | VDDQ                            | Power supply to VTT LDO. Bypass to ground with a 10-μF (minimum) ceramic capacitor. Connect to ground when not in use.   |
| 47                           | VTT          | O   | VDDQ / 2                        | Output of load VTT LDO. Bypass to ground with 2× 22-μF (minimum) ceramic capacitors. Leave floating when not in use.   |
| 48                           | VTTFB        | I   | VDDQ / 2                        | Remote feedback sense for VTT LDO. Connect to positive terminal of output capacitor. Short to GND when not in use.   |
| 49                           | LDOA3        | O   | 0.7–1.5 V                       | Output of LDOA3. Bypass to ground with a 4.7-μF (typical) ceramic capacitor. Leave floating when not in use.   |
| 50                           | PVINLDOA2_A3 | I   | 1.8 V                           | Power supply to LDOA2 and LDOA3. Bypass to ground with a 4.7-μF (typical) ceramic capacitor. Connect to ground when not in use.  |
| 51                           | LDOA2        | O   | 0.7–1.5 V                       | Output of LDOA2. Bypass to ground with a 4.7-μF (typical) ceramic capacitor. Leave floating when not in use.   |
| 54                           | LDO3P3       | O   | 3.3 V                           | Output of 3.3-V internal LDO. Bypass to ground with a 4.7-μF (typical) ceramic capacitor.  |
| 56                           | LDO5P0       | O   | 5 V                             | Output of 5-V internal LDO or an internal switch that connects this pin to V5ANA. Bypass to ground with a 4.7-μF (typical) ceramic capacitor.                                |
| 57                           | V5ANA        | I   | 5 V                             | External 5-V supply input to internal load switch that connects this pin to LDO5P0 pin. Bypass this pin with an optional ceramic capacitor to improve transient performance. |

**表 5-1. Pin Functions (続き)**

| PIN         |                        | I/O | SUPPLY, OP<br>VOLTAGE<br>LEVEL | DESCRIPTION   |
|-------------|------------------------|-----|--------------------------------|---|
| NO.         | NAME                   |     |                                |   |
| INTERFACE   |                        |     |                                |   |
| 13          | PMICEN                 | I   |                                | PMIC cold-boot pin. At assertion rising edge of the signal of this pin power state transitions from G3 to S4/S5. Driving the pin to <i>L</i> shuts down all VRs.  |
| 14          | LDOLS_EN or<br>SWA1_EN | I   |                                | Enable pin for LDOA2, LDOA3, and SWA1 when OTP is configured to LDOLS_EN. Enable pin for just SWA1 when OTP is configured to SWA1_EN. Resources turn on at assertion (H) and turn off at deassertion (L) of the pin. Optionally, when the pin is pulled low, the host can write to enable bits in Reg 0xA0–Reg 0xA1 to control the rails. |
| 15          | IRQB                   | O   |                                | Open-drain output interrupt pin. Refer to <a href="#">セクション 7.6.4</a> , <i>IRQ: PMIC Interrupt Register</i> , for definitions.  |
| 16          | RSMRSTB                | O   |                                | Open-drain output Always-ON-rail Power Good. It reflects a valid state whenever VSYS is available.  |
| 26          | GPO                    | O   |                                | Open-drain output controlled by an I <sup>2</sup> C register bit defined in <a href="#">セクション 7.6.27</a> , <i>GPO_CTRL: GPO Control Register</i> , by the user, which then can be used as an enable signal to an external VR.   |
| 27          | PCH_PWROK              | O   |                                | Open-drain output global Power Good. It reflects a valid state whenever VSYS is available.  |
| 28          | PROCHOT                | O   |                                | Optional open-drain output for indicating PMIC thermal event. Invert before connecting to SoC if used, otherwise leave floating. This pin is triggered when any of the PMIC die temperature sensors detects the T <sub>HOT</sub> temperature.   |
| 58          | CLK                    | I   |                                | I <sup>2</sup> C clock  |
| 59          | DATA                   | I/O |                                | I <sup>2</sup> C data   |
| 60          | THERMTRIPB             | I   |                                | Thermal shutdown signal from SoC  |
| 61          | SLP_S0B                | I   |                                | Power state pin. PMIC goes into Connected Standby at falling edge and exits from Connected Standby at rising edge.  |
| 62          | SLP_S3B                | I   |                                | Power state pin. PMIC goes into S3 at falling edge and exits from S3, transitions into S0 at rising edge.   |
| 63          | SLP_S4B                | I   |                                | Power state pin. PMIC goes into S4 at falling edge and exits from S4, transitions into S3 at rising edge.   |
| REFERENCE   |                        |     |                                |   |
| 53          | VREF                   | O   | 1.25 V                         | Band-gap reference output. Stabilize it by connecting a 100-nF (typical) ceramic capacitor between this pin and quiet ground.   |
| 52          | AGND                   | —   |                                | Analog ground. Do not connect to the thermal pad ground on top layer. Connect to ground of VREF capacitor.  |
| 55          | VSYS                   | I   |                                | System voltage detection and input to internal LDOs (3.3 V and 5 V). Bypass to ground with a 1-μF (typical) ceramic capacitor.  |
| THERMAL PAD |                        |     |                                |   |
| —           | Thermal pad            | —   |                                | Connect to PCB ground plane using multiple vias for good thermal and electrical performance.  |

## 6 Specifications

### 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

|  | MIN               | MAX | UNIT |
|--|-------------------|-----|------|
| <b>ANALOG</b>  |                   |     |      |
| VSYS Input voltage from battery  | −0.3              | 28  | V    |
| PVIN3, PVIN4, PVIN5, LDO5P0, DRV5V_1_6, DRV5V_2_A1, DRVL1, DRVL2, DRVL6  | −0.3              | 7   | V    |
| V5ANA  | −0.3              | 6   | V    |
| PGNDSNS1, PGNDSNS2, PGNDSNS6, AGND, FBGND2   | −0.3              | 0.3 | V    |
| DRVH1, DRVH2, DRVH6, BOOT1, BOOT2, BOOT6   | −0.3              | 34  | V    |
| SW1, SW2, SW6  | −5 <sup>(2)</sup> | 28  | V    |
| LX3, LX4, LX5  | −2 <sup>(3)</sup> | 8   | V    |
| BOOTx to SWx Differential voltage  | −0.3              | 5.5 | V    |
| VREF, LDO3P3, FBVOUT1, FBVOUT2, FBVOUT6, FB3, FB4, FB5, ILIM1, ILIM2, ILIM6, PVINVTT, VTT, VTTFB, PVINSWA1, SWA1, PVINSWB1_B2, SWB1, SWB2, LDOA1 | −0.3              | 3.6 | V    |
| PVINLDOA2_A3, LDOA2, LDOA3   | −0.3              | 3.3 | V    |
| <b>DIGITAL IOs</b>   |                   |     |      |
| DATA, CLK, PCH_PWROK, RSMRSTB, GPO   | −0.3              | 3.6 | V    |
| PMICEN, SLP_S4B, SLP_S3B, SLP_S0B, LDOLS_EN, SWA1_EN, THERMTRIPB, IRQB, PROCHOT  | −0.3              | 7   | V    |
| Storage temperature, T <sub>stg</sub>  | −55               | 150 | °C   |

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) Transient for less than 5 ns.

(3) Transient for less than 20 ns.

### 6.2 ESD Ratings

|  | VALUE  | UNIT  |
|--|--|-------|
| V <sub>ESD</sub> Electrostatic discharge | Human Body Model (HBM), per ANSI/ESDA/JEDEC JS001 <sup>(1)</sup> | ±1000 |
|  | Charged Device Model (CDM), per JESD22-C101 <sup>(2)</sup>       | ±250  |

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

|   | MIN  | NOM | MAX  | UNIT |
|---|------|-----|------|------|
| <b>ANALOG</b>   |      |     |      |      |
| VSYS  | 5.6  | 13  | 21   | V    |
| VREF  | −0.3 |     | 1.3  | V    |
| PVIN3, PVIN4, PVIN5, LDO5P0, V5ANA, DRV5V_1_6, DRV5V_2_A1 | −0.3 | 5   | 5.5  | V    |
| PGNDSNS1, PGNDSNS2, PGNDSNS6, AGND, FBGND2                | −0.3 |     | 0.3  | V    |
| DRVH1, DRVH2, DRVH6, BOOT1, BOOT2, BOOT6                  | −0.3 |     | 26.5 | V    |
| DRVL1, DRVL2, DRVL6                                       | −0.3 |     | 5.5  | V    |
| SW1, SW2, SW6   | −1   |     | 21   | V    |
| LX3, LX4, LX5   | −1   |     | 5.5  | V    |
| FBVOUT1, FBVOUT2, FBVOUT6, FB3, FB4, FB5                  | −0.3 |     | 3.6  | V    |
| LDO3P3, ILIM1, ILIM2, ILIM6, LDOA1                        | −0.3 |     | 3.3  | V    |
| PVINVT  | −0.3 |     | VDDQ | V    |



### 6.3 Recommended Operating Conditions (続き)

over operating free-air temperature range (unless otherwise noted)

|   | MIN  | NOM | MAX      | UNIT |
|---|------|-----|----------|------|
| VTT, VTTFB  | –0.3 |     | VDDQ / 2 | V    |
| PVINSWA1, SWA1  | –0.3 | 3.3 | 3.6      | V    |
| PVINSWB1_B2, PVINLDOA2_A3, SWB1, SWB2   | –0.3 |     | 1.8      | V    |
| LDOA2, LDOA3  | –0.3 |     | 1.5      | V    |
| <b>DIGITAL IOs</b>  |      |     |          |      |
| DATA, CLK, PMICEN, SLP_S4B, SLP_S3B, LDOLS_EN, SWA1_EN, SLP_S0B, THERMTRIPB, PROCHOT, IRQB, RSMRSTB, PCH_PWROK, GPO | –0.3 |     | 3.3      | V    |
| <b>CHIP</b>   |      |     |          |      |
| T <sub>A</sub> Operating ambient temperature  | –40  | 27  | 85       | °C   |
| T <sub>J</sub> Operating junction temperature   | –40  | 27  | 125      | °C   |

### 6.4 Thermal Information

| THERMAL METRIC <sup>(1)</sup> |  | TPS65094x  | UNIT |
|-------------------------------|--|------------|------|
|                               |  | RSK (VQFN) |      |
|                               |  | 64 PINS    |      |
| R <sub>θJA</sub>              | Junction-to-ambient thermal resistance       | 25.8       | °C/W |
| R <sub>θJC(top)</sub>         | Junction-to-case (top) thermal resistance    | 11.3       | °C/W |
| R <sub>θJB</sub>              | Junction-to-board thermal resistance         | 4.4        | °C/W |
| Ψ <sub>JT</sub>               | Junction-to-top characterization parameter   | 0.2        | °C/W |
| Ψ <sub>JB</sub>               | Junction-to-board characterization parameter | 4.4        | °C/W |
| R <sub>θJC(bot)</sub>         | Junction-to-case (bottom) thermal resistance | 0.7        | °C/W |

(1) For more information about traditional and new thermal metrics, see [Semiconductor and IC Package Thermal Metrics](#).

### 6.5 Electrical Characteristics: Total Current Consumption

over recommended free-air temperature range and over recommended input voltage range (typical values are at T<sub>A</sub> = 25°C) (unless otherwise noted)

| PARAMETER   | TEST CONDITIONS   | MIN | TYP | MAX | UNIT |
|---|---|-----|-----|-----|------|
| I <sub>SD</sub> PMIC shutdown current that includes I <sub>Q</sub> for references, LDO5, LDO3P3, and digital core | V <sub>SYS</sub> = 13 V, all functional output rails are disabled |     | 65  |     | μA   |

### 6.6 Electrical Characteristics: Reference and Monitoring System

over recommended free-air temperature range and over recommended input voltage range (typical values are at T<sub>A</sub> = 25°C) (unless otherwise noted)

| PARAMETER                    |   | TEST CONDITIONS  | MIN   | TYP | MAX  | UNIT |
|------------------------------|---|--|-------|-----|------|------|
| REFERENCE                    |   |  |       |     |      |      |
| V <sub>REF</sub>             | Band-gap reference voltage                |  | 1.25  |     |      | V    |
|                              | Accuracy                                  |  | −0.5% |     | 0.5% |      |
| C <sub>VREF</sub>            | Band-gap output capacitor                 |  | 0.047 | 0.1 | 0.22 | μF   |
| V <sub>SYS_UVLO_5V</sub>     | VSYS UVLO threshold for LDO5              | V <sub>SYS</sub> falling                               | 5.24  | 5.4 | 5.56 | V    |
| V <sub>SYS_UVLO_5V_HYS</sub> | VSYS UVLO threshold hysteresis for LDO5   | V <sub>SYS</sub> rising above V <sub>SYS_UVLO_5V</sub> | 200   |     |      | mV   |
| V <sub>SYS_UVLO_3V</sub>     | VSYS UVLO threshold for LDO3P3            | V <sub>SYS</sub> falling                               | 3.45  | 3.6 | 3.75 | V    |
| V <sub>SYS_UVLO_3V_HYS</sub> | VSYS UVLO threshold hysteresis for LDO3P3 | V <sub>SYS</sub> rising above V <sub>SYS_UVLO_3V</sub> | 150   |     |      | mV   |

## 6.6 Electrical Characteristics: Reference and Monitoring System (続き)

over recommended free-air temperature range and over recommended input voltage range (typical values are at  $T_A = 25^\circ\text{C}$ ) (unless otherwise noted)

| PARAMETER                          |   | TEST CONDITIONS  | MIN | TYP | MAX | UNIT             |
|------------------------------------|---|--|-----|-----|-----|------------------|
| $T_{\text{CRIT}}$                  | Critical threshold of die temperature                                   | $T_J$ rising   | 130 | 145 | 160 | $^\circ\text{C}$ |
| $T_{\text{CRIT\_HYS}}$             | Hysteresis of $T_{\text{CRIT}}$   | $T_J$ falling  |     | 10  |     | $^\circ\text{C}$ |
| $T_{\text{HOT}}$                   | Hot threshold of die temperature  | $T_J$ rising   | 110 | 115 | 120 | $^\circ\text{C}$ |
| $T_{\text{HOT\_HYS}}$              | Hysteresis of $T_{\text{HOT}}$  | $T_J$ falling  |     | 10  |     | $^\circ\text{C}$ |
| <b>LDO5</b>                        |   |  |     |     |     |                  |
| $V_{\text{IN}}$                    | Input voltage at $V_{\text{SYS}}$ pin                                   |  |     | 13  | 21  | V                |
| $V_{\text{OUT}}$                   | DC output voltage   | $I_{\text{OUT}} = 10\text{ mA}$  | 4.9 | 5   | 5.1 | V                |
| $I_{\text{OUT}}$                   | DC output current   |  |     | 100 | 180 | mA               |
| $I_{\text{OCP}}$                   | Overcurrent protection  | Measured with output shorted to ground   | 200 |     |     | mA               |
| $V_{\text{TH\_PG}}$                | Power Good assertion threshold in percentage of target $V_{\text{OUT}}$ | $V_{\text{OUT}}$ rising  |     | 94% |     |                  |
| $V_{\text{TH\_PG\_HYS}}$           | Power Good deassertion hysteresis                                       | $V_{\text{OUT}}$ rising or falling   |     | 4%  |     |                  |
| $I_{\text{Q}}$                     | Quiescent current   | $V_{\text{IN}} = 13\text{ V}$ , $I_{\text{OUT}} = 0\text{ A}$  |     | 20  |     | $\mu\text{A}$    |
| $C_{\text{OUT}}$                   | External output capacitance   |  | 2.7 | 4.7 | 10  | $\mu\text{F}$    |
| <b>V5ANA-to-LDO5P0 LOAD SWITCH</b> |   |  |     |     |     |                  |
| $R_{\text{DS(on)}}$                | On resistance   | $V_{\text{IN}} = 5\text{ V}$ , measured from V5ANA pin to LDO5P0 pin at $I_{\text{OUT}} = 200\text{ mA}$ |     |     | 1   | $\Omega$         |
| $V_{\text{TH\_PG}}$                | Power Good threshold for external 5-V supply                            | $V_{\text{V5ANA}}$ rising  |     | 4.7 |     | V                |
| $V_{\text{TH\_HYS\_PG}}$           | Power Good threshold hysteresis for external 5-V supply                 | $V_{\text{V5ANA}}$ falling   |     | 100 |     | mV               |
| $I_{\text{LKG}}$                   | Leakage current   | Switch disabled, $V_{\text{V5ANA}} = 5\text{ V}$ , $V_{\text{LDO5}} = 0\text{ V}$                        |     |     | 10  | $\mu\text{A}$    |
| <b>LDO3P3</b>                      |   |  |     |     |     |                  |
| $V_{\text{IN}}$                    | Input voltage at $V_{\text{SYS}}$ pin                                   |  |     | 13  | 21  | V                |
| $V_{\text{OUT}}$                   | DC output voltage   | $I_{\text{OUT}} = 10\text{ mA}$  |     | 3.3 |     | V                |
|                                    | Accuracy  | $V_{\text{IN}} = 13\text{ V}$ , $I_{\text{OUT}} = 10\text{ mA}$  | –3% |     | 3%  |                  |
| $I_{\text{OUT}}$                   | DC output current   |  |     |     | 40  | mA               |
| $I_{\text{OCP}}$                   | Overcurrent protection  | Measured with output shorted to ground   | 70  |     |     | mA               |
| $V_{\text{TH\_PG}}$                | Power Good assertion threshold in percentage of target $V_{\text{OUT}}$ | $V_{\text{OUT}}$ rising  |     | 92% |     |                  |
| $V_{\text{TH\_PG\_HYS}}$           | Power Good deassertion hysteresis                                       | $V_{\text{OUT}}$ falling   |     | 3%  |     |                  |
| $I_{\text{Q}}$                     | Quiescent current   | $V_{\text{IN}} = 13\text{ V}$ , $I_{\text{OUT}} = 0\text{ A}$  |     | 20  |     | $\mu\text{A}$    |
| $C_{\text{OUT}}$                   | External output capacitance   |  | 2.2 | 4.7 | 10  | $\mu\text{F}$    |

## 6.7 Electrical Characteristics: Buck Controllers

over recommended input voltage range,  $T_A = -40^\circ\text{C}$  to  $+85^\circ\text{C}$  and  $T_A = 25^\circ\text{C}$  for typical values (unless otherwise noted)

| PARAMETER       |  | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------------|--|-----------------|-----|-----|-----|------|
| <b>BUCK1</b>    |  |                 |     |     |     |      |
| $V_{\text{IN}}$ | Power input voltage for external HSD FET |                 | 5.6 | 13  | 21  | V    |

## 6.7 Electrical Characteristics: Buck Controllers (続き)

over recommended input voltage range,  $T_A = -40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$  and  $T_A = 25^{\circ}\text{C}$  for typical values (unless otherwise noted)

| PARAMETER                       |  | TEST CONDITIONS   | MIN   | TYP   | MAX   | UNIT              |
|---------------------------------|--|---|-------|-------|-------|-------------------|
| $V_{OUT}$                       | DC output voltage  | Step size   |       | 10    |       | mV                |
|                                 |  | BUCK1_VID[6:0] = 0000000  |       | 0     |       | V                 |
|                                 |  | BUCK1_VID[6:0] = 0000001  |       | 0.5   |       |                   |
|                                 |  | BUCK1_VID[6:0] = 0000010  |       | 0.51  |       |                   |
|                                 |  | ⋮   |       | ⋮     |       |                   |
|                                 |  | BUCK1_VID[6:0] = 0110011 (default)  |       | 1.00  |       |                   |
|                                 |  | ⋮   |       | ⋮     |       |                   |
|                                 |  | BUCK1_VID[6:0] = 1110101  |       | 1.66  |       |                   |
|                                 |  | BUCK1_VID[6:0] = 1110110–1111111  |       | 1.67  |       |                   |
|                                 | DC output voltage accuracy   | $V_{OUT} \geq 1\text{ V}$ , $I_{OUT} = 100\text{ mA}$ to $5\text{ A}$   | –2%   |       | 2%    |                   |
|                                 |  | $V_{OUT} = 0.75\text{ V}$ , $I_{OUT} = 100\text{ mA}$ to $2.1\text{ A}$   | –2.5% |       | 2.5%  |                   |
|                                 |  | $V_{OUT} \leq 0.6\text{ V}$ , $I_{OUT} = 10\text{ mA}$  | –3.5% |       | 3.5%  |                   |
|                                 | Total output voltage accuracy (DC + ripple) in DCM   | $I_{OUT} = 10\text{ mA}$ , $V_{OUT} \leq 0.785\text{ V}$ , $V_{SYS} = 13\text{ V}$  | –20   |       | 40    | mV                |
|                                 |  | $I_{OUT} = 10\text{ mA}$ , $V_{OUT} \leq 0.785\text{ V}$ , $V_{SYS} = 21\text{ V}$  | –20   |       | 55    |                   |
| SR( $V_{OUT}$ )                 | Output DVS slew rate   |   | 2.5   | 3.125 |       | mV/ $\mu\text{s}$ |
| $I_{LIM\_LSD}$                  | Low-side output valley current limit accuracy (programmed by external resistor $R_{LIM}$ ) | See セクション 7.3.3.4, <i>Current Limit</i> , for details.  | –15%  |       | 15%   |                   |
| $V_{TH\_ZC}$                    | Low-side current zero crossing detection threshold   |   | –11   |       | 11    | mV                |
| $I_{LIMREF}$                    | Source current out of ILIM1 pin  | $T = 25^{\circ}\text{C}$  | 45    | 50    | 55    | $\mu\text{A}$     |
| $V_{LIM}$                       | Voltage at ILIM1 pin   | $V_{LIM} = R_{LIM} \times I_{LIMREF}$   | 0.2   |       | 2.25  | V                 |
| $\Delta V_{OUT}/\Delta V_{IN}$  | Line regulation  | $V_{OUT} \geq 1\text{ V}$ , $I_{OUT} = 5\text{ A}$  | –0.5% |       | 0.5%  |                   |
| $\Delta V_{OUT}/\Delta I_{OUT}$ | Load regulation  | $V_{IN} = 13\text{ V}$ , $V_{OUT} \geq 1\text{ V}$ ,<br>$I_{OUT} = 0\text{ A}$ to $5\text{ A}$ ,<br>referenced to $V_{OUT}$ at $I_{OUT} = 5\text{ A}$   | 0%    |       | 1%    |                   |
| $\Delta V_{OUT\_TR}^{(1)}$      | Load transient regulation  | DC + AC at sense point, $V_{IN} = 13\text{ V}$ ,<br>$V_{OUT} = 1.00\text{ V}$ ,<br>$I_{OUT} = 1.5\text{ A}$ to $5\text{ A}$ and $5\text{ A}$ to $1.5\text{ A}$ with $1\text{ }\mu\text{s}$ of $t_r$ and $t_f$     | –50   |       | 50    | mV                |
|                                 |  | DC + AC at sense point, $V_{IN} = 13\text{ V}$ ,<br>$V_{OUT} = 0.75\text{ V}$ ,<br>$I_{OUT} = 0.3\text{ A}$ to $1.5\text{ A}$ and $1.5\text{ A}$ to $0.3\text{ A}$ with $1\text{ }\mu\text{s}$ of $t_r$ and $t_f$ |       |       |       |                   |
| $V_{TH\_PG}$                    | Power Good deassertion threshold in percentage of target $V_{OUT}$                         | $V_{OUT}$ rising  |       | 108%  |       |                   |
|                                 |  | $V_{OUT}$ falling   |       | 92%   |       |                   |
| $V_{TH\_HYS\_PG}$               | Power Good reassertion hysteresis entering back into $V_{TH\_PG}$                          | $V_{OUT}$ rising or falling   |       | 3%    |       |                   |
| $C_{OUT}$                       | External output capacitance  | Recommended amount to meet transient specification  | 180   | 220   |       | $\mu\text{F}$     |
| $L_{SW}$                        | External output inductance   |   | 0.376 | 0.47  | 0.564 | $\mu\text{H}$     |
| $R_{DS(on\_DRVH)}$              | Driver DRVH resistance   | Source, $IDRVH = -50\text{ mA}$   |       | 3     |       | $\Omega$          |
|                                 |  | Sink, $IDRVH = 50\text{ mA}$  |       | 2     |       |                   |

## 6.7 Electrical Characteristics: Buck Controllers (続き)

over recommended input voltage range,  $T_A = -40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$  and  $T_A = 25^{\circ}\text{C}$  for typical values (unless otherwise noted)

| PARAMETER                                     |   | TEST CONDITIONS  | MIN   | TYP   | MAX               | UNIT              |
|---|---|--|-------|-------|-------------------|-------------------|
| $R_{\text{DS(on)_DRV L}}$                     | Driver DRV L resistance   | Source, $I_{\text{DRV L}} = -50\text{ mA}$   |       | 3     |                   | $\Omega$          |
|   |   | Sink, $I_{\text{DRV L}} = 50\text{ mA}$  |       | 0.4   |                   |                   |
| $R_{\text{DIS}}$                              | Output auto-discharge resistance  | BUCK1_DIS[1:0] = 01  |       | 100   |                   | $\Omega$          |
|   |   | BUCK1_DIS[1:0] = 10  |       | 200   |                   |                   |
|   |   | BUCK1_DIS[1:0] = 11  |       | 500   |                   |                   |
| $C_{\text{BOOT}}$                             | Bootstrap capacitance   |  |       | 100   |                   | nF                |
| $R_{\text{ON\_BOOT}}$                         | Bootstrap switch ON resistance  |  |       |       | 20                | $\Omega$          |
| <b>BUCK2</b>                                  |   |  |       |       |                   |                   |
| $V_{\text{IN}}$                               | Power input voltage for external HSD FET  |  | 5.6   | 13    | 21                | V                 |
| $V_{\text{OUT}}$                              | DC output voltage   | Step size  |       | 10    |                   | mV                |
|   |   | BUCK2_VID[6:0] = 0000000 (default)   |       | 0     |                   | V                 |
|   |   | BUCK2_VID[6:0] = 0000001   |       | 0.5   |                   |                   |
|   |   | BUCK2_VID[6:0] = 0000010   |       | 0.51  |                   |                   |
|   |   | ⋮  |       | ⋮     |                   |                   |
|   |   | BUCK2_VID[6:0] = 1110101   |       | 1.66  |                   |                   |
|   |   | BUCK2_VID[6:0] = 1110110–1111111   |       | 1.67  |                   |                   |
|   | DC output voltage accuracy  | $V_{\text{OUT}} \geq 1\text{ V}$ , $I_{\text{OUT}} = 100\text{ mA}$ to 21 A  | –2%   |       | 2%                |                   |
|   |   | $V_{\text{OUT}} = 0.75\text{ V}$ , $I_{\text{OUT}} = 100\text{ mA}$ to 6.3 A   | –2.5% |       | 2.5%              |                   |
|   |   | $V_{\text{OUT}} \leq 0.6\text{ V}$ , $I_{\text{OUT}} = 10\text{ mA}$   | –3.5% |       | 3.5%              |                   |
|   | Total output voltage accuracy (DC + ripple) in DCM  | $I_{\text{OUT}} = 10\text{ mA}$ , $V_{\text{OUT}} \leq 0.765\text{ V}$   | –20   |       | 40                | mV                |
| $\text{SR}(V_{\text{OUT}})$                   | Output DVS slew rate  |  | 2.5   | 3.125 |                   | mV/ $\mu\text{s}$ |
| $I_{\text{LIM\_LSD}}$                         | Low-side output valley current limit accuracy (programmed by external resistor $R_{\text{LIM}}$ ) | See セクション 7.3.3.4, <i>Current Limit</i> , for details.   | –15%  |       | 15%               |                   |
| $V_{\text{TH\_ZC}}$                           | Low-side current zero crossing detection threshold  |  | –11   |       | 11                | mV                |
| $I_{\text{LIMREF}}$                           | Source current out of ILIM2 pin   | $T = 25^{\circ}\text{C}$   | 45    | 50    | 55                | $\mu\text{A}$     |
| $V_{\text{LIM}}$                              | Voltage at ILIM2 pin  | $V_{\text{LIM}} = R_{\text{LIM}} \times I_{\text{LIMREF}}$   | 0.2   |       | 2.25              | V                 |
| $\Delta V_{\text{OUT}}/\Delta V_{\text{IN}}$  | Line regulation   | $V_{\text{OUT}} \geq 1\text{ V}$ , $I_{\text{OUT}} = 21\text{ A}$  | –0.5% |       | 0.5%              |                   |
| $\Delta V_{\text{OUT}}/\Delta I_{\text{OUT}}$ | Load regulation   | $V_{\text{IN}} = 13\text{ V}$ , $1\text{ V} \leq V_{\text{OUT}} \leq 1.3\text{ V}$ ,<br>$I_{\text{OUT}} = 0\text{ A}$ to 21 A,<br>referenced to $V_{\text{OUT}}$ at $I_{\text{OUT}} = 21\text{ A}$ | 0%    |       | 1%                |                   |
| $\Delta V_{\text{OUT\_TR}}^{(1)}$             | Load transient regulation   | DC + AC at sense point, $V_{\text{IN}} = 13\text{ V}$ , $V_{\text{OUT}} = 1\text{ V}$ ,<br>$I_{\text{OUT}} = 1\text{ A}$ to 21 A and 21 A to 1 A with 1 $\mu\text{s}$ of $t_r$ and $t_f$           | –160  |       | 30 <sup>(2)</sup> | mV                |
|   |   | DC + AC at sense point, $V_{\text{IN}} = 13\text{ V}$ ,<br>$V_{\text{OUT}} = 0.75\text{ V}$ , $I_{\text{OUT}} = 1\text{ A}$ to 3.3 A and 3.3 A to 1 A with 1 $\mu\text{s}$ of $t_r$ and $t_f$      | –50   |       | 50 <sup>(2)</sup> |                   |
| $V_{\text{TH\_PG}}$                           | Power Good deassertion threshold in percentage of target $V_{\text{OUT}}$                         | $V_{\text{OUT}}$ rising  |       | 108%  |                   |                   |
|   |   | $V_{\text{OUT}}$ falling   |       | 92%   |                   |                   |

## 6.7 Electrical Characteristics: Buck Controllers (続き)

over recommended input voltage range,  $T_A = -40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$  and  $T_A = 25^{\circ}\text{C}$  for typical values (unless otherwise noted)

| PARAMETER                      |  | TEST CONDITIONS   | MIN   | TYP  | MAX   | UNIT          |
|--------------------------------|--|---|-------|------|-------|---------------|
| $V_{TH\_HYS\_PG}$              | Power Good reassertion hysteresis entering back into $V_{TH\_PG}$                          | $V_{OUT}$ rising or falling   |       | 3%   |       |               |
| $L_{SW}$                       | External output inductance   |   | 0.176 | 0.22 | 0.264 | $\mu\text{H}$ |
| $C_{OUT}$                      | External output capacitance  | Recommended amount to meet transient specification                    | 440   | 550  |       | $\mu\text{F}$ |
| $R_{DS(on)\_DRVH}$             | Driver DRVH resistance   | Source, $IDRVH = -50\text{ mA}$                                       |       | 3    |       | $\Omega$      |
|                                |  | Sink, $IDRVH = 50\text{ mA}$  |       | 2    |       |               |
| $R_{DS(on)\_DRVL}$             | Driver DRVL resistance   | Source, $IDRVL = -50\text{ mA}$                                       |       | 3    |       | $\Omega$      |
|                                |  | Sink, $IDRVL = 50\text{ mA}$  |       | 0.4  |       |               |
| $R_{DIS}$                      | Output auto-discharge resistance   | BUCK2_DIS[1:0] = 01   |       | 100  |       | $\Omega$      |
|                                |  | BUCK2_DIS[1:0] = 10   |       | 200  |       |               |
|                                |  | BUCK2_DIS[1:0] = 11   |       | 500  |       |               |
| $C_{BOOT}$                     | Bootstrap capacitance  |   |       | 100  |       | nF            |
| $R_{ON\_BOOT}$                 | Bootstrap switch ON resistance   |   |       |      | 20    | $\Omega$      |
| <b>BUCK6</b>                   |  |   |       |      |       |               |
| $V_{IN}$                       | Power input voltage for external HSD FET   |   | 5.6   | 13   | 21    | V             |
| $V_{OUT}$                      | DC output voltage  | Step size   |       | 10   |       | mV            |
|                                |  | BUCK6_VID[6:0] = 0000000  |       | 0    |       | V             |
|                                |  | BUCK6_VID[6:0] = 0000001  |       | 0.5  |       |               |
|                                |  | BUCK6_VID[6:0] = 0000010  |       | 0.51 |       |               |
|                                |  | ⋮   |       | ⋮    |       |               |
|                                |  | BUCK6_VID[6:0] = 0111101 (TPS650940 and TPS650944 default)            |       | 1.1  |       |               |
|                                |  | ⋮   |       | ⋮    |       |               |
|                                |  | BUCK6_VID[6:0] = 1000111 (TPS650941 default)                          |       | 1.2  |       |               |
|                                |  | ⋮   |       | ⋮    |       |               |
|                                |  | BUCK6_VID[6:0] = 1010110 (TPS650942 default)                          |       | 1.35 |       |               |
|                                |  | ⋮   |       | ⋮    |       |               |
|                                |  | BUCK6_VID[6:0] = 1110101  |       | 1.66 |       |               |
|                                |  | BUCK6_VID[6:0] = 1110110–1111111                                      |       | 1.67 |       |               |
|                                | DC output voltage accuracy   | $V_{OUT} \geq 1\text{ V}$ , $I_{OUT} = 100\text{ mA}$ to $7\text{ A}$ | –2%   |      | 2%    |               |
| $I_{LIM\_LSD}$                 | Low-side output valley current limit accuracy (programmed by external resistor $R_{LIM}$ ) | See <a href="#">セクション 7.3.3.4, Current Limit</a> , for details.       | –15%  |      | 15%   |               |
| $V_{TH\_ZC}$                   | Low-side current zero crossing detection threshold   |   | –11   |      | 11    | mV            |
| $I_{LIMREF}$                   | Source current out of ILIM6 pin  | $T = 25^{\circ}\text{C}$  | 45    | 50   | 55    | $\mu\text{A}$ |
| $V_{LIM}$                      | Voltage at ILIM6 pin   | $V_{LIM} = R_{LIM} \times I_{LIMREF}$                                 | 0.2   |      | 2.25  | V             |
| $\Delta V_{OUT}/\Delta V_{IN}$ | Line regulation  | $V_{OUT} \geq 1\text{ V}$ , $I_{OUT} = 7\text{ A}$                    | –0.5% |      | 0.5%  |               |

## 6.7 Electrical Characteristics: Buck Controllers (続き)

over recommended input voltage range,  $T_A = -40^\circ\text{C}$  to  $+85^\circ\text{C}$  and  $T_A = 25^\circ\text{C}$  for typical values (unless otherwise noted)

| PARAMETER   | TEST CONDITIONS   | MIN   | TYP  | MAX   | UNIT          |
|---|---|-------|------|-------|---------------|
| $\Delta V_{OUT}/\Delta I_{OUT}$ Load regulation                                     | $V_{IN} = 13\text{ V}$ , $V_{OUT} \geq 1\text{ V}$ , $I_{OUT} = 0\text{ A}$ to $7\text{ A}$ , referenced to $V_{OUT}$ at $I_{OUT} = 7\text{ A}$   | 0%    |      | 1%    |               |
| $\Delta V_{OUT\_TR}$ Load transient regulation                                      | DC + AC at sense point, $V_{IN} = 13\text{ V}$ , $V_{OUT} = 1.35\text{ V}$ , $I_{OUT} = 2.1\text{ A}$ to $7\text{ A}$ and $7\text{ A}$ to $2.1\text{ A}$ with $1.96\text{ }\mu\text{s}$ of $t_r$ and $t_f$ ( $2.5\text{ A}/\mu\text{s}$ ) | -5%   |      | 5%    |               |
| $V_{TH\_PG}$ Power Good deassertion threshold in percentage of target $V_{OUT}$     | $V_{OUT}$ rising  |       | 108% |       |               |
|   | $V_{OUT}$ falling   |       | 92%  |       |               |
| $V_{TH\_HYS\_PG}$ Power Good reassertion hysteresis entering back into $V_{TH\_PG}$ | $V_{OUT}$ rising or falling   |       | 3%   |       |               |
| $L_{SW}$ External output inductance   |   | 0.376 | 0.47 | 0.564 | $\mu\text{H}$ |
| $C_{OUT}$ External output capacitance   | Recommended amount to meet transient specification  | 150   | 220  |       | $\mu\text{F}$ |
| $R_{DS(on)\_DRVH}$ Driver DRVH resistance   | Source, $IDRVH = -50\text{ mA}$   |       | 3    |       | $\Omega$      |
|   | Sink, $IDRVH = 50\text{ mA}$  |       | 2    |       |               |
| $R_{DS(on)\_DRVL}$ Driver DRVL resistance   | Source, $IDRVL = -50\text{ mA}$   |       | 3    |       | $\Omega$      |
|   | Sink, $IDRVL = 50\text{ mA}$  |       | 0.4  |       |               |
| $R_{DIS}$ Output auto-discharge resistance  | BUCK6_DIS[1:0] = 01   |       | 100  |       | $\Omega$      |
|   | BUCK6_DIS[1:0] = 10   |       | 200  |       |               |
|   | BUCK6_DIS[1:0] = 11   |       | 500  |       |               |
| $C_{BOOT}$ Bootstrap capacitance  |   |       | 100  |       | nF            |
| $R_{ON\_BOOT}$ Bootstrap switch ON resistance                                       |   |       |      | 20    | $\Omega$      |

- Frequency of transient load current ranges from 0 to 1 MHz with duty cycle of 50%. For cases where duty cycle and frequency are limited by  $t_r$  and  $t_f$ , the highest frequency is set by  $1 / (t_r + t_f)$ , where  $t_r$  is rise time (0% to 100%) and  $t_f$  is fall time (100% to 0%).
- Additional overshoot of up to 100 mV is allowed as long as it lasts less than 50  $\mu\text{s}$ .

## 6.8 Electrical Characteristics: Synchronous Buck Converters

over recommended input voltage range,  $T_A = -40^\circ\text{C}$  to  $+85^\circ\text{C}$  and  $T_A = 25^\circ\text{C}$  for typical values (unless otherwise noted)

| PARAMETER                              | TEST CONDITIONS                    | MIN   | TYP   | MAX  | UNIT              |
|--|------------------------------------|---|-------|------|-------------------|
| <b>BUCK3</b>                           |                                    |   |       |      |                   |
| $V_{IN}$ Power input voltage           |                                    | 4.5   | 5     | 5.5  | V                 |
| $V_{OUT}$                              | Step size                          |   | 25    |      | mV                |
|  | BUCK3_VID[6:0] = 0000000           |   | 0     |      | V                 |
|  | BUCK3_VID[6:0] = 0000001           |   | 0.65  |      |                   |
|  | BUCK3_VID[6:0] = 0000010           |   | 0.675 |      |                   |
|  | ⋮                                  |   | ⋮     |      |                   |
|  | BUCK3_VID[6:0] = 0010001 (default) |   | 1.05  |      |                   |
|  | ⋮                                  |   | ⋮     |      |                   |
|  | BUCK3_VID[6:0] = 1110101           |   | 3.55  |      |                   |
|  | BUCK3_VID[6:0] = 1110110–1111111   |   | 3.575 |      |                   |
|  | DC output voltage accuracy         | $V_{OUT} = 1.05\text{ V}$ , $I_{OUT} = 1.5\text{ A}$  | -2%   | 2%   |                   |
|  |                                    | $V_{OUT} = 1.05\text{ V}$ , $I_{OUT} = 100\text{ mA}$ | -2.5% | 2.5% |                   |
| $SR(V_{OUT})$ Output DVS slew rate     |                                    | 2.5   | 3.125 |      | mV/ $\mu\text{s}$ |
| $I_{OUT}$ Continuous DC output current |                                    |   |       | 3    | A                 |

## 6.8 Electrical Characteristics: Synchronous Buck Converters (続き)

over recommended input voltage range,  $T_A = -40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$  and  $T_A = 25^{\circ}\text{C}$  for typical values (unless otherwise noted)

| PARAMETER   |   | TEST CONDITIONS  | MIN   | TYP   | MAX   | UNIT |
|---|---|--|-------|-------|-------|------|
| I <sub>IND_LIM</sub>                                | HSD FET current limit   |  | 4.3   |       | 7     | A    |
| I <sub>Q</sub>                                      | Quiescent current   | V <sub>IN</sub> = 5 V, V <sub>OUT</sub> = 1 V  |       | 35    |       | μA   |
| ΔV <sub>OUT</sub> /ΔV <sub>IN</sub>                 | Line regulation   | V <sub>OUT</sub> = 1.05 V, I <sub>OUT</sub> = 1.5 A  | −0.5% |       | 0.5%  |      |
| ΔV <sub>OUT</sub> /ΔI <sub>OUT</sub>                | Load regulation   | V <sub>IN</sub> = 5 V, V <sub>OUT</sub> = 1.05 V, I <sub>OUT</sub> = 0 A to 3 A, referenced to V <sub>OUT</sub> at I <sub>OUT</sub> = 1.5 A                | −0.2% |       | 2%    |      |
| ΔV <sub>OUT_TR</sub> <sup>(1)</sup>                 | Load transient regulation   | DC + AC at sense point, V <sub>IN</sub> = 5 V, V <sub>OUT</sub> = 1.05 V, I <sub>OUT</sub> = 0.9 A to 3 A and 3 A to 0.9 A with slew rate of 2.5 A/μs      | −5%   |       | 7%    |      |
| V <sub>TH_PG</sub>                                  | Power Good deassertion threshold in percentage of target V <sub>OUT</sub> | V <sub>OUT</sub> rising  |       | 108%  |       |      |
|   |   | V <sub>OUT</sub> falling   |       | 92%   |       |      |
| V <sub>TH_HYS_PG</sub>                              | Power Good reassertion hysteresis entering back into V <sub>TH_PG</sub>   | V <sub>OUT</sub> rising or falling   |       | 3%    |       |      |
| L <sub>SW</sub>                                     | Output inductance   |  | 0.376 | 0.47  | 0.564 | μH   |
| C <sub>IN</sub>                                     | Input bypass capacitance  |  | 2.5   | 10    | 12    | μF   |
| C <sub>OUT</sub>                                    | Output filtering capacitance  |  | 61.6  | 88    | 110   | μF   |
| R <sub>DIS</sub>                                    | Output auto-discharge resistance  | BUCK3_DIS[1:0] = 01  |       | 100   |       | Ω    |
|   |   | BUCK3_DIS[1:0] = 10  |       | 200   |       |      |
|   |   | BUCK3_DIS[1:0] = 11  |       | 500   |       |      |
| BUCK4   |   |  |       |       |       |      |
| V <sub>IN</sub>                                     | Power input voltage   |  | 4.5   | 5     | 5.5   | V    |
| V <sub>OUT</sub>                                    | DC output voltage   | Step size  |       | 25    |       | mV   |
|   |   | BUCK4_VID[6:0] = 0000000   |       | 0     |       | V    |
|   |   | BUCK4_VID[6:0] = 0000001   |       | 0.65  |       |      |
|   |   | BUCK4_VID[6:0] = 0000010   |       | 0.675 |       |      |
|   |   | ⋮  |       | ⋮     |       |      |
|   |   | BUCK4_VID[6:0] = 0101111 (default)   |       | 1.8   |       |      |
|   |   | ⋮  |       | ⋮     |       |      |
|   |   | BUCK4_VID[6:0] = 1110101   |       | 3.55  |       |      |
|   |   | BUCK4_VID[6:0] = 1110110–1111111   |       | 3.575 |       |      |
|   | DC output voltage accuracy  | V <sub>OUT</sub> = 1.8 V, I <sub>OUT</sub> = 1.5 A   | −2%   |       | 2%    |      |
| V <sub>OUT</sub> = 1.8 V, I <sub>OUT</sub> = 100 mA |   | −2.5%  |       | 2.5%  |       |      |
| I <sub>OUT</sub>                                    | Continuous DC output current  |  |       |       | 3     | A    |
| I <sub>IND_LIM</sub>                                | HSD FET current limit   |  | 4.3   |       | 7     | A    |
| I <sub>Q</sub>                                      | Quiescent current   | V <sub>IN</sub> = 5 V, V <sub>OUT</sub> = 1.8 V  |       | 35    |       | μA   |
| ΔV <sub>OUT</sub> /ΔV <sub>IN</sub>                 | Line regulation   | V <sub>OUT</sub> = 1.8 V, I <sub>OUT</sub> = 1.5 A   | −0.5% |       | 0.5%  |      |
| ΔV <sub>OUT</sub> /ΔI <sub>OUT</sub>                | Load regulation   | V <sub>IN</sub> = 5 V, V <sub>OUT</sub> = 1.8 V, I <sub>OUT</sub> = 0 A to 1.5 A, referenced to V <sub>OUT</sub> at I <sub>OUT</sub> = 0.75 A              | −0.2% |       | 0.65% |      |
| ΔV <sub>OUT_TR</sub> <sup>(1)</sup>                 | Load transient regulation   | DC + AC at sense point, V <sub>IN</sub> = 5 V, V <sub>OUT</sub> = 1.8 V, I <sub>OUT</sub> = 0.45 A to 1.5 A and 1.5 A to 0.45 A with slew rate of 2.5 A/μs | −5%   |       | 5%    |      |

## 6.8 Electrical Characteristics: Synchronous Buck Converters (続き)

over recommended input voltage range,  $T_A = -40^\circ\text{C}$  to  $+85^\circ\text{C}$  and  $T_A = 25^\circ\text{C}$  for typical values (unless otherwise noted)

| PARAMETER  |   | TEST CONDITIONS   | MIN   | TYP  | MAX   | UNIT |   |
|--|---|---|-------|------|-------|------|---|
| V <sub>TH_PG</sub>                                   | Power Good deassertion threshold in percentage of target V <sub>OUT</sub> | V <sub>OUT</sub> rising   | 108%  |      |       |      |   |
|  |   | V <sub>OUT</sub> falling  | 92%   |      |       |      |   |
| V <sub>TH_HYS_PG</sub>                               | Power Good reassertion hysteresis entering back into V <sub>TH_PG</sub>   | V <sub>OUT</sub> rising or falling  | 3%    |      |       |      |   |
| L <sub>SW</sub>                                      | Output inductance   |   | 0.376 | 0.47 | 0.564 | μH   |   |
| C <sub>IN</sub>                                      | Input bypass capacitance  |   | 2.5   | 10   | 12    | μF   |   |
| C <sub>OUT</sub>                                     | Output filtering capacitance  |   | 46    | 66   | 110   | μF   |   |
| R <sub>DIS</sub>                                     | Output auto-discharge resistance  | BUCK4_DIS[1:0] = 01   | 100   |      |       | Ω    |   |
|  |   | BUCK4_DIS[1:0] = 10   | 200   |      |       |      |   |
|  |   | BUCK4_DIS[1:0] = 11   | 500   |      |       |      |   |
| BUCK5  |   |   |       |      |       |      |   |
| V <sub>IN</sub>                                      | Power input voltage   |   | 4.5   | 5    | 5.5   | V    |   |
| V <sub>OUT</sub>                                     | DC output voltage   | Step size   | 10    |      |       | mV   |   |
|  |   | BUCK5_VID[6:0] = 0000000  | 0     |      |       | V    |   |
|  |   | BUCK5_VID[6:0] = 0000001  | 0.5   |      |       |      |   |
|  |   | BUCK5_VID[6:0] = 0000010  | 0.51  |      |       |      |   |
|  |   | ⋮   | ⋮     |      |       |      |   |
|  |   | BUCK5_VID[6:0] = 1001011 (default)  | 1.24  |      |       |      |   |
|  |   | ⋮   | ⋮     |      |       |      |   |
|  |   | BUCK5_VID[6:0] = 1110101  | 1.66  |      |       |      |   |
|  | BUCK4_VID[6:0] = 1110110–1111111  | 1.67  |       |      |       |      |   |
|  | DC output voltage accuracy  | V <sub>OUT</sub> = 1.24 V, I <sub>OUT</sub> = 1.5 A   | –2%   |      | 2%    |      |   |
| V <sub>OUT</sub> = 1.24 V, I <sub>OUT</sub> = 100 mA |   | –2.5%   |       | 2.5% |       |      |   |
| I <sub>OUT</sub>                                     | Continuous DC output current  |   | 3.2   |      |       | A    |   |
| I <sub>IND_LIM</sub>                                 | HSD FET current limit   |   | 4.3   | 7    |       |      | A |
| I <sub>Q</sub>                                       | Quiescent current   | V <sub>IN</sub> = 5 V, V <sub>OUT</sub> = 1.24 V  | 35    |      |       | μA   |   |
| ΔV <sub>OUT</sub> /ΔV <sub>IN</sub>                  | Line regulation   | V <sub>OUT</sub> = 1.24 V, I <sub>OUT</sub> = 1.5 A   | –0.5% |      | 0.5%  |      |   |
| ΔV <sub>OUT</sub> /ΔI <sub>OUT</sub>                 | Load regulation   | V <sub>IN</sub> = 5 V, V <sub>OUT</sub> = 1.24 V, I <sub>OUT</sub> = 0 A to 1.5 A, referenced to V <sub>OUT</sub> at I <sub>OUT</sub> = 0.75 A              | –0.2% |      | 1%    |      |   |
| ΔV <sub>OUT_TR</sub> <sup>(1)</sup>                  | Load transient regulation   | DC + AC at sense point, V <sub>IN</sub> = 5 V, V <sub>OUT</sub> = 1.24 V, I <sub>OUT</sub> = 0.45 A to 1.5 A and 1.5 A to 0.45 A with slew rate of 2.5 A/μs | –5%   |      | 5%    |      |   |
| V <sub>TH_PG</sub>                                   | Power Good deassertion threshold in percentage of target V <sub>OUT</sub> | V <sub>OUT</sub> rising   | 108%  |      |       |      |   |
|  |   | V <sub>OUT</sub> falling  | 92%   |      |       |      |   |
| V <sub>TH_HYS_PG</sub>                               | Power Good reassertion hysteresis entering back into V <sub>TH_PG</sub>   | V <sub>OUT</sub> rising or falling  | 3     |      |       |      |   |
| L <sub>SW</sub>                                      | Output inductance   |   | 0.376 | 0.47 | 0.564 | μH   |   |



## 6.8 Electrical Characteristics: Synchronous Buck Converters (続き)

over recommended input voltage range,  $T_A = -40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$  and  $T_A = 25^{\circ}\text{C}$  for typical values (unless otherwise noted)

| PARAMETER |                                  | TEST CONDITIONS     | MIN | TYP | MAX | UNIT          |
|-----------|----------------------------------|---------------------|-----|-----|-----|---------------|
| $C_{IN}$  | Input bypass capacitance         |                     | 2.5 | 10  | 12  | $\mu\text{F}$ |
| $C_{OUT}$ | Output filtering capacitance     |                     | 31  | 44  | 110 | $\mu\text{F}$ |
| $R_{DIS}$ | Output auto-discharge resistance | BUCK5_DIS[1:0] = 01 |     | 100 |     | $\Omega$      |
|           |                                  | BUCK5_DIS[1:0] = 10 |     | 200 |     |               |
|           |                                  | BUCK5_DIS[1:0] = 11 |     | 500 |     |               |

## 6.9 Electrical Characteristics: LDOs

over recommended input voltage range,  $T_A = -40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$  and  $T_A = 25^{\circ}\text{C}$  for typical values (unless otherwise noted)

| PARAMETER                       |  | TEST CONDITIONS   | MIN   | TYP  | MAX  | UNIT          |
|---------------------------------|--|---|-------|------|------|---------------|
| <b>LDOA1</b>                    |  |   |       |      |      |               |
| $V_{IN}$                        | Input voltage  |   | 4.5   | 5    | 5.5  | V             |
| $V_{OUT}$                       | DC output voltage  | $I_{OUT} = 10\text{ mA}$ , LDOA1_SEL[3:0] = 0000                    |       | 1.35 |      | V             |
|                                 |  | LDOA1_SEL[3:0] = 0001   |       | 1.5  |      |               |
|                                 |  | LDOA1_SEL[3:0] = 0010   |       | 1.6  |      |               |
|                                 |  | LDOA1_SEL[3:0] = 0011   |       | 1.7  |      |               |
|                                 |  | LDOA1_SEL[3:0] = 0100 (TPS650944 default)                           |       | 1.8  |      |               |
|                                 |  | LDOA1_SEL[3:0] = 0101   |       | 1.9  |      |               |
|                                 |  | LDOA1_SEL[3:0] = 0110   |       | 2    |      |               |
|                                 |  | LDOA1_SEL[3:0] = 0111   |       | 2.1  |      |               |
|                                 |  | LDOA1_SEL[3:0] = 1000   |       | 2.3  |      |               |
|                                 |  | LDOA1_SEL[3:0] = 1001   |       | 2.4  |      |               |
|                                 |  | LDOA1_SEL[3:0] = 1010   |       | 2.5  |      |               |
|                                 |  | LDOA1_SEL[3:0] = 1011   |       | 2.7  |      |               |
|                                 |  | LDOA1_SEL[3:0] = 1100   |       | 2.85 |      |               |
|                                 |  | LDOA1_SEL[3:0] = 1101   |       | 3    |      |               |
|                                 |  | LDOA1_SEL[3:0] = 1110 (TPS650940, TPS650941, and TPS650942 default) |       | 3.3  |      |               |
| $V_{OUT}$                       | Accuracy   | $I_{OUT} = 0$ to 200 mA   | -2%   |      | 2%   |               |
| $I_{OUT}$                       | DC output current  |   |       |      | 200  | mA            |
| $\Delta V_{OUT}/\Delta V_{IN}$  | Line regulation  | $I_{OUT} = 40\text{ mA}$  | -0.5% |      | 0.5% |               |
| $\Delta V_{OUT}/\Delta I_{OUT}$ | Load regulation  | $I_{OUT} = 10\text{ mA}$ to 200 mA                                  | -2%   |      | 2%   |               |
| $I_{OCP}$                       | Overcurrent protection   | $V_{IN} = 5\text{ V}$ , Measured with output shorted to ground      | 500   |      |      | mA            |
| $V_{TH\_PG}$                    | Power Good deassertion threshold in percentage of target $V_{OUT}$ | $V_{OUT}$ rising  |       | 108% |      |               |
|                                 |  | $V_{OUT}$ falling   |       | 92%  |      |               |
| $V_{TH\_HYS\_PG}$               | Power Good reassertion hysteresis entering back into $V_{TH\_PG}$  | $V_{OUT}$ rising or falling   |       | 3%   |      |               |
| $I_Q$                           | Quiescent current  | $I_{OUT} = 0\text{ A}$  |       | 23   |      | $\mu\text{A}$ |
| $C_{OUT}$                       | External output capacitance  |   | 2.7   | 4.7  | 10   | $\mu\text{F}$ |
|                                 | ESR  |   |       |      | 100  | m $\Omega$    |

## 6.9 Electrical Characteristics: LDOs (続き)

over recommended input voltage range,  $T_A = -40^\circ\text{C}$  to  $+85^\circ\text{C}$  and  $T_A = 25^\circ\text{C}$  for typical values (unless otherwise noted)

| PARAMETER                            |   | TEST CONDITIONS   | MIN   | TYP  | MAX  | UNIT |
|--------------------------------------|---|---|---|------|------|------|
| R <sub>DIS</sub>                     | Output auto-discharge resistance  | LDOA1_DIS[1:0] = 01   |   | 100  |      | Ω    |
|                                      |   | LDOA1_DIS[1:0] = 10   |   | 190  |      |      |
|                                      |   | LDOA1_DIS[1:0] = 11   |   | 450  |      |      |
| LDOA2                                |   |   |   |      |      |      |
| V <sub>IN</sub>                      | Power input voltage   |   | V <sub>OUT</sub> + V <sub>DROP</sub> <sup>(1)</sup> | 1.8  | 1.98 | V    |
| V <sub>OUT</sub>                     | DC output voltage in normal operating mode                              | LDOA2_VID[3:0] = 0000 (TPS650944 default)   |   | 0.7  |      | V    |
|                                      |   | LDOA2_VID[3:0] = 0001   |   | 0.75 |      |      |
|                                      |   | LDOA2_VID[3:0] = 0010   |   | 0.8  |      |      |
|                                      |   | LDOA2_VID[3:0] = 0011   |   | 0.85 |      |      |
|                                      |   | LDOA2_VID[3:0] = 0100   |   | 0.9  |      |      |
|                                      |   | LDOA2_VID[3:0] = 0101   |   | 0.95 |      |      |
|                                      |   | LDOA2_VID[3:0] = 0110   |   | 1    |      |      |
|                                      |   | LDOA2_VID[3:0] = 0111   |   | 1.05 |      |      |
|                                      |   | LDOA2_VID[3:0] = 1000   |   | 1.1  |      |      |
|                                      |   | LDOA2_VID[3:0] = 1001   |   | 1.15 |      |      |
|                                      |   | LDOA2_VID[3:0] = 1010 (TPS650940, TPS650941, and TPS650942 default)   |   | 1.2  |      |      |
|                                      |   | LDOA2_VID[3:0] = 1011   |   | 1.25 |      |      |
|                                      |   | LDOA2_VID[3:0] = 1100   |   | 1.3  |      |      |
|                                      |   | LDOA2_VID[3:0] = 1101   |   | 1.35 |      |      |
|                                      |   | LDOA2_VID[3:0] = 1110   |   | 1.4  |      |      |
|                                      |   | LDOA2_VID[3:0] = 1111   |   | 1.5  |      |      |
| V <sub>OUT</sub>                     | DC output voltage accuracy  | I <sub>OUT</sub> = 0 to 600 mA  | –2%   |      | 3%   |      |
| I <sub>OUT</sub>                     | DC output current   |   |   |      | 600  | mA   |
| V <sub>DROP</sub>                    | Dropout voltage   | V <sub>OUT</sub> = 0.99 × V <sub>OUT_NOM</sub> ,<br>I <sub>OUT</sub> = 600 mA   |   |      | 350  | mV   |
| ΔV <sub>OUT</sub> /ΔV <sub>IN</sub>  | Line regulation   | I <sub>OUT</sub> = 300 mA   | –0.5%   |      | 0.5% |      |
| ΔV <sub>OUT</sub> /ΔI <sub>OUT</sub> | Load regulation   | I <sub>OUT</sub> = 10 mA to 600 mA  | –2%   |      | 2%   |      |
| I <sub>OCP</sub>                     | Overcurrent protection  | Measured with output shorted to ground  | 0.65  | 1.25 |      | A    |
| V <sub>TH_PG</sub>                   | Power Good assertion threshold in percentage of target V <sub>OUT</sub> | V <sub>OUT</sub> rising   |   | 108% |      |      |
|                                      |   | V <sub>OUT</sub> falling  |   | 92%  |      |      |
| V <sub>TH_HYS_PG</sub>               | Power Good deassertion hysteresis                                       | V <sub>OUT</sub> falling  |   | 3%   |      |      |
| I <sub>Q</sub>                       | Quiescent current   | I <sub>OUT</sub> = 0 A  |   | 20   |      | μA   |
| PSRR                                 | Power supply rejection ratio  | f = 1 kHz, V <sub>IN</sub> = 1.8 V, V <sub>OUT</sub> = 1.2 V,<br>I <sub>OUT</sub> = 300 mA,<br>C <sub>OUT</sub> = 2.2 μF to 4.7 μF  |   | 48   |      | dB   |
|                                      |   | f = 10 kHz, V <sub>IN</sub> = 1.8 V, V <sub>OUT</sub> = 1.2 V,<br>I <sub>OUT</sub> = 300 mA,<br>C <sub>OUT</sub> = 2.2 μF to 4.7 μF |   | 30   |      | dB   |
| C <sub>OUT</sub>                     | External output capacitance   |   | 2.2   | 4.7  | 10   | μF   |
|                                      | ESR   |   |   |      | 100  | mΩ   |
| R <sub>DIS</sub>                     | Output auto-discharge resistance  | LDOA2_DIS[1:0] = 01   |   | 80   |      | Ω    |
|                                      |   | LDOA2_DIS[1:0] = 10   |   | 180  |      |      |
|                                      |   | LDOA2_DIS[1:0] = 11   |   | 475  |      |      |

## 6.9 Electrical Characteristics: LDOs (続き)

over recommended input voltage range,  $T_A = -40^\circ\text{C}$  to  $+85^\circ\text{C}$  and  $T_A = 25^\circ\text{C}$  for typical values (unless otherwise noted)

| PARAMETER                       |  | TEST CONDITIONS  | MIN                        | TYP  | MAX  | UNIT          |
|---------------------------------|--|--|----------------------------|------|------|---------------|
| <b>LDOA3</b>                    |  |  |                            |      |      |               |
| $V_{IN}$                        | Power input voltage  |  | $V_{OUT} + V_{DROP}^{(1)}$ | 1.8  | 1.98 | V             |
| $V_{OUT}$                       | DC output voltage in normal operating mode                       | LDOA3_VID[3:0] = 0000 (TPS650944 default)  |                            | 0.7  |      | V             |
|                                 |  | LDOA3_VID[3:0] = 0001  |                            | 0.75 |      |               |
|                                 |  | LDOA3_VID[3:0] = 0010  |                            | 0.8  |      |               |
|                                 |  | LDOA3_VID[3:0] = 0011  |                            | 0.85 |      |               |
|                                 |  | LDOA3_VID[3:0] = 0100  |                            | 0.9  |      |               |
|                                 |  | LDOA3_VID[3:0] = 0101  |                            | 0.95 |      |               |
|                                 |  | LDOA3_VID[3:0] = 0110  |                            | 1    |      |               |
|                                 |  | LDOA3_VID[3:0] = 0111  |                            | 1.05 |      |               |
|                                 |  | LDOA3_VID[3:0] = 1000  |                            | 1.1  |      |               |
|                                 |  | LDOA3_VID[3:0] = 1001  |                            | 1.15 |      |               |
|                                 |  | LDOA3_VID[3:0] = 1010  |                            | 1.2  |      |               |
|                                 |  | LDOA3_VID[3:0] = 1011 (TPS650940, TPS650941, and TPS650942 default)  |                            | 1.25 |      |               |
|                                 |  | LDOA3_VID[3:0] = 1100  |                            | 1.3  |      |               |
|                                 |  | LDOA3_VID[3:0] = 1101  |                            | 1.35 |      |               |
|                                 |  | LDOA3_VID[1:0] = 1110  |                            | 1.4  |      |               |
|                                 |  | LDOA3_VID[1:0] = 1111  |                            | 1.5  |      |               |
| $V_{OUT}$                       | DC output voltage accuracy                                       | $I_{OUT} = 0$ to 600 mA  | –2%                        |      | 3%   |               |
| $I_{OUT}$                       | DC output current  |  |                            |      | 600  | mA            |
| $I_{OCP}$                       | Overcurrent protection   | Measured with output shorted to ground   | 0.65                       | 1.25 |      | A             |
| $V_{DROP}$                      | Dropout voltage  | $V_{OUT} = 0.99 \times V_{OUT\_NOM}$ ,<br>$I_{OUT} = 600$ mA   |                            |      | 350  | mV            |
| $\Delta V_{OUT}/\Delta V_{IN}$  | Line regulation  | $I_{OUT} = 300$ mA   | –0.5%                      |      | 0.5% |               |
| $\Delta V_{OUT}/\Delta I_{OUT}$ | Load regulation  | $I_{OUT} = 10$ mA to 600 mA  | –2%                        |      | 2%   |               |
| $V_{TH\_PG}$                    | Power Good assertion threshold in percentage of target $V_{OUT}$ | $V_{OUT}$ rising   |                            | 108% |      |               |
|                                 |  | $V_{OUT}$ falling  |                            | 92%  |      |               |
| $V_{TH\_HYS\_PG}$               | Power Good deassertion hysteresis                                | $V_{OUT}$ falling  |                            | 3%   |      |               |
| $I_Q$                           | Quiescent current  | $I_{OUT} = 0$ A  |                            | 20   |      | $\mu\text{A}$ |
| PSRR                            | Power supply rejection ratio                                     | $f = 1$ kHz, $V_{IN} = 1.8$ V,<br>$V_{OUT} = 1.2$ V,<br>$I_{OUT} = 300$ mA,<br>$C_{OUT} = 2.2$ $\mu\text{F}$ to 4.7 $\mu\text{F}$  |                            | 48   |      | dB            |
|                                 |  | $f = 10$ kHz, $V_{IN} = 1.8$ V,<br>$V_{OUT} = 1.2$ V,<br>$I_{OUT} = 300$ mA,<br>$C_{OUT} = 2.2$ $\mu\text{F}$ to 4.7 $\mu\text{F}$ |                            | 30   |      |               |
| $C_{OUT}$                       | External output capacitance                                      |  | 2.2                        | 4.7  | 10   | $\mu\text{F}$ |
|                                 | ESR  |  |                            |      | 100  | m $\Omega$    |
| $R_{DIS}$                       | Output auto-discharge resistance                                 | LDOA3_DIS[1:0] = 01  |                            | 80   |      | $\Omega$      |
|                                 |  | LDOA3_DIS[1:0] = 10  |                            | 180  |      |               |
|                                 |  | LDOA3_DIS[1:0] = 11  |                            | 475  |      |               |

## 6.9 Electrical Characteristics: LDOs (続き)

over recommended input voltage range,  $T_A = -40^\circ\text{C}$  to  $+85^\circ\text{C}$  and  $T_A = 25^\circ\text{C}$  for typical values (unless otherwise noted)

| PARAMETER                       |  | TEST CONDITIONS   | MIN   | TYP          | MAX  | UNIT          |
|---------------------------------|--|---|-------|--------------|------|---------------|
| <b>VTT LDO</b>                  |  |   |       |              |      |               |
| $V_{IN}$                        | Power input voltage  |   |       | VDDQ         | 3.3  | V             |
| $V_{OUT}$                       | DC output voltage  | Measured at VTTFB pin   |       | $V_{IN} / 2$ |      | V             |
|                                 | DC output voltage accuracy   | Relative to $V_{IN} / 2$ , $I_{OUT} = 100\text{ mA}$ , $1.1\text{ V} \leq V_{IN} \leq 1.5\text{ V}$   | -10   |              | 10   | mV            |
| $I_{OUT}$                       | DC Output Current (RMS Value Over Operation)                             | $1.1\text{ V} \leq V_{IN} \leq 1.5\text{ V}$  | -500  | 0            | 500  | mA            |
|                                 | Pulsed Current (Duty Cycle Limited to Remain Below DC RMS Specification) | source(+) and sink(-): LPDDR3 and LPDDR4 OTPs, $1.1\text{ V} \leq V_{IN} \leq 1.5\text{ V}$   | -500  |              | 500  | mA            |
|                                 |  | source(+) and sink(-): DDR3L OTPs, $1.1\text{ V} \leq V_{IN} \leq 1.5\text{ V}$   | -1800 |              | 1800 |               |
| $\Delta V_{OUT}/\Delta I_{OUT}$ | Load regulation  | Relative to $V_{IN} / 2$ , $I_{OUT} \leq 10\text{ mA}$ , $1.1\text{ V} \leq V_{IN} \leq 1.5\text{ V}$   | -10   |              | 10   | mV            |
|                                 |  | Relative to $V_{IN} / 2$ , $I_{OUT} \leq 500\text{ mA}$ , $1.1\text{ V} \leq V_{IN} \leq 1.5\text{ V}$  | -20   |              | 20   |               |
|                                 |  | Relative to $V_{IN} / 2$ , $I_{OUT} \leq 1200\text{ mA}$ , $1.1\text{ V} \leq V_{IN} \leq 1.5\text{ V}$   | -30   |              | 30   |               |
|                                 |  | Relative to $V_{IN} / 2$ , $I_{OUT} \leq 1800\text{ mA}$ , $1.1\text{ V} \leq V_{IN} \leq 1.5\text{ V}$   | -40   |              | 40   |               |
| $\Delta V_{OUT\_TR}$            | Load transient regulation  | DC + AC at sense point, $1.1\text{ V} \leq V_{IN} \leq 1.5\text{ V}$ , ( $I_{OUT} = 0$ to $350\text{ mA}$ and $350\text{ mA}$ to $0$ ) AND ( $0$ to $-350\text{ mA}$ and $-350\text{ mA}$ to $0$ ) with $1\text{ }\mu\text{s}$ of rise and fall time<br>$C_{OUT} = 40\text{ }\mu\text{F}$ | -5%   |              | 5%   |               |
| $I_{OCP}$                       | Overcurrent protection   | Measured with output shorted to ground: OTPs with VTT $I_{LIM} = 0.95\text{ A}$   | 0.95  |              |      | A             |
|                                 |  | Measured with output shorted to ground: OTPs with VTT $I_{LIM} = 1.8\text{ A}$  | 1.8   |              |      |               |
| $V_{TH\_PG}$                    | Power Good deassertion threshold in percentage of target $V_{OUT}$       | $V_{OUT}$ rising  |       | 110%         |      |               |
|                                 |  | $V_{OUT}$ falling   |       | 95%          |      |               |
| $V_{TH\_HYS\_PG}$               | Power Good reassertion hysteresis entering back into $V_{TH\_PG}$        | $V_{OUT}$ rising or falling   |       | 5%           |      |               |
| $I_Q$                           | Total ground current   | $V_{IN} = 1.2\text{ V}$ , $I_{OUT} = 0\text{ A}$  |       |              | 240  | $\mu\text{A}$ |
| $I_{LKG}$                       | OFF leakage current  | $V_{IN} = 1.2\text{ V}$ , disabled  |       |              | 1    | $\mu\text{A}$ |
| $C_{IN}$                        | External input capacitance   |   | 10    |              |      | $\mu\text{F}$ |
| $C_{OUT}$                       | External output capacitance  |   | 35    |              |      | $\mu\text{F}$ |

(1) The minimum value must be equal to or greater than 1.62 V.

## 6.10 Electrical Characteristics: Load Switches

over operating free-air temperature range (unless otherwise noted)

| PARAMETER    |                     | TEST CONDITIONS  | MIN | TYP | MAX | UNIT       |
|--------------|---------------------|--|-----|-----|-----|------------|
| <b>SWA1</b>  |                     |  |     |     |     |            |
| $V_{IN}$     | Input voltage range |  | 0.5 | 1.8 | 3.3 | V          |
| $I_{OUT}$    | DC output current   |  |     |     | 300 | mA         |
| $R_{DS(on)}$ | ON resistance       | $V_{IN} = 1.8\text{ V}$ , measured from PVINSWA1 pin to SWA1 pin at $I_{OUT} = I_{OUT(MAX)}$ |     | 60  | 93  | m $\Omega$ |
|              |                     | $V_{IN} = 3.3\text{ V}$ , measured from PVINSWA1 pin to SWA1 pin at $I_{OUT} = I_{OUT(MAX)}$ |     | 100 | 165 |            |

## 6.10 Electrical Characteristics: Load Switches (続き)

over operating free-air temperature range (unless otherwise noted)

| PARAMETER              |   | TEST CONDITIONS  | MIN | TYP  | MAX  | UNIT |
|------------------------|---|--|-----|------|------|------|
| V <sub>TH_PG</sub>     | Power Good deassertion threshold in percentage of target V <sub>OUT</sub> | V <sub>OUT</sub> rising  |     | 108% |      |      |
|                        |   | V <sub>OUT</sub> falling   |     | 92%  |      |      |
| V <sub>TH_HYS_PG</sub> | Power Good reassertion hysteresis entering back into V <sub>TH_PG</sub>   | V <sub>OUT</sub> rising or falling   |     | 2%   |      |      |
| I <sub>INRUSH</sub>    | Inrush current upon turnon  | V <sub>IN</sub> = 3.3 V, C <sub>OUT</sub> = 0.1 μF   |     |      | 10   | mA   |
| I <sub>Q</sub>         | Quiescent current   | V <sub>IN</sub> = 3.3 V, I <sub>OUT</sub> = 0 A  |     | 10.5 |      | μA   |
|                        |   | V <sub>IN</sub> = 1.8 V, I <sub>OUT</sub> = 0 A  |     | 9    |      |      |
| I <sub>LKG</sub>       | Leakage current   | Switch disabled, V <sub>IN</sub> = 1.8 V   |     | 7    | 370  | nA   |
|                        |   | Switch disabled, V <sub>IN</sub> = 3.3 V   |     | 10   | 900  |      |
| C <sub>OUT</sub>       | External output capacitance   |  |     | 0.1  |      | μF   |
| R <sub>DIS</sub>       | Output auto-discharge resistance  | SWA1_DIS[1:0] = 01   |     | 100  |      | Ω    |
|                        |   | SWA1_DIS[1:0] = 10   |     | 200  |      |      |
|                        |   | SWA1_DIS[1:0] = 11   |     | 500  |      |      |
| <b>SWB1_2</b>          |   |  |     |      |      |      |
| V <sub>IN</sub>        | Input voltage range   |  | 0.5 | 1.8  | 3.3  | V    |
| I <sub>OUT</sub>       | DC current per output   |  |     |      | 400  | mA   |
| R <sub>DS(on)</sub>    | ON resistance per output  | V <sub>IN</sub> = 1.8 V, measured from PVINSWB1_B2 pin to SWB1 or SWB2 pin at I <sub>OUT</sub> = I <sub>OUT(MAX)</sub> |     | 68   | 92   | mΩ   |
|                        |   | V <sub>IN</sub> = 3.3 V, measured from PVINSWB1_B2 pin to SWB1 or SWB2 pin at I <sub>OUT</sub> = I <sub>OUT(MAX)</sub> |     | 75   | 125  |      |
| V <sub>TH_PG</sub>     | Power Good deassertion threshold in percentage of target V <sub>OUT</sub> | V <sub>OUT</sub> rising  |     | 108% |      |      |
|                        |   | V <sub>OUT</sub> falling   |     | 92%  |      |      |
| V <sub>TH_HYS_PG</sub> | Power Good reassertion hysteresis entering back into V <sub>TH_PG</sub>   | V <sub>OUT</sub> rising or falling   |     | 2%   |      |      |
| I <sub>INRUSH</sub>    | Inrush current upon turning on  | V <sub>IN</sub> = 3.3 V, C <sub>OUT</sub> = 0.1 μF   |     |      | 10   | mA   |
| I <sub>Q</sub>         | Quiescent current   | V <sub>IN</sub> = 3.3 V, I <sub>OUT</sub> = 0 A  |     | 10.5 |      | μA   |
|                        |   | V <sub>IN</sub> = 1.8 V, I <sub>OUT</sub> = 0 A  |     | 9    |      |      |
| I <sub>LKG</sub>       | Leakage current   | Switch disabled, V <sub>IN</sub> = 1.8 V   |     | 7    | 460  | nA   |
|                        |   | Switch disabled, V <sub>IN</sub> = 3.3 V   |     | 10   | 1150 |      |
| C <sub>OUT</sub>       | External output capacitance   |  |     | 0.1  |      | μF   |
| R <sub>DIS</sub>       | Output auto-discharge resistance  | SWBx_DIS[1:0] = 01   |     | 100  |      | Ω    |
|                        |   | SWBx_DIS[1:0] = 10   |     | 200  |      |      |
|                        |   | SWBx_DIS[1:0] = 11   |     | 500  |      |      |

## 6.11 Digital Signals: I<sup>2</sup>C Interface

over recommended free-air temperature range and over recommended input voltage range (typical values are at T<sub>A</sub> = 25°C) (unless otherwise noted)

| PARAMETER        | TEST CONDITIONS          | MIN | TYP  | MAX | UNIT |
|------------------|--------------------------|-----|------|-----|------|
| V <sub>OL</sub>  | Low-level output voltage |     |      | 0.4 | V    |
| V <sub>IH</sub>  | High-level input voltage | 1.2 |      |     | V    |
| V <sub>IL</sub>  | Low-level input voltage  |     |      | 0.4 | V    |
| I <sub>LKG</sub> | Leakage current          |     | 0.01 | 0.3 | μA   |

## 6.11 Digital Signals: I<sup>2</sup>C Interface (続き)

over recommended free-air temperature range and over recommended input voltage range (typical values are at  $T_A = 25^\circ\text{C}$ ) (unless otherwise noted)

| PARAMETER                                       | TEST CONDITIONS | MIN | TYP | MAX | UNIT       |
|---|-----------------|-----|-----|-----|------------|
| R <sub>PULL-UP</sub> Pullup resistance          | Standard mode   |     |     | 8.5 | k $\Omega$ |
|   | Fast mode       |     |     | 2.5 |            |
|   | Fast mode plus  |     |     | 1   |            |
| C <sub>OUT</sub> Total load capacitance per pin |                 |     |     | 50  | pF         |

## 6.12 Digital Input Signals (LDOLS\_EN, SWA1\_EN, THERMTRIPB, PMICEN, SLP\_S3B, SLP\_S4B, SLP\_S0B)

over recommended free-air temperature range and over recommended input voltage range (typical values are at  $T_A = 25^\circ\text{C}$ ) (unless otherwise noted)

| PARAMETER                                | TEST CONDITIONS | MIN  | TYP | MAX | UNIT |
|--|-----------------|------|-----|-----|------|
| V <sub>IH</sub> High-level input voltage |                 | 0.85 |     |     | V    |
| V <sub>IL</sub> Low-level input voltage  |                 |      |     | 0.4 | V    |

## 6.13 Digital Output Signals (IRQB, RSMRSTB, PCH\_PWROK, PROCHOT)

Over recommended free-air temperature range and over recommended input voltage range (typical values are at  $T_A = 25^\circ\text{C}$ ) (unless otherwise noted)

| PARAMETER                                | TEST CONDITIONS              | MIN | TYP | MAX  | UNIT          |
|--|------------------------------|-----|-----|------|---------------|
| V <sub>OL</sub> Low-level output voltage | I <sub>OL</sub> < 2 mA       |     |     | 0.4  | V             |
| I <sub>LKG</sub> Leakage current         | V <sub>PULL-UP</sub> = 1.8 V |     |     | 0.35 | $\mu\text{A}$ |

## 6.14 Timing Requirements

over recommended free-air temperature range and over recommended input voltage range (typical values are at  $T_A = 25^\circ\text{C}$ ) (unless otherwise noted)

|                                 |                                  | MIN | NOM | MAX  | UNIT |
|---------------------------------|----------------------------------|-----|-----|------|------|
| <b>I<sup>2</sup>C INTERFACE</b> |                                  |     |     |      |      |
| f <sub>CLK</sub>                | Clock frequency (standard mode)  |     |     | 100  | kHz  |
|                                 | Clock frequency (fast mode)      |     |     | 400  |      |
|                                 | Clock frequency (fast mode plus) |     |     | 1000 |      |
| t <sub>r</sub>                  | Rise time (standard mode)        |     |     | 1000 | ns   |
|                                 | Rise time (fast mode)            |     |     | 300  |      |
|                                 | Rise time (fast mode plus)       |     |     | 120  |      |
| t <sub>f</sub>                  | Rise time (standard mode)        |     |     | 300  | ns   |
|                                 | Rise time (fast mode)            |     |     | 300  |      |
|                                 | Rise time (fast mode plus)       |     |     | 120  |      |

## 6.15 Switching Characteristics

over operating free-air temperature range and over recommended input voltage range (typical values are at  $T_A = 25^\circ\text{C}$ ) (unless otherwise noted)

| PARAMETER                         | TEST CONDITIONS   | MIN | TYP | MAX | UNIT          |
|-----------------------------------|---|-----|-----|-----|---------------|
| <b>BUCK CONTROLLERS</b>           |   |     |     |     |               |
| t <sub>PG</sub> Total turnon time | Measured from enable going high to when output reaches 90% of target value. |     | 550 | 850 | $\mu\text{s}$ |

## 6.15 Switching Characteristics (続き)

over operating free-air temperature range and over recommended input voltage range (typical values are at  $T_A = 25^\circ\text{C}$ ) (unless otherwise noted)

| PARAMETER            |                         | TEST CONDITIONS   | MIN | TYP  | MAX  | UNIT |
|----------------------|-------------------------|---|-----|------|------|------|
| T <sub>ON,MIN</sub>  | Minimum ON time of DRVH |   |     | 50   |      | ns   |
| T <sub>DEAD</sub>    | Driver dead-time        | DRVH off to DRVL on   |     | 15   |      | ns   |
|                      |                         | DRVL off to DRVH on   |     | 30   |      |      |
| f <sub>SW</sub>      | Switching frequency     | Continuous-conduction mode, V <sub>IN</sub> = 13 V, V <sub>OUT</sub> ≥ 1 V  |     | 1000 |      | kHz  |
| BUCK CONVERTERS      |                         |   |     |      |      |      |
| t <sub>PG</sub>      | Total turnon time       | Measured from enable going high to when output reaches 90% of target value.<br>V <sub>OUT</sub> = 1 V, C <sub>OUT</sub> = 88 μF   |     | 250  | 1000 | μs   |
| f <sub>SW</sub>      | Switching frequency     | Continuous-conduction mode, BUCK3 V <sub>OUT</sub> = 1 V, I <sub>OUT</sub> = 1 A  |     | 1.6  |      | MHz  |
|                      |                         | Continuous-conduction mode, BUCK3 V <sub>OUT</sub> = 1.05 V, I <sub>OUT</sub> = 1 A   |     | 1.7  |      |      |
|                      |                         | Continuous-conduction mode, BUCK4 V <sub>OUT</sub> = 1.8 V, I <sub>OUT</sub> = 1 A  |     | 2.5  |      |      |
|                      |                         | Continuous-conduction mode, BUCK5 V <sub>OUT</sub> = 1.24 V, I <sub>OUT</sub> = 1 A   |     | 2.4  |      |      |
|                      |                         | Continuous-conduction mode, BUCK5 V <sub>OUT</sub> = 1.35 V, I <sub>OUT</sub> = 1 A   |     | 2.5  |      |      |
| LDOAx                |                         |   |     |      |      |      |
| t <sub>STARTUP</sub> | Start-up time           | Measured from enable going high to when output reaches 95% of final value,<br>V <sub>OUT</sub> = 1.2 V, C <sub>OUT</sub> = 4.7 μF |     | 180  |      | μs   |
| VTT LDO              |                         |   |     |      |      |      |
| t <sub>STARTUP</sub> | Start-up time           | Measured from enable going high to PG assertion,<br>V <sub>OUT</sub> = 0.675 V, C <sub>OUT</sub> = 40 μF                          |     | 22   |      | μs   |
| SWA1                 |                         |   |     |      |      |      |
| t <sub>TURN-ON</sub> | Turnon time             | Measured from enable going high to reach 95% of final value,<br>V <sub>IN</sub> = 3.3 V, C <sub>OUT</sub> = 0.1 μF                |     | 0.85 |      | ms   |
|                      |                         | Measured from enable going high to reach 95% of final value,<br>V <sub>IN</sub> = 1.8 V, C <sub>OUT</sub> = 0.1 μF                |     | 0.63 |      |      |
| SWB1_2               |                         |   |     |      |      |      |
| t <sub>TURN-ON</sub> | Turnon time             | Measured from enable going high to reach 95% of final value,<br>V <sub>IN</sub> = 3.3 V, C <sub>OUT</sub> = 0.1 μF                |     | 1.1  |      | ms   |
|                      |                         | Measured from enable going high to reach 95% of final value,<br>V <sub>IN</sub> = 1.8 V, C <sub>OUT</sub> = 0.1 μF                |     | 0.82 |      |      |

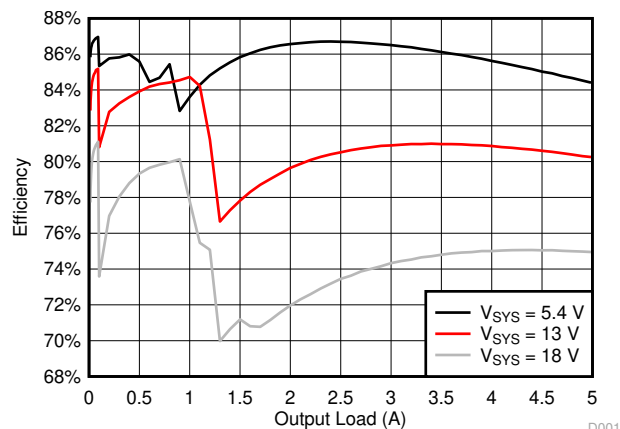


図 6-1. BUCK1 (VNN) Efficiency at  $V_{OUT} = 1\text{ V}$

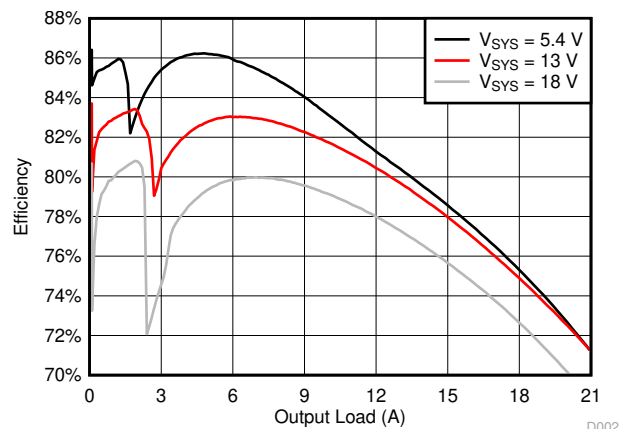
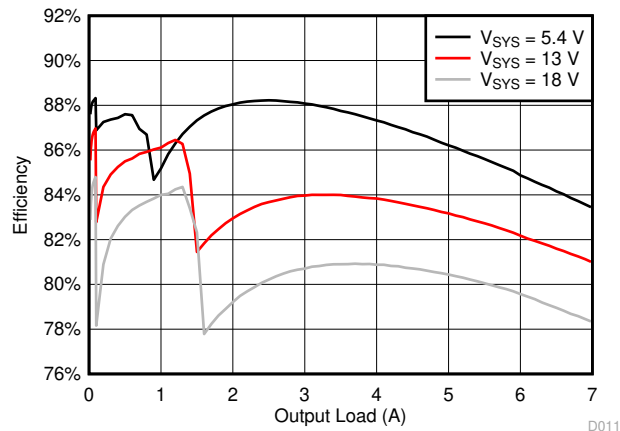
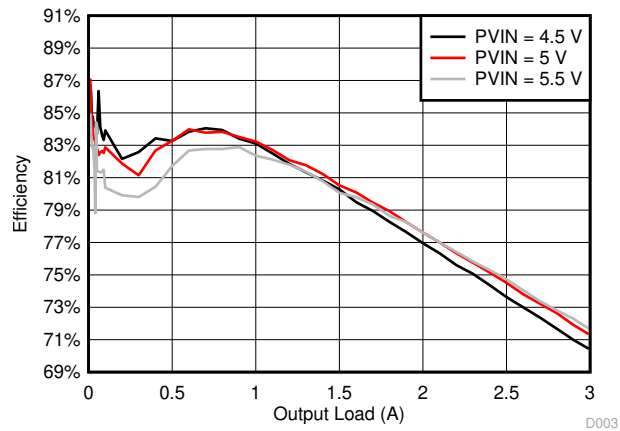
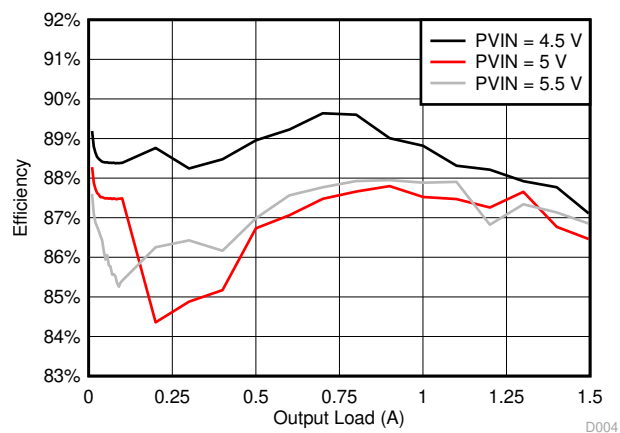
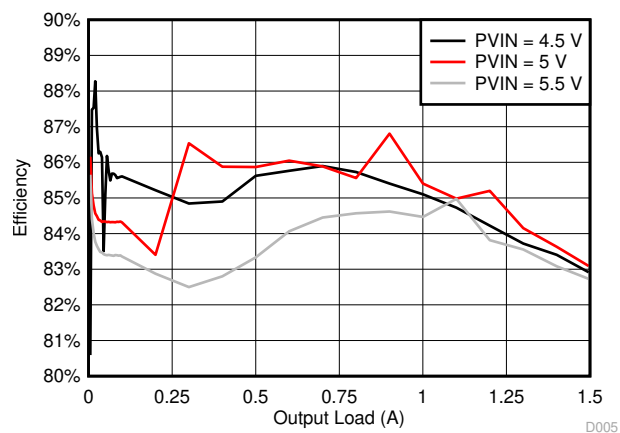


図 6-2. BUCK2 (VCCGI) Efficiency at  $V_{OUT} = 1\text{ V}$


**図 6-3. BUCK6 (VDDQ) Efficiency at  $V_{OUT} = 1.2\text{ V}$** 

**図 6-4. BUCK3 (VCCRAM) Efficiency at  $V_{OUT} = 1.05\text{ V}$** 

**図 6-5. BUCK4 (V1P8A) Efficiency at  $V_{OUT} = 1.8\text{ V}$** 

**図 6-6. BUCK5 (V1P24A) Efficiency at  $V_{OUT} = 1.24\text{ V}$**



## 7 Detailed Description

### 7.1 Overview

The TPS65094x device provides all the necessary power supplies for the Intel Reference Designs. For an overview of the different OTP configurations, consult 表 4-1. The following VRs are integrated: three step-down controllers (BUCK1, BUCK2, and BUCK6), three step-down converters (BUCK3, BUCK4, and BUCK5), a sink and source LDO (VTT LDO), three low-voltage  $V_{IN}$  LDOs (LDOA1–LDOA3), and three load switches that are managed by power-up sequence logic to provide the proper power rails, sequencing, and protection. All VRs have a built-in discharge resistor, and the value can be changed by the DISCHCNT1–DISCHCNT3 and LDOA1\_CTRL registers. When enabling a VR, the PMIC automatically disconnects the discharge resistor for that rail without any I<sup>2</sup>C command. 表 7-1 summarizes the key characteristics of the voltage rails.

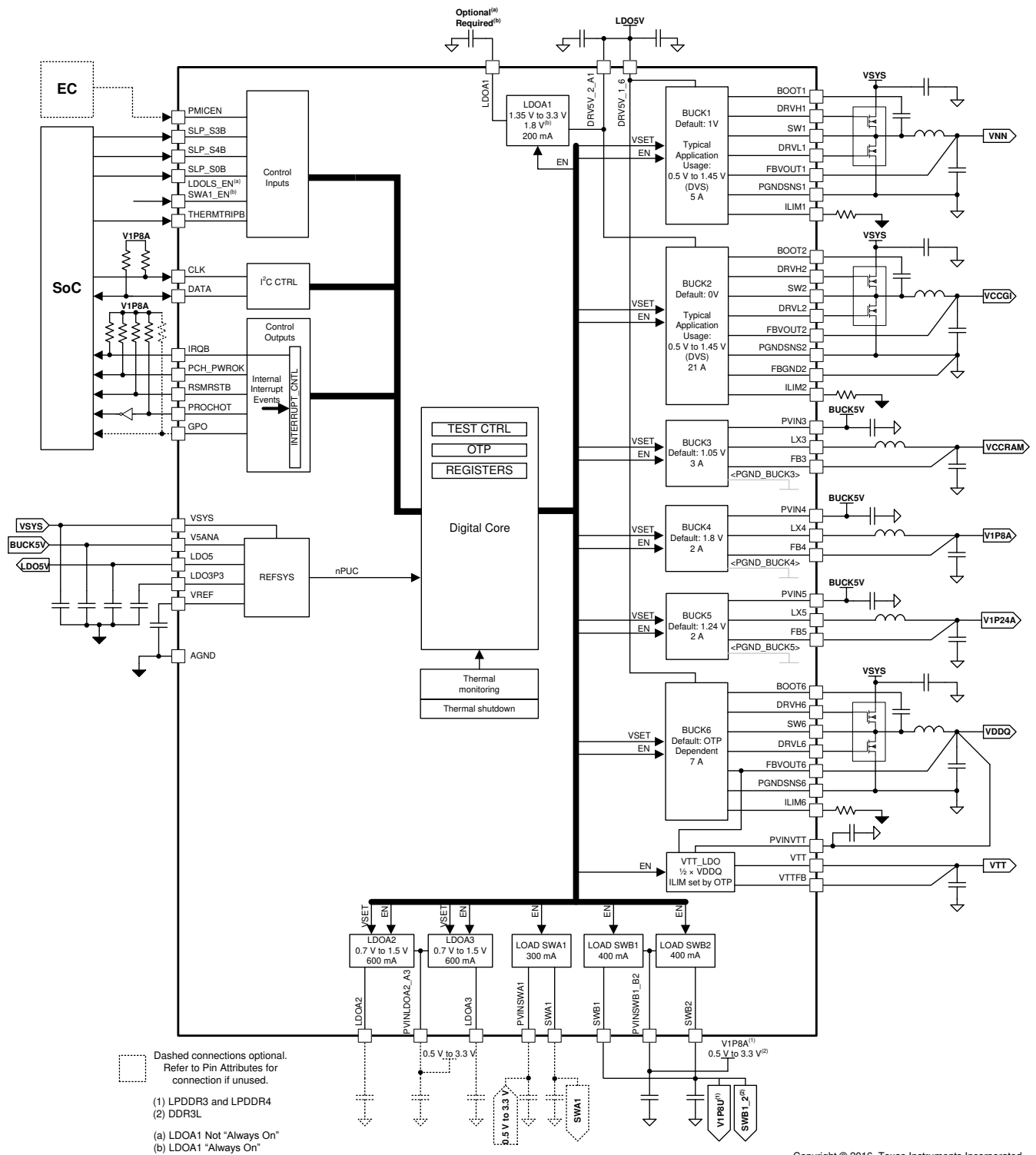
**表 7-1. Summary of Voltage Regulators**

| RAIL                  | TYPE                 | INPUT VOLTAGE<br>(V) |      | OUTPUT VOLTAGE RANGE<br>(V) |                 |       | TYPICAL<br>APPLICATION<br>CURRENT<br>(mA) |
|-----------------------|----------------------|----------------------|------|-----------------------------|-----------------|-------|---|
|                       |                      | MIN                  | MAX  | MIN                         | TYP             | MAX   |   |
| BUCK1 (VNN)           | Step-down controller | 4.5                  | 21   | 0.5                         | 1.05            | 1.67  | 5000                                      |
| BUCK2 (VCCGI)         | Step-down controller | 4.5                  | 21   | 0.5                         | 1               | 1.67  | 21000                                     |
| BUCK3 (VCCRAM)        | Step-down converter  | 4.5                  | 5.5  | 0.65                        | 1.05            | 3.575 | 3000                                      |
| BUCK4 (V1P8A)         | Step-down converter  | 4.5                  | 5.5  | 0.65                        | 1.8             | 3.575 | 1500                                      |
| BUCK5 (V1P24A)        | Step-down converter  | 4.5                  | 5.5  | 0.5                         | 1.24            | 1.67  | 1900                                      |
| BUCK6 (VDDQ)          | Step-down controller | 4.5                  | 21   | 0.5                         | OTP dependent   | 1.67  | 7000                                      |
| LDOA1                 | LDO                  | 4.5                  | 5.5  | 1.35                        | OTP dependent   | 3.3   | 200 <sup>(1)</sup>                        |
| LDOA2                 | LDO                  | 1.62                 | 1.98 | 0.7                         | OTP dependent   | 1.5   | 600                                       |
| LDOA3                 | LDO                  | 1.62                 | 1.98 | 0.7                         | OTP dependent   | 1.5   | 600                                       |
| SWA1                  | Load switch          | 0.5                  | 3.3  |                             |                 |       | 300                                       |
| SWB1_2 <sup>(2)</sup> | Load switch          | 0.5                  | 3.3  |                             |                 |       | 800 (combined)                            |
| VTT                   | Sink and source LDO  | BUCK6 output         |      |                             | $V_{BUCK6} / 2$ |       | OTP dependent                             |

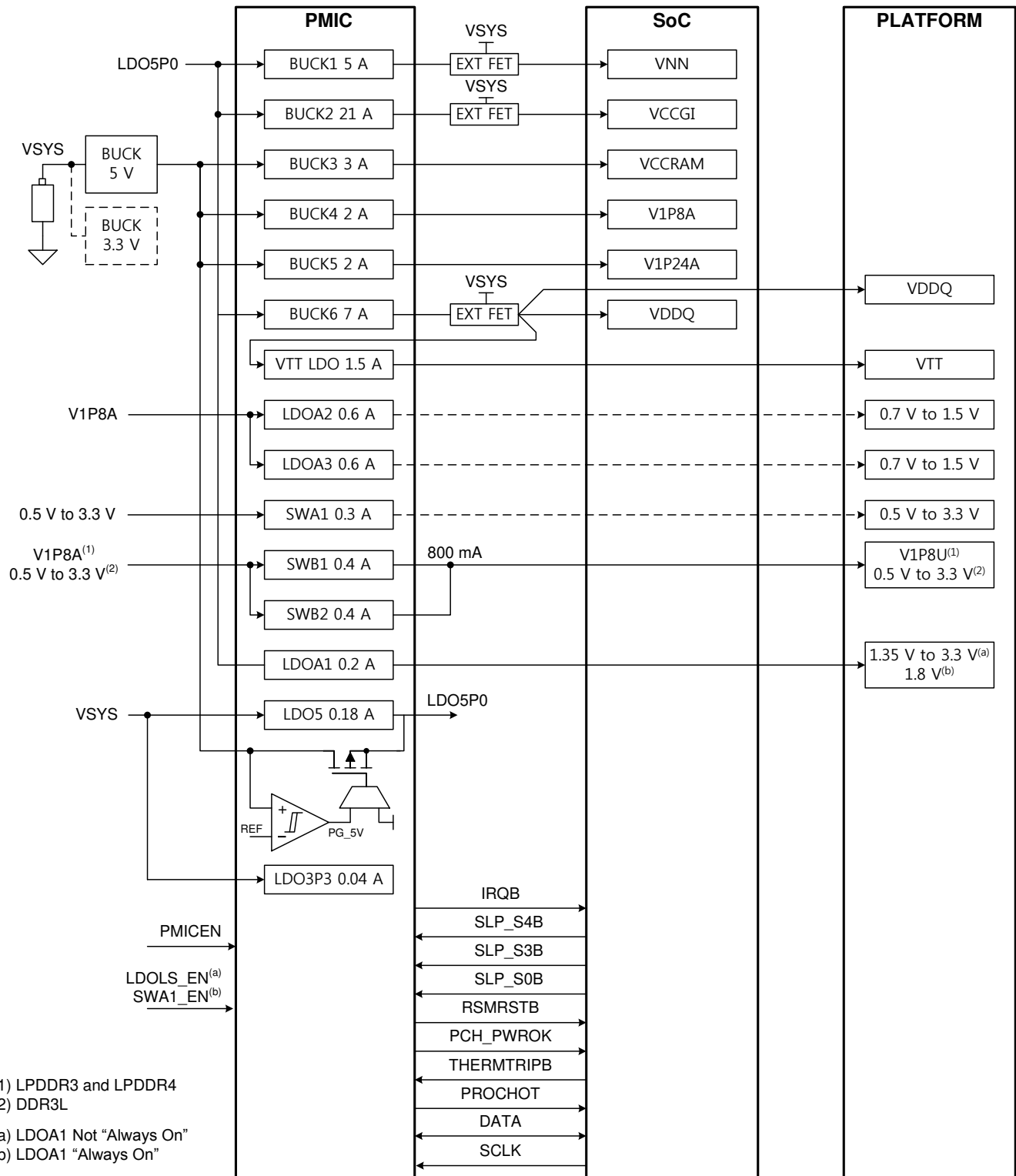
- (1) When powered from a 5-V supply through the DRV5V\_2\_A1 pin. Otherwise, maximum current is limited by maximum  $I_{OUT}$  of LDO5.  
(2) For LPDDR3 and LPDDR4 memory, SWB1\_2 is configured to V1P8U and controlled by SLP\_S4B. For DDR3L memory, SWB1\_2 is configured to either V3P3S or V1P8S and controlled by SLP\_S3B.

## 7.2 Functional Block Diagram

Figure 7-1 shows a functional block diagram of the PMIC.



### Figure 7-1. PMIC Functional Block Diagram



Copyright © 2016, Texas Instruments Incorporated

図 7-2. Apollo Lake Power Map

## 7.3 Feature Description

### 7.3.1 Power Good (PGOOD)

The TPS65094x device provides information on status of VRs through two Power Good signals or pins. 表 7-2 defines which signals are required to assert the PGOOD signals.

表 7-2. Power Good Summary

| POWER GOOD <sup>(1)</sup> | QUALIFYING SIGNALS (LOGICAL AND) |            |                               |             |                 |                                      |                         |                          |                     |                              |                         |
|---------------------------|----------------------------------|------------|-------------------------------|-------------|-----------------|--------------------------------------|-------------------------|--------------------------|---------------------|------------------------------|-------------------------|
|                           | UVLO<br>(VSY<br>S ><br>5.6 V)    | PMIC<br>EN | THERMTR<br>IPB <sup>(2)</sup> | SLP_<br>S4B | SLP_<br>S3<br>B | BUCK1_<br>PG (VNN)<br><sup>(3)</sup> | BUCK4_<br>PG<br>(V1P8A) | BUCK5_P<br>G<br>(V1P24A) | BUCK6_P<br>G (VDDQ) | BUCK3_<br>PG<br>(VCCRA<br>M) | BUCK2_<br>PG<br>(VCCGI) |
| RSMRSTB                   | ✓                                | ✓          | ✓                             |             |                 | ✓                                    | ✓                       | ✓                        |                     |                              |                         |
| PCH_PWROK <sup>(2)</sup>  | ✓                                | ✓          | ✓                             | ✓           | ✓               | ✓                                    | ✓                       | ✓                        | ✓                   | ✓                            | ✓                       |

(1) All Power Good signals must immediately deassert at the loss of any of the qualifying signals, or at the occurrence of a fault condition.

(2) THERMTRIPB is treated as deasserted until the first assertion of RSMRSTB.

(3) BUCK1\_PG is only a part of RSMRSTB Power Good tree until the first assertion of PCH\_PWROK after PMICEN transition (L → H). Also, it becomes part of the PCH\_PWROK Power Good tree only after the first assertion of PCH\_PWROK.

### 7.3.2 Register Reset Conditions

All registers are reset if any of the following conditions are met:

- VSYS pin voltage drops below 5.4 V
- Falling edge of PMICEN for OTPs where LDOA1 is not "Always On"
- Falling edge of THERMTRIPB while RSMRSTB = 1
- Power fault of any regulator where xx\_FLTMSK = 0 (see セクション 7.6.28, PWR\_FAULT\_MASK1 Register, and セクション 7.6.29, PWR\_FAULT\_MASK2 Register)
- PMIC critical temperature shutdown
- Software shutdown (writing 1 to the SDWN bit in the FORCESHUTDOWN register, see 図 7-35)

Additionally, BUCK1 and BUCK2 VID registers are reset on the falling edge of SLP\_S0IXB and SLP\_S3B.

### 7.3.3 SMPS Voltage Regulators

The buck controllers integrate gate drivers for external power stages with programmable current limit (set by an external resistor at ILIMx pin), which allows for optimal selection of external passive components based on the desired system load. The buck converters include integrated power stage and require a minimum number of pins for power input, inductor, and output voltage feedback input. Combined with high-frequency switching, all these features allow use of inductors in small form factor, thus reducing the total cost and size of the system.

BUCK3–BUCK6 have selectable auto- and forced-PWM mode through the BUCKx\_MODE bit in the BUCKxCTRL register. In default auto mode, the VR automatically switches between PWM and PFM depending on the output load to maximize efficiency. The host cannot select Forced PWM mode for other SMPS VRs as they stay in auto mode at all times.

See 表 7-3 and 表 7-4 for the full voltage tables for all SMPS regulators.

表 7-3. 10-mV Step-Size  $V_{OUT}$  Range (BUCK1, BUCK2, BUCK5, BUCK6)

| VID Bits | $V_{OUT}$ | VID Bits | $V_{OUT}$ | VID Bits | $V_{OUT}$ |
|----------|-----------|----------|-----------|----------|-----------|
| 0000000  | 0         | 0101011  | 0.92      | 1010110  | 1.35      |
| 0000001  | 0.50      | 0101100  | 0.93      | 1010111  | 1.36      |
| 0000010  | 0.51      | 0101101  | 0.94      | 1011000  | 1.37      |
| 0000011  | 0.52      | 0101110  | 0.95      | 1011001  | 1.38      |
| 0000100  | 0.53      | 0101111  | 0.96      | 1011010  | 1.39      |
| 0000101  | 0.54      | 0110000  | 0.97      | 1011011  | 1.40      |
| 0000110  | 0.55      | 0110001  | 0.98      | 1011100  | 1.41      |
| 0000111  | 0.56      | 0110010  | 0.99      | 1011101  | 1.42      |
| 0001000  | 0.57      | 0110011  | 1.00      | 1011110  | 1.43      |
| 0001001  | 0.58      | 0110100  | 1.01      | 1011111  | 1.44      |
| 0001010  | 0.59      | 0110101  | 1.02      | 1100000  | 1.45      |
| 0001011  | 0.60      | 0110110  | 1.03      | 1100001  | 1.46      |
| 0001100  | 0.61      | 0110111  | 1.04      | 1100010  | 1.47      |
| 0001101  | 0.62      | 0111000  | 1.05      | 1100011  | 1.48      |
| 0001110  | 0.63      | 0111001  | 1.06      | 1100100  | 1.49      |
| 0001111  | 0.64      | 0111010  | 1.07      | 1100101  | 1.50      |
| 0010000  | 0.65      | 0111011  | 1.08      | 1100110  | 1.51      |
| 0010001  | 0.66      | 0111100  | 1.09      | 1100111  | 1.52      |
| 0010010  | 0.67      | 0111101  | 1.10      | 1101000  | 1.53      |
| 0010011  | 0.68      | 0111110  | 1.11      | 1101001  | 1.54      |
| 0010100  | 0.69      | 0111111  | 1.12      | 1101010  | 1.55      |
| 0010101  | 0.70      | 1000000  | 1.13      | 1101011  | 1.56      |
| 0010110  | 0.71      | 1000001  | 1.14      | 1101100  | 1.57      |
| 0010111  | 0.72      | 1000010  | 1.15      | 1101101  | 1.58      |
| 0011000  | 0.73      | 1000011  | 1.16      | 1101110  | 1.59      |
| 0011001  | 0.74      | 1000100  | 1.17      | 1101111  | 1.60      |
| 0011010  | 0.75      | 1000101  | 1.18      | 1110000  | 1.61      |
| 0011011  | 0.76      | 1000110  | 1.19      | 1110001  | 1.62      |
| 0011100  | 0.77      | 1000111  | 1.20      | 1110010  | 1.63      |
| 0011101  | 0.78      | 1001000  | 1.21      | 1110011  | 1.64      |
| 0011110  | 0.79      | 1001001  | 1.22      | 1110100  | 1.65      |
| 0011111  | 0.80      | 1001010  | 1.23      | 1110101  | 1.66      |
| 0100000  | 0.81      | 1001011  | 1.24      | 1110110  | 1.67      |
| 0100001  | 0.82      | 1001100  | 1.25      | 1110111  | 1.67      |
| 0100010  | 0.83      | 1001101  | 1.26      | 1111000  | 1.67      |
| 0100011  | 0.84      | 1001110  | 1.27      | 1111001  | 1.67      |
| 0100100  | 0.85      | 1001111  | 1.28      | 1111010  | 1.67      |
| 0100101  | 0.86      | 1010000  | 1.29      | 1111011  | 1.67      |
| 0100110  | 0.87      | 1010001  | 1.30      | 1111100  | 1.67      |
| 0100111  | 0.88      | 1010010  | 1.31      | 1111101  | 1.67      |
| 0101000  | 0.89      | 1010011  | 1.32      | 1111110  | 1.67      |
| 0101001  | 0.90      | 1010100  | 1.33      | 1111111  | 1.67      |
| 0101010  | 0.91      | 1010101  | 1.34      |          |           |

表 7-4. 25-mV Step-Size  $V_{OUT}$  Range (BUCK3, BUCK4)

| VID Bits | $V_{OUT}$ | VID Bits | $V_{OUT}$ | VID Bits | $V_{OUT}$ |
|----------|-----------|----------|-----------|----------|-----------|
| 0000000  | 0         | 0101011  | 1.700     | 1010110  | 2.775     |
| 0000001  | 0.650     | 0101100  | 1.725     | 1010111  | 2.800     |
| 0000010  | 0.675     | 0101101  | 1.750     | 1011000  | 2.825     |
| 0000011  | 0.700     | 0101110  | 1.775     | 1011001  | 2.850     |
| 0000100  | 0.725     | 0101111  | 1.800     | 1011010  | 2.875     |
| 0000101  | 0.750     | 0110000  | 1.825     | 1011011  | 2.900     |
| 0000110  | 0.775     | 0110001  | 1.850     | 1011100  | 2.925     |
| 0000111  | 0.800     | 0110010  | 1.875     | 1011101  | 2.950     |
| 0001000  | 0.825     | 0110011  | 1.900     | 1011110  | 2.975     |
| 0001001  | 0.850     | 0110100  | 1.925     | 1011111  | 3.000     |
| 0001010  | 0.875     | 0110101  | 1.950     | 1100000  | 3.025     |
| 0001011  | 0.900     | 0110110  | 1.975     | 1100001  | 3.050     |
| 0001100  | 0.925     | 0110111  | 2.000     | 1100010  | 3.075     |
| 0001101  | 0.950     | 0111000  | 2.025     | 1100011  | 3.100     |
| 0001110  | 0.975     | 0111001  | 2.050     | 1100100  | 3.125     |
| 0001111  | 1.000     | 0111010  | 2.075     | 1100101  | 3.150     |
| 0010000  | 1.025     | 0111011  | 2.100     | 1100110  | 3.175     |
| 0010001  | 1.050     | 0111100  | 2.125     | 1100111  | 3.200     |
| 0010010  | 1.075     | 0111101  | 2.150     | 1101000  | 3.225     |
| 0010011  | 1.100     | 0111110  | 2.175     | 1101001  | 3.250     |
| 0010100  | 1.125     | 0111111  | 2.200     | 1101010  | 3.275     |
| 0010101  | 1.150     | 1000000  | 2.225     | 1101011  | 3.300     |
| 0010110  | 1.175     | 1000001  | 2.250     | 1101100  | 3.325     |
| 0010111  | 1.200     | 1000010  | 2.275     | 1101101  | 3.350     |
| 0011000  | 1.225     | 1000011  | 2.300     | 1101110  | 3.375     |
| 0011001  | 1.250     | 1000100  | 2.325     | 1101111  | 3.400     |
| 0011010  | 1.275     | 1000101  | 2.350     | 1110000  | 3.425     |
| 0011011  | 1.300     | 1000110  | 2.375     | 1110001  | 3.450     |
| 0011100  | 1.325     | 1000111  | 2.400     | 1110010  | 3.475     |
| 0011101  | 1.350     | 1001000  | 2.425     | 1110011  | 3.500     |
| 0011110  | 1.375     | 1001001  | 2.450     | 1110100  | 3.525     |
| 0011111  | 1.400     | 1001010  | 2.475     | 1110101  | 3.550     |
| 0100000  | 1.425     | 1001011  | 2.500     | 1110110  | 3.575     |
| 0100001  | 1.450     | 1001100  | 2.525     | 1110111  | 3.575     |
| 0100010  | 1.475     | 1001101  | 2.550     | 1111000  | 3.575     |
| 0100011  | 1.500     | 1001110  | 2.575     | 1111001  | 3.575     |
| 0100100  | 1.525     | 1001111  | 2.600     | 1111010  | 3.575     |
| 0100101  | 1.550     | 1010000  | 2.625     | 1111011  | 3.575     |
| 0100110  | 1.575     | 1010001  | 2.650     | 1111100  | 3.575     |
| 0100111  | 1.600     | 1010010  | 2.675     | 1111101  | 3.575     |
| 0101000  | 1.625     | 1010011  | 2.700     | 1111110  | 3.575     |
| 0101001  | 1.650     | 1010100  | 2.725     | 1111111  | 3.575     |
| 0101010  | 1.675     | 1010101  | 2.750     |          |           |

The controllers are fast-reacting, high-frequency, scalable output power controllers capable of driving two external N-MOSFETs. They use a D-CAP2 control scheme that optimizes transient responses at high load currents for such applications as CORE and DDR supplies. The output voltage is compared with internal reference voltage after divider resistors. The PWM comparator determines the timing to turn on the high-side MOSFET. The PWM comparator response maintains a very small PWM output ripple voltage. Because the device does not have a dedicated oscillator for control loop on board, switching cycle is controlled by the adaptive ON time circuit. The ON time is controlled to meet the target switching frequency by feed-forwarding the input and output voltage into the ON time one-shot timer.

The diagram illustrates the internal architecture of the PMIC, showing the flow of signals and power between various functional blocks. The blocks are categorized into PMIC Internal Signals (dashed boxes) and External Inputs/Outputs (solid boxes).

**PMIC Internal Signals (dashed boxes):**

- DCHG
- VFB
- REF
- VSYS
- ILIM
- GND

**External Inputs/Outputs (solid boxes):**

- VDD
- PGOOD
- FAULT
- EN
- BOOTx
- DRVHx
- SWx
- DRV5V\_x\_x
- DRVLx
- PGNDSNSx

**Internal Functional Blocks:**

- UV (Under-Voltage) and OV (Over-Voltage) Comparators:** These comparators monitor the VREF - VTH\_PG and VREF + VTH\_PG signals. Their outputs are connected to the PGOOD signal.
- Control Logic:** This central block receives inputs from the UV, OV, PWM, and ZC comparators, and the VSYS signal. It outputs control signals to the HS, LS, XCON, and One-Shot blocks.
- PWM (Pulse Width Modulation) and SS Ramp Comp (Switching Ramp Compensation) Blocks:** These blocks process the VFB and REF signals to generate a PWM signal and a ramp compensation signal, which are then fed into the Control Logic.
- OC (Output Current) and NOC (No-Output Current) Comparators:** These comparators monitor the output current (IOUT) and its derivative (dIOUT/dt) using a 50 μA current source and resistors. Their outputs are connected to the Control Logic.
- ZC (Zero-Current) Comparator:** This comparator monitors the output current (IOUT) and its derivative (dIOUT/dt) using a 50 μA current source and resistors. Its output is connected to the Control Logic.
- HS (High-Side) and LS (Low-Side) Drivers:** These drivers control the power MOSFETs (HS and LS) in the power stage. They receive control signals from the Control Logic and the XCON block.
- XCON (X-Capacitor Control) and One-Shot Blocks:** These blocks manage the X-Capacitor (XCAP) and generate a one-shot pulse, respectively. They receive control signals from the Control Logic and the HS/LS drivers.

**Legend:**

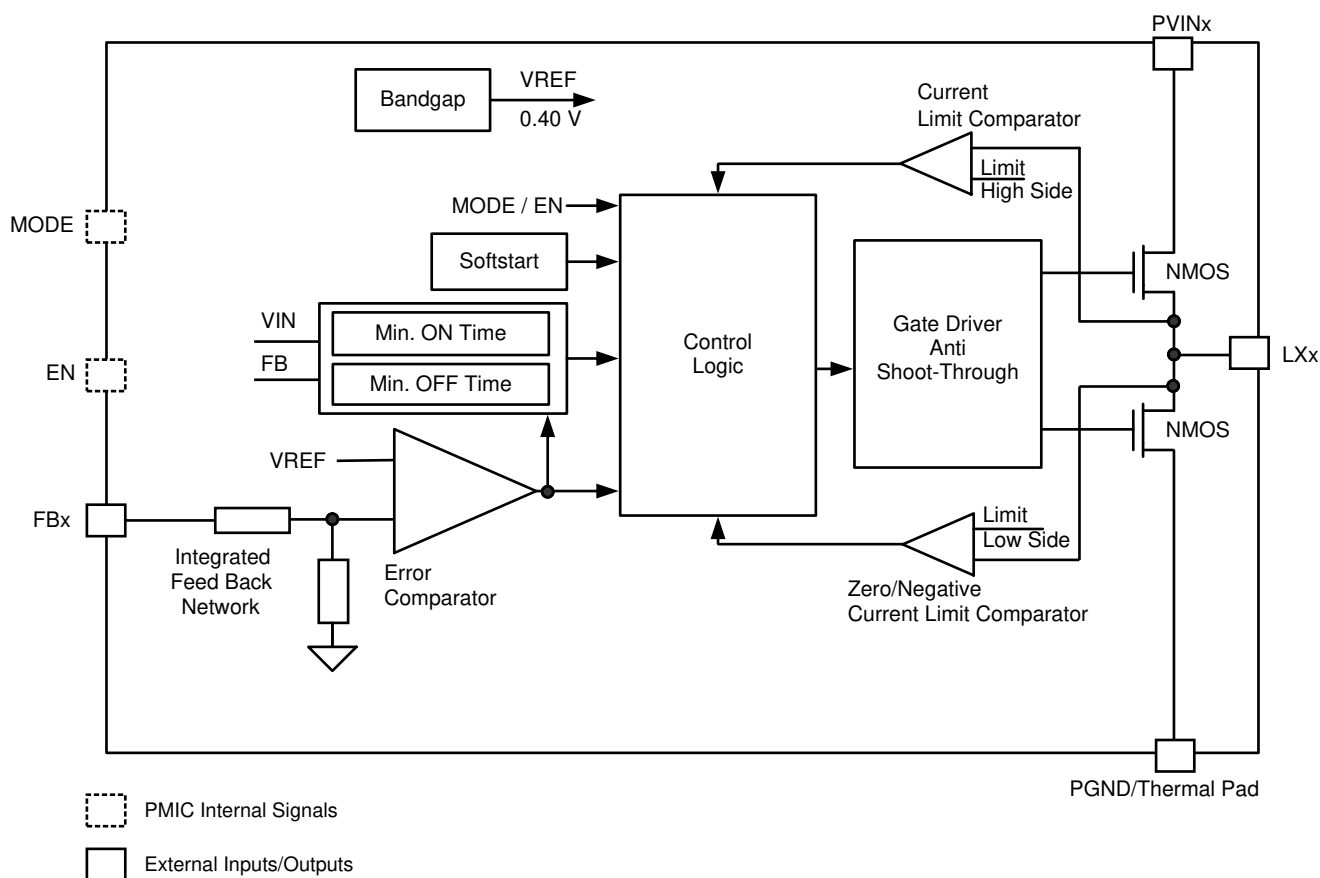
- PMIC Internal Signals (dashed box)
- External Inputs/Outputs (solid box)

English Data Sheet: [SWCS133](#)

### 7.3.3.2 Converter Overview

The PMIC synchronous step-down DC-DC converters include a unique hysteretic PWM control scheme which enables a high switching frequency converter, excellent transient and AC load regulation, as well as operation with cost-competitive external components. The controller topology supports forced PWM mode as well as power-save mode operation. Power-save mode operation, or PFM mode, reduces the quiescent current consumption and ensures high conversion efficiency at light loads by skipping switch pulses. In forced PWM mode, the device operates on a quasi-fixed frequency, avoids pulse skipping, and allows filtering of the switch noise by external filter components. The PMIC device offers fixed output voltage options featuring smallest solution size by using only three external components per converter.

A significant advantage of PMIC compared to other hysteretic PWM controller topologies is the excellent capability of the AC load transient regulation. When the output voltage falls below the threshold of the error comparator, a switch pulse is initiated, and the high-side switch is turned on. The high-side switch remains turned on until a minimum ON-time of  $t_{ONmin}$  expires and the output voltage trips the threshold of the error comparator or the inductor current reaches the high-side switch current limit. When the high-side switch turns off, the low-side switch rectifier is turned on and the inductor current ramps down until the high-side switch turns on again or the inductor current reaches zero. In forced PWM mode operation, negative inductor current is allowed to enable continuous conduction mode even at no load condition.



Copyright © 2016, Texas Instruments Incorporated

**7-4. Converter Block Diagram**



### 7.3.3.3 DVS

BUCK1–BUCK6 and LDOA1–3 support dynamic voltage scaling (DVS) for maximum system efficiency. The VR outputs can slew up and down in either 10-mV or 25-mV steps using the 7-bit voltage ID (VID) defined in [セクション 6.7, Electrical Characteristics: Buck Controllers](#), and [セクション 6.8, Electrical Characteristics: Synchronous Buck Converters](#). DVS slew rate is minimum 2.5 mV/μs. To meet the minimum slew rate, VID progresses to the next code at 3-μs (nom) interval per 10-mV step. When DVS is active, the VR is forced into PWM mode to ensure the output keeps track of VID code with minimal delay. Additionally, PGOOD is masked when DVS is in progress. [図 7-5](#) shows an example of slew down and up from one VID to another.

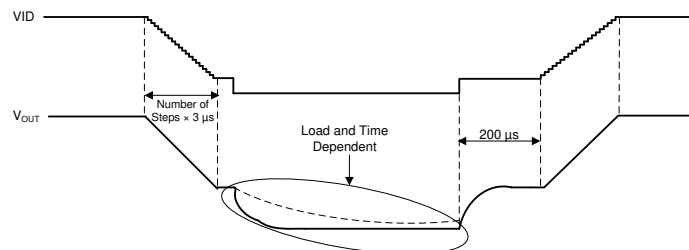


**図 7-5. DVS Timing Diagram I**

As shown in [図 7-6](#), if a BUCKx\_VID[6:0] is set to 7b000 0000, the output voltage slews down to 0.5 V first, and then drifts down to 0 V as the SMPS stops switching. Subsequently, if a BUCKx\_VID[6:0] is set to a value (neither 7b000 0000 nor 7b000 0001) when the output voltage is less than 0.5 V, the VR ramps up to 0.5 V first with soft-start kicking in, then it slews up to the target voltage in the aforementioned slew rate.

注

A fixed 200 μs of soft-start time is reserved for V<sub>OUT</sub> to reach 0.5 V. In this case, however, the SMPS is not forced into PWM mode because it otherwise could cause V<sub>OUT</sub> to droop momentarily if V<sub>OUT</sub> is drifting above 0.5 V for any reason.



**図 7-6. DVS Timing Diagram II**

### 7.3.3.4 Current Limit

The buck controllers (BUCK1, BUCK2, and BUCK6) have inductor-valley current-limit architecture and the current limit is programmable by an external resistor at the ILIMx pin. [式 1](#) shows the calculation for a desired resistor value, depending on specific application conditions. I<sub>LIMREF</sub> is the current source out of the ILIMx pin that is typically 50 μA, and R<sub>DS(on)</sub> is the maximum channel resistance of the low-side FET. The scaling factor is 1.3 to take into account all errors and temperature variations of R<sub>DS(on)</sub>, I<sub>LIMREF</sub>, and R<sub>ILIM</sub>. Finally, 8 is another scaling factor associated with I<sub>LIMREF</sub>.

$$R_{ILIM} = \frac{R_{DS(on)} \times 8 \times 1.3 \times \left( I_{LIM} - \frac{I_{ripple(min)}}{2} \right)}{I_{LIMREF}} \quad (1)$$

where

- $I_{LIM}$  is the target current limit. An appropriate margin must be allowed when determining  $I_{LIM}$  from maximum output DC load current.
- $I_{ripple(min)}$  is the minimum peak-to-peak inductor ripple current for a given  $V_{OUT}$ .

$$I_{ripple(min)} = \frac{V_{OUT} (V_{IN(MIN)} - V_{OUT})}{L_{max} \times V_{IN(MIN)} \times f_{sw(max)}} \quad (2)$$

where

- $L_{max}$  is maximum inductance
- $f_{sw(max)}$  is maximum switching frequency
- $V_{IN(MIN)}$  minimum input voltage to the external power stage

The buck converter limit inductor peak current cycle-by-cycle to  $I_{IND\_LIM}$  is specified in [セクション 6.8, Electrical Characteristics: Synchronous Buck Converters](#).

### 7.3.4 LDOs and Load Switches

#### 7.3.4.1 VTT LDO

Powered from the BUCK6 output (VDDQ), the VTT LDO tracks VDDQ and regulates to half of the VDDQ voltage for proper DDR termination. The LDO current limit is OTP dependent, and it is designed specifically to power DDR memory. The VTT LDO is enabled by assertion (L → H) of the SLP\_S0B pin and is disabled by deassertion (H → L) of the same pin. The LDO core is a transconductance amplifier with large gain, and it drives a current output stage that either sources or sinks current depending on the deviation of VTTFB pin voltage from the target regulation voltage.

#### 7.3.4.2 LDOA1–LDOA3

The TPS65094x device integrates three optional general-purpose LDOs. LDOA1 is powered from a 5-V supply through the DRV5V\_2\_A1 pin and it can be factory configured to be an Always-On rail as long as a valid power supply is available at VSYS. See [表 7-5](#) for LDOA1 output voltage options. LDOA2 and LDOA3 share a power input pin (PVINLDOA2\_A3). The output regulation voltages are set by writing to LDOAx\_VID[3:0] bits (Reg 0x9A, 0x9B, and 0xAE). See [表 7-6](#) for LDOA2 and LDOA3 output voltage options. LDOA1 is controlled by LDOA1CTRL register. LDOA2 and LDOA3 can be controlled either by the LDOLS\_EN pin or by writing to the LDOA2\_EN bit (Reg 0xA0) and the LDOA3\_EN bit (Reg 0xA1) as long as LDOLS\_EN is low.

**表 7-5. LDOA1 Output Voltage Options**

| VID Bits | V <sub>OUT</sub> | VID Bits | V <sub>OUT</sub> | VID Bits | V <sub>OUT</sub> | VID Bits | V <sub>OUT</sub> |
|----------|------------------|----------|------------------|----------|------------------|----------|------------------|
| 0000     | 1.35             | 0100     | 1.8              | 1000     | 2.3              | 1100     | 2.85             |
| 0001     | 1.5              | 0101     | 1.9              | 1001     | 2.4              | 1101     | 3.0              |
| 0010     | 1.6              | 0110     | 2.0              | 1010     | 2.5              | 1110     | 3.3              |
| 0011     | 1.7              | 0111     | 2.1              | 1011     | 2.7              | 1111     | Not Used         |

**表 7-6. LDOA2 and LDOA3 Output Voltage Options**

| VID Bits | V <sub>OUT</sub> | VID Bits | V <sub>OUT</sub> | VID Bits | V <sub>OUT</sub> | VID Bits | V <sub>OUT</sub> |
|----------|------------------|----------|------------------|----------|------------------|----------|------------------|
| 0000     | 0.70             | 0100     | 0.90             | 1000     | 1.10             | 1100     | 1.30             |
| 0001     | 0.75             | 0101     | 0.95             | 1001     | 1.15             | 1101     | 1.35             |
| 0010     | 0.80             | 0110     | 1.00             | 1010     | 1.20             | 1110     | 1.40             |
| 0011     | 0.85             | 0111     | 1.05             | 1011     | 1.25             | 1111     | 1.50             |

#### 7.3.4.3 Load Switches

The PMIC features three general-purpose load switches. SWA1 has a power input pin (PVINSWA1), while SWB1 and SWB2 share a power input pin (PVINSWB1\_B2). All switches have built-in slew rate control during start-up to limit the inrush current.

表 7-7 lists the control signals for enabling and disabling each LDO and load switch.

**表 7-7. Summary of LDO and Load Switch Control**

| CONTROL SIGNAL                    | RAIL               |
|-----------------------------------|--------------------|
| SLP_S4B or SLP_S3B <sup>(1)</sup> | SWB1_2             |
| LDOLS_EN <sup>(2)</sup>           | LDOA2, LDOA3, SWA1 |
| SWA1_EN <sup>(3)</sup>            | SWA1               |
| SLP_S0B <sup>(4)</sup>            | VTT LDO            |

- (1) For LPDDR3 and LPDDR4 memory, SWB1\_2 is configured to V1P8U and controlled by SLP\_S4B. For DDR3L memory, SWB1\_2 is configured to either V3P3S or V1P8S and controlled by SLP\_S3B.
- (2) When LDOLS\_EN = 0, the user can write to enable bits in Reg 0xA0–Reg 0xA1 to enable or disable the rails. Alternatively, all of them may be factory configured to be part of sequence along with other voltage rails. Pin name changed to SWA1\_EN when LDOA1 is factory programmed to always on.
- (3) When SWA1\_EN = 0, the user can write to enable bits in Reg 0xA0–Reg 0xA1 to enable or disable the rails. Alternatively, all of them may be factory configured to be part of sequence along with other voltage rails. Pin name changed to LDOLS\_EN when LDOA1 is not factory programmed to always on.
- (4) BUCK6\_PG must be asserted as well.

### 7.3.5 Power Sequencing and VR Control

When a valid power source is available at VSYS (VSYS ≥ 5.6 V), internal analog blocks including LDO5 and LDO3P3 are enabled. For part numbers with LDOA1 set as an always on rail, the PMIC leaves reset and I<sup>2</sup>C communication is available as soon as LDO3P3 and LDO5 power goods are confirmed. For part numbers with LDOA1 set as a general-purpose LDO, the PMIC remains in reset until PMICEN is set high. Five input pins of the TPS65094x device are driven by a host or by external-controller (EC) defined power states that transition from one to another in sequence.

表 7-8 shows various system-level power states. Also, 表 7-9 summarizes a list of active rails in each power state. The sequencing for the transitions between these states is described in the following sections.

If a rail is either disabled by I<sup>2</sup>C or OTP programming, then it is not enabled by the following sequences. For example, VTT LDO is not enabled for LPDDR4 OTPs.

**表 7-8. Power State and Corresponding I/O Status**

| POWER STATE | SIGNALS TO PMIC |                        |                        |                        |                           | SIGNALS FROM PMIC |           |
|-------------|-----------------|------------------------|------------------------|------------------------|---------------------------|-------------------|-----------|
|             | PMICEN          | SLP_S4B <sup>(1)</sup> | SLP_S3B <sup>(1)</sup> | SLP_S0B <sup>(2)</sup> | THERMTRIPB <sup>(3)</sup> | RSMRSTB           | PCH_PWROK |
| G3          | 0               | 0                      | 0                      | 0                      | 0                         | 0                 | 0         |
| S4/S5       | 1               | 0                      | 0                      | 1                      | 1                         | 1                 | 0         |
| S3          | 1               | 1                      | 0                      | 1                      | 1                         | 1                 | 0         |
| S0iX        | 1               | 1                      | 1                      | 0                      | 1                         | 1                 | 1         |
| S0          | 1               | 1                      | 1                      | 1                      | 1                         | 1                 | 1         |

- (1) When PMIC is first enabled, SLP\_S4B and SLP\_S3B are to be treated as if they are low (actual state of signal ignored) until the deassertion of RSMRSTB (L → H).
- (2) When PMIC is first enabled, SLP\_S0B are to be treated as if they are high (actual state of signal ignored) until the assertion of PCH\_PWROK (L → H).
- (3) THERMTRIPB is to be treated as if it is high (actual state of signal ignored) until the deassertion of RSMRSTB (L → H).

**表 7-9. Active Rails in Each Power State**

| POWER STATE | ACTIVE RAILS  |
|-------------|---|
| S4/S5       | BUCK1 (VNN), BUCK4 (V1P8A), BUCK5 (V1P24A)                    |
| S3          | Rails in S4/S5 + SWB1_2 (V1P8U) <sup>(1)</sup> , BUCK6 (VDDQ) |

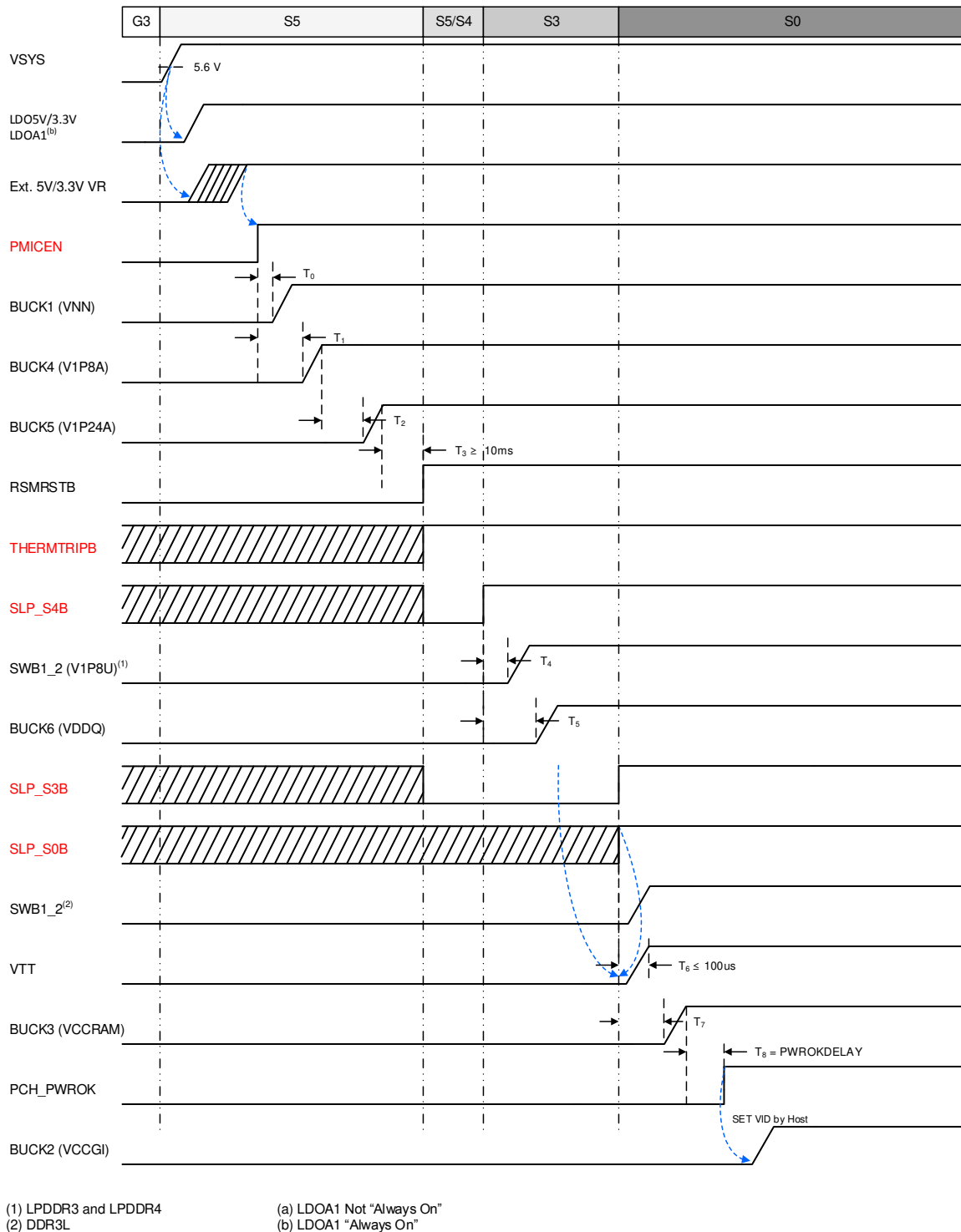
表 7-9. Active Rails in Each Power State (続き)

| POWER STATE | ACTIVE RAILS   |
|-------------|--|
| S0          | Rails in S3 + SWB1_2 <sup>(2)</sup> , VTT, BUCK2 (VCCGI), BUCK3 (VCCRAM) |
| S0iX        | Rails in S0 – BUCK1 (VNN), BUCK2 (VCCGI), BUCK3 (VCCRAM), VTT            |

(1) For LPDDR3 and LPDDR4

(2) For DDR3L

### 7.3.5.1 Cold Boot



**7-7. Cold Boot Sequence**

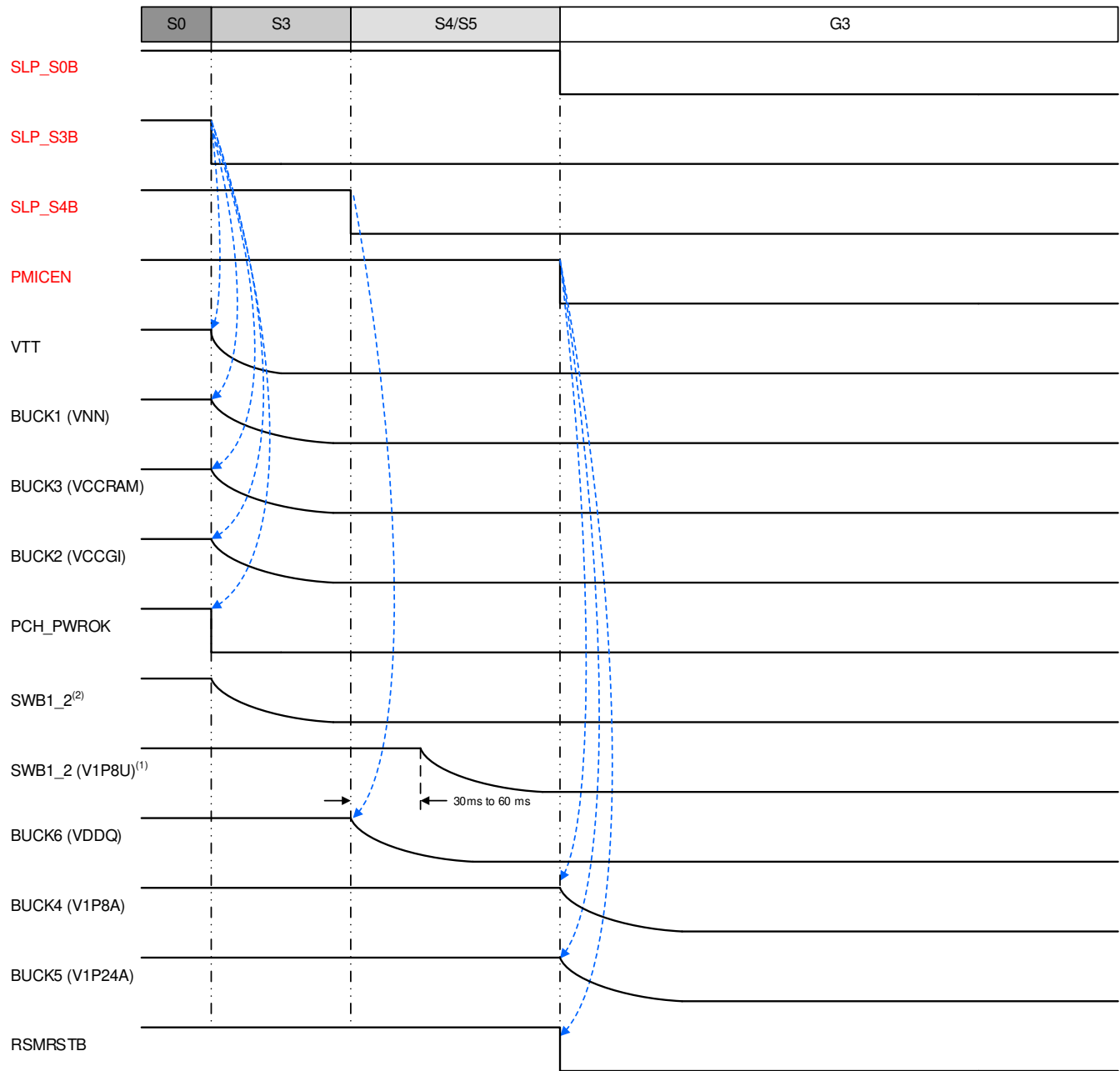
As  $V_{\text{SYS}}$  crosses above  $V_{\text{SYS\_UVLO\_5V}} + V_{\text{SYS\_UVLO+5V\_HYS}}$ , the cold-boot sequence is initiated by pulling the PMICEN pin high followed by driving the remaining control pins high in order. SLP\_S3B and SLP\_S4B may go high at the same time. SLP\_S0B is not defined until the first transition to S0 after RSMRSTB deassertion. SLP\_S0B is defined for all Sx power-state transitions after the first transition to S0.

表 7-10 lists definitions of the timing delays. These timing delays also apply to the subsequent sequences. T0 to T10 are factory programmable to 0 ms, 2 ms, 4 ms, 8 ms, 16 ms, 24 ms, 32 ms, or 64 ms.

**表 7-10. Definition of Delays During Cold Boot Sequence**

| DELAY | DESCRIPTION  | TYP VALUE | UNIT |
|-------|--|-----------|------|
| T0    | PMICEN to BUCK1 (VNN) enable   | 0         | ms   |
| T1    | PMICEN to BUCK4 (V1P8A) enable   | 4         | ms   |
| T2    | BUCK4 PG to BUCK5 (V1P24A) enable  | 0         | ms   |
| T3    | BUCK5 PG to RSMRSTB deassertion  | 10        | ms   |
| T4    | SLP_S4B deassertion to SWB1_2 (V1P8U) enable   | 0         | ms   |
| T5    | SLP_S4B deassertion to BUCK6 (VDDQ) enable   | 4         | ms   |
| T6    | Logical AND of BUCK6 PG, SLP_S0B, SLP_S3B, and SLP_S4B to VTT enable                                   | 0         | ms   |
| T7    | SLP_S0B deassertion to BUCK3 (VCCRAM) enable   | 2         | ms   |
| T8    | Logical AND of all PGs (except BUCK2) to PCH_PWROK assertion. User selectable from POK_DELAY register. | 100       | ms   |

### 7.3.5.2 Cold OFF

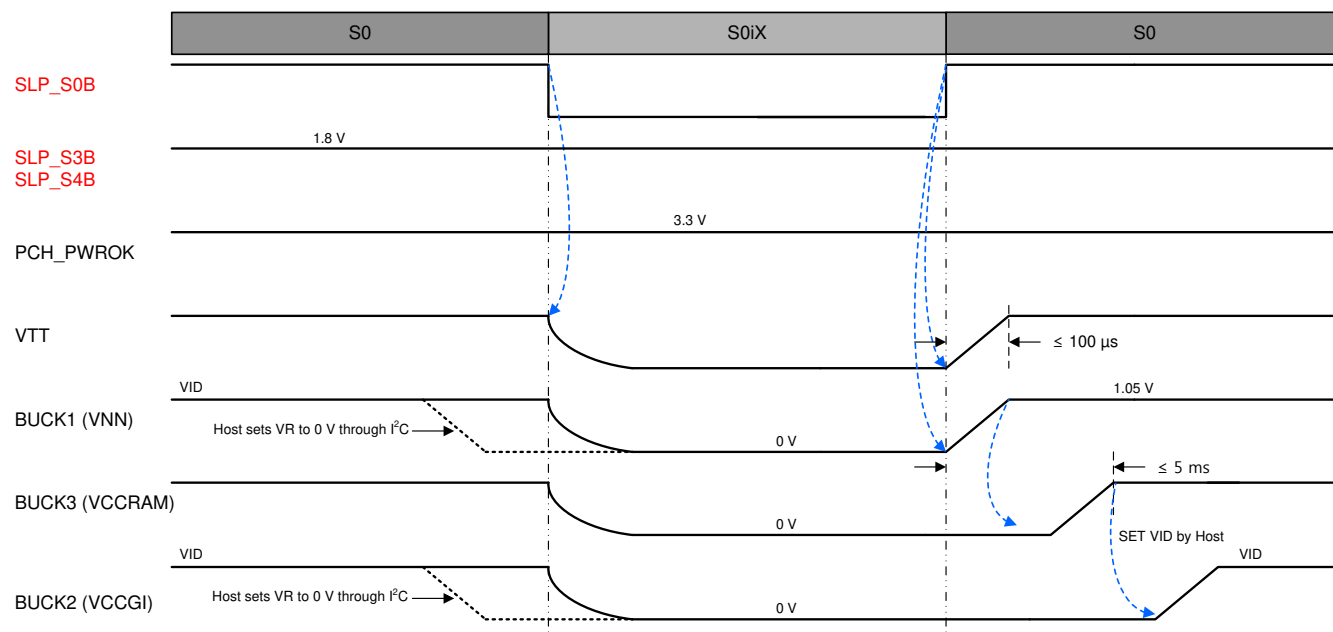


(1) LPDDR3 and LPDDR4  
(2) DDR3L

図 7-8. Cold OFF Sequence

Cold OFF sequence is initiated by pulling the SLP\_S3B pin low in the S0 state, followed by SLP\_S4B, SLP\_S0B, and PMICEN.

### 7.3.5.3 Connected Standby Entry and Exit



**図 7-9. Connected Standby Entry and Exit Sequence**

S0 to S0iX (Connected Standby) entry and exit occurs when SLP\_S0B is pulled low and high, respectively. In Connected Standby state, VTT LDO is turned off, but all PGOODs remain asserted. BUCK1–BUCK3 are not disabled, but instead stop switching while BUCK4–BUCK6 remain in regulation. SWB1\_2 also stays enabled. On entry, BUCK2 and BUCK3 decay to 0 V with their VID registers retaining the last programmed values to which the BUCKs ramp back up on exit. The host can write to BUCK2CTRL and BUCK3CTRL registers regardless of the state of the SLP\_S0B pin while SLP\_S3B and SLP\_S4B are high, which means that BUCK2 and BUCK3 can be changed to ramp to a different voltage upon exiting S0iX than they had when entering S0iX state. BUCK1 ramps back up to the default value (1.05 V).

表 7-11 summarizes status of each VR in Connected Standby state.

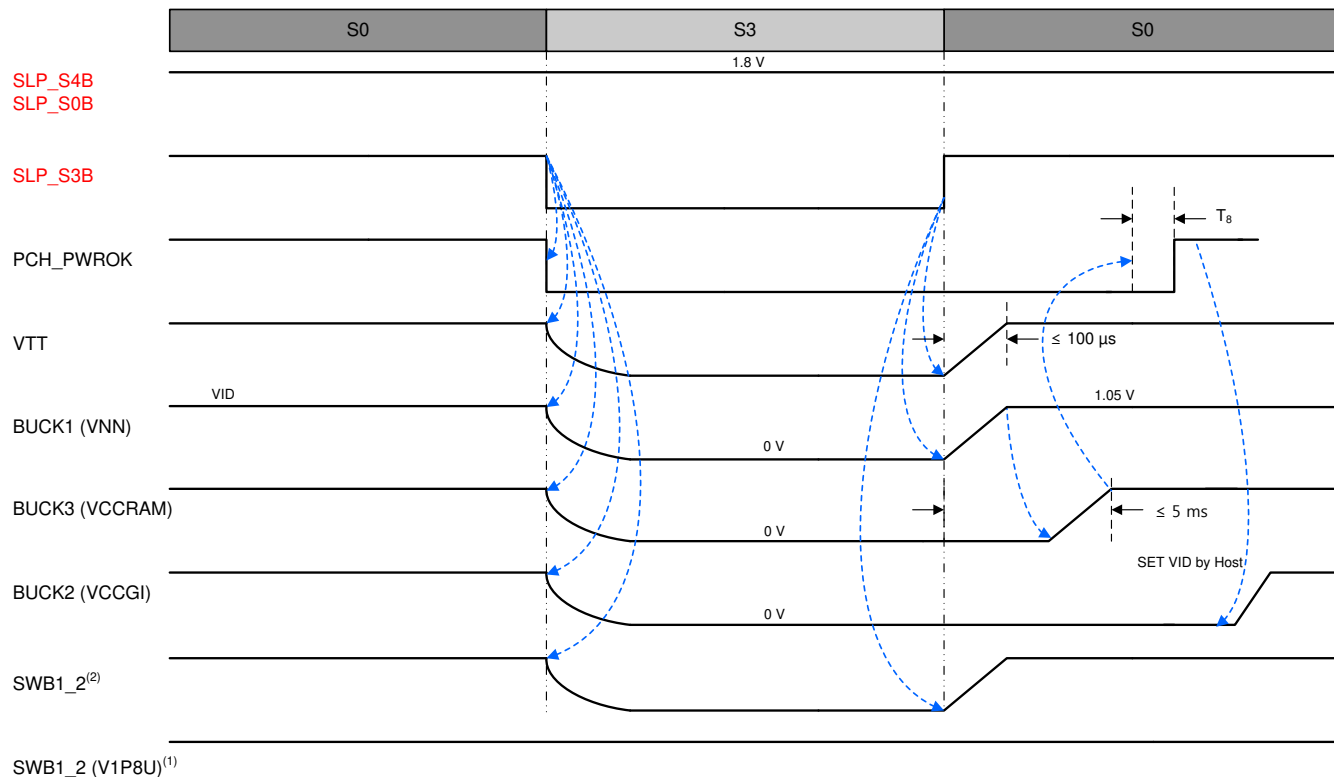
**表 7-11. Summary of Rails on Connected Standby Entry and Exit**

| VR             | S0 → S0iX     | S0iX → S0     |
|----------------|---------------|---------------|
| BUCK1 (VNN)    | 0 V           | 1.05 V        |
| BUCK2 (VCCGI)  | 0 V           | 0 V           |
| BUCK3 (VCCRAM) | 0 V           | 1.05 V        |
| BUCK4 (V1P8A)  | VID value     | VID value     |
| BUCK5 (V1P24A) | VID value     | VID value     |
| BUCK6 (VDDQ)   | OTP dependent | OTP dependent |
| VTT LDO (VTT)  | OFF           | VDDQ / 2      |
| SWB1_2         | ON            | ON            |



### 7.3.5.4 S0 to S3 Entry and Exit

Assertion of SLP\_S3B (H → L) triggers S3 entry. Deassertion of SLP\_S3B causes S3 exit and S0 entry as depicted in 図 7-10. On S3 exit, BUCK1–BUCK3 behave exactly the same way as they do on S0iX exit, which is explained in セクション 7.3.5.3, *Connected Standby Entry and Exit*.

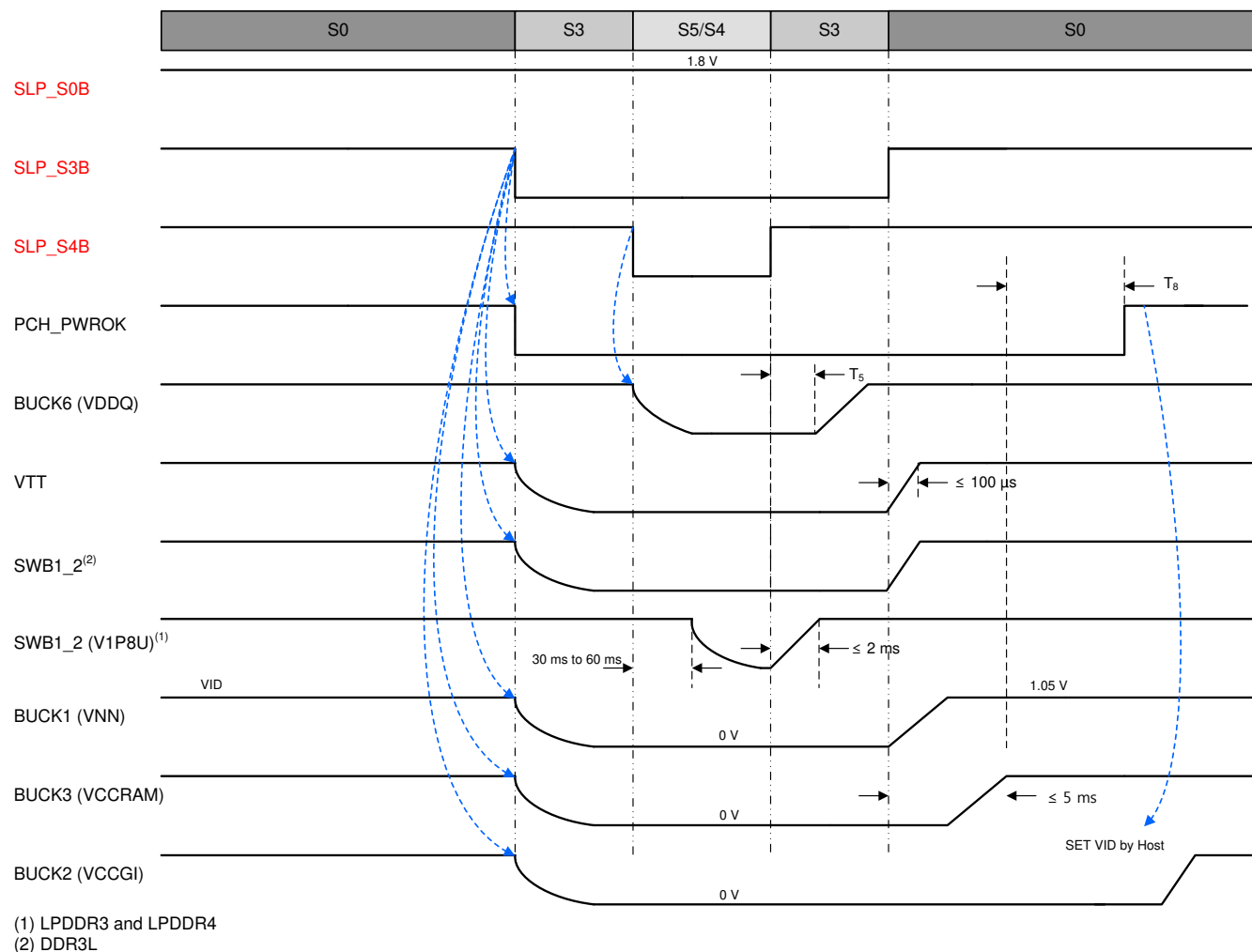


(1) LPDDR3 and LPDDR4  
(2) DDR3L

図 7-10. S3 Entry and Exit Sequence

### 7.3.5.5 S0 to S4/5 Entry and Exit

Assertion of the SLP\_S4B (H → L) after the S3 entry pushes the sequence further down to S4/5 where SWB1\_2 (for LPDDR3 or LPDDR4) and BUCK6 are disabled. Any rails not shown are essentially the same as the S0 to S3 entry and exit case described in [Figure 7-11](#).



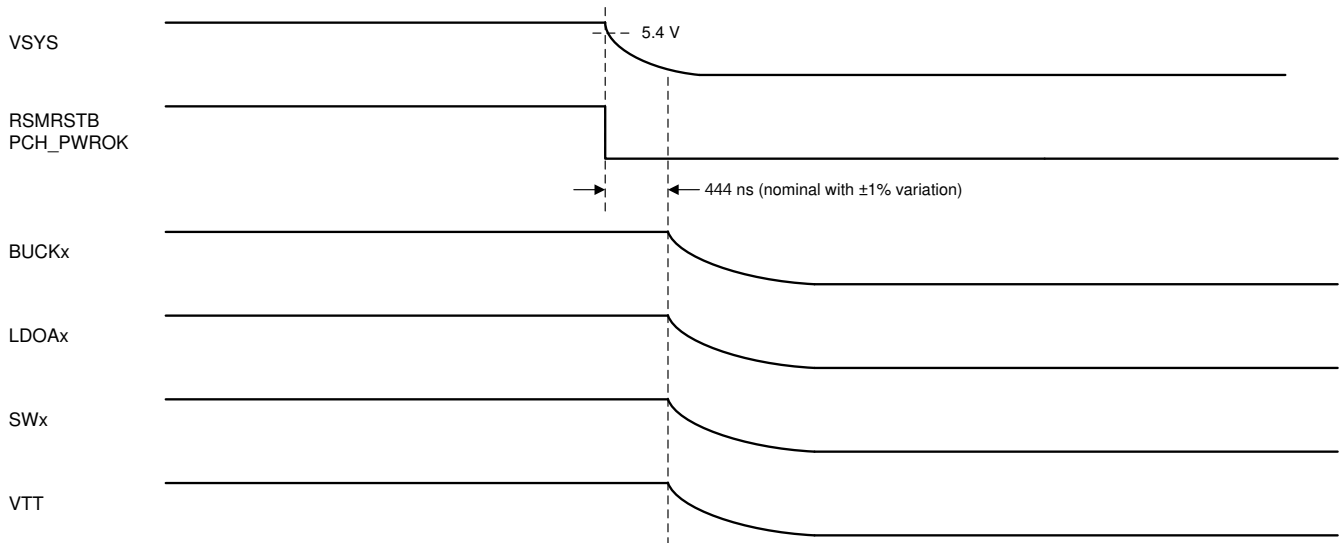
**Figure 7-11. S4/5 Entry and Exit Sequence**

### 7.3.5.6 Emergency Shutdown

When  $V_{SYS}$  crosses below  $V_{SYS\_UVLO\_5V}$ , all Power Good pins are deasserted; after 444 ns (nominal) of delay, all VRs shut down (see [図 7-12](#)). Upon shutdown, all internal discharge resistors are set to 100  $\Omega$  to ensure timely decay of all VR outputs.  $V_{SYS}$  crossing above  $V_{SYS\_UVLO\_5V} + V_{SYS\_UVLO\_5V\_HYS}$  and assertion of PMICEN is required to re-enable the VRs.

Other conditions that cause emergency shutdown are the following:

- The die temperature rising above the critical temperature threshold ( $T_{CRIT}$ )
- Falling edge of THERMTRIPB
- Deassertion of Power Good of any rail or failure to reach power good within 10 ms of enable (configurable)



**図 7-12. Emergency Shutdown Sequence**

## 7.4 Device Functional Modes

### 7.4.1 Off Mode

When power supply at the  $V_{SYS}$  pin is less than  $V_{SYS\_UVLO\_5V}$  (5.4-V nominal) +  $V_{SYS\_UVLO\_5V\_HYS}$  (0.2-V nominal), the device is in off mode, where all output rails are disabled. If the supply voltage is greater than  $V_{SYS\_UVLO\_3V}$  (3.6-V nominal) +  $V_{SYS\_UVLO\_3V\_HYS}$  (0.15-V nominal) while it is still less than  $V_{SYS\_UVLO\_5V} + V_{SYS\_UVLO\_5V\_HYS}$ , then the internal band-gap reference ( $V_{REF}$  pin) along with LDO3P3 are enabled and regulated at target values.

### 7.4.2 Standby Mode

When power supply at the  $V_{SYS}$  pin rises above  $V_{SYS\_UVLO\_5V} + V_{SYS\_UVLO\_5V\_HYS}$ , the device enters standby mode, where all internal reference and regulators (LDO3P3 and LDO5) are running, and I<sup>2</sup>C interface and PMICEN pin are ready to respond. All default registers defined in [セクション 7.6, Register Maps](#), have now been loaded from one-time programmable (OTP) memory. Quiescent current consumption in standby mode is specified in [セクション 6.5, Electrical Characteristics: Total Current Consumption](#).

### 7.4.3 Active Mode

The device proceeds to active mode when any output rail is enabled either through an input pin as discussed in [セクション 7.3.5, Power Sequencing and VR Control](#), or by writing to the EN bits through I<sup>2</sup>C. Output regulation voltage can also be changed by writing to the VID bits defined in [セクション 7.6, Register Maps](#).

## 7.5 Programming

### 7.5.1 I<sup>2</sup>C Interface

The I<sup>2</sup>C interface is a 2-wire serial interface developed by NXP™ (formerly Philips Semiconductor) (see the I<sup>2</sup>C-Bus Specification and user manual, Rev 4, 13 February 2012). The bus consists of a data line (SDA) and a clock line (SCL) with pullup structures. When the bus is idle, both SDA and SCL lines are pulled high. All the I<sup>2</sup>C compatible devices connect to the I<sup>2</sup>C bus through open-drain I/O pins, DATA and CLK. A master device, usually a microcontroller or a digital signal processor, controls the bus. The master is responsible for generating the SCL signal and device addresses. The master also generates specific conditions that indicate the start and stop of data transfer. A slave device receives and/or transmits data on the bus under control of the master device.

The TPS65094x device works as a slave and supports the following data transfer modes, as defined in the I<sup>2</sup>C-Bus Specification: standard mode (100 kbps), fast mode (400 kbps), and high-speed mode (1 Mbps). The interface adds flexibility to the power supply solution, enabling programming of most functions to new values depending on the instantaneous application requirements. Register contents are loaded when V<sub>SYS</sub> higher than V<sub>SYS\_UVLO\_5V</sub> is applied to the TPS65094x device. The I<sup>2</sup>C interface is running from an internal oscillator that is automatically enabled when there is an access to the interface.

The data transfer protocol for standard and fast modes are exactly the same, therefore, they are referred to as F/S-mode in this document. The protocol for high-speed mode is different from F/S-mode, and it is referred to as H/S-mode.

The TPS65094x device supports 7-bit addressing; however, 10-bit addressing and general call address are not supported. The default device address is 0x5E.

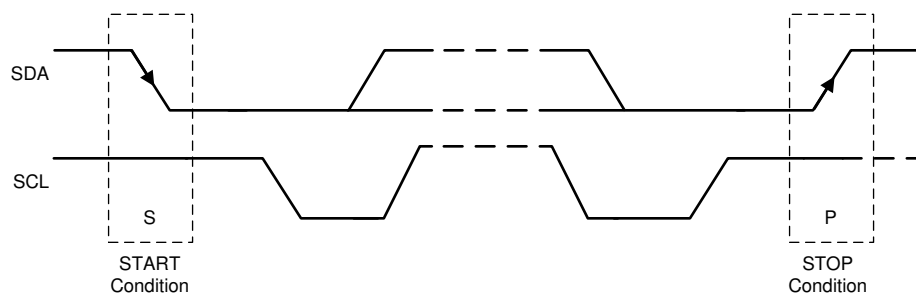
#### 7.5.1.1 F/S-Mode Protocol

The master initiates data transfer by generating a START condition. The START condition exists when a high-to-low transition occurs on the SDA line while SCL is high (see [Figure 7-13](#)). All I<sup>2</sup>C-compatible devices recognize a START condition.

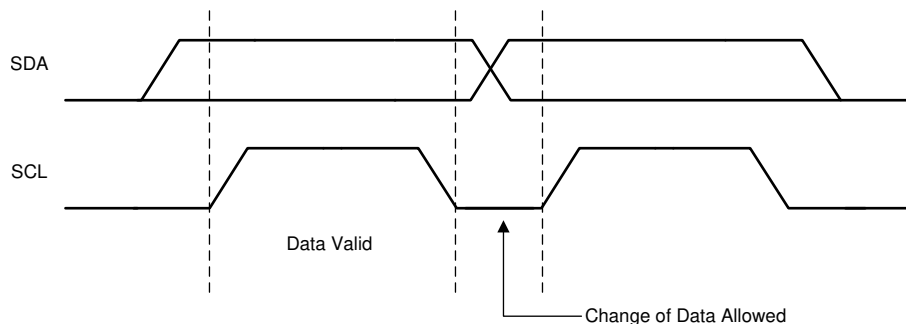
The master then generates the SCL pulses and transmits the 7-bit address and the read/write direction bit R/W on the SDA line. During all transmissions, the master ensures that data is valid. A valid data condition requires the SDA line to be stable during the entire high period of the clock pulse (see [Figure 7-14](#)). All devices recognize the address sent by the master and compare it to their internal fixed addresses. Only the slave device with a matching address generates an acknowledge (see [Figure 7-15](#)), by pulling the SDA line low during the entire high period of the ninth SCL cycle. Upon detecting this acknowledge, the master identifies that the communication link with a slave has been established.

The master generates further SCL cycles to either transmit data to the slave (R/W bit = 0) or receive data from the slave (R/W bit = 1). In either case, the receiver must acknowledge the data sent by the transmitter. An acknowledge signal can either be generated by the master or by the slave, depending on which one is the receiver. Any 9-bit valid data sequences consisting of 8-bit data and 1-bit acknowledge can continue as long as necessary.

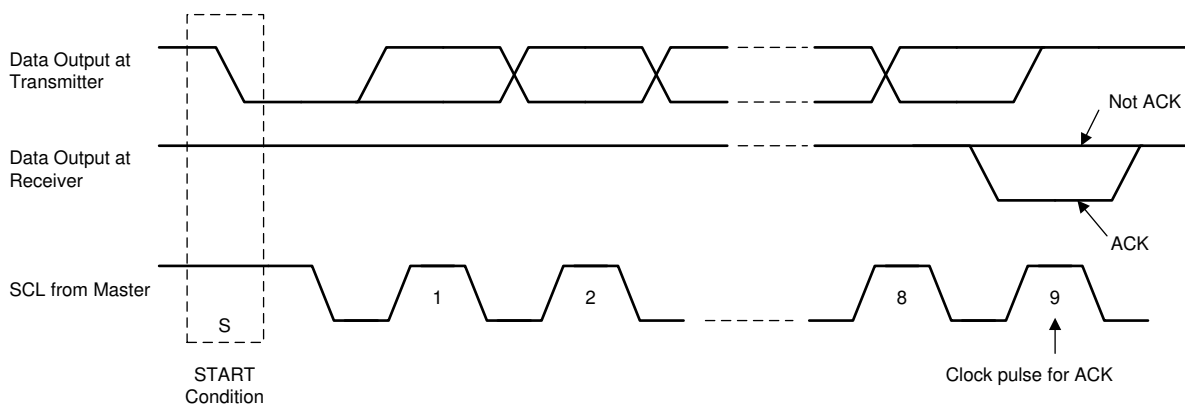
To signal the end of the data transfer, the master generates a STOP condition by pulling the SDA line from low to high while the SCL line is high (see [Figure 7-13](#)). This STOP condition releases the bus and stops the communication link with the addressed slave. All I<sup>2</sup>C-compatible devices must recognize the STOP condition. Upon the receipt of a STOP condition, all devices detect that the bus is released, and they wait for a START condition followed by a matching address.



7-13. START and STOP Conditions



7-14. Bit Transfer on the I<sup>2</sup>C Bus



7-15. Acknowledge on the I<sup>2</sup>C Bus

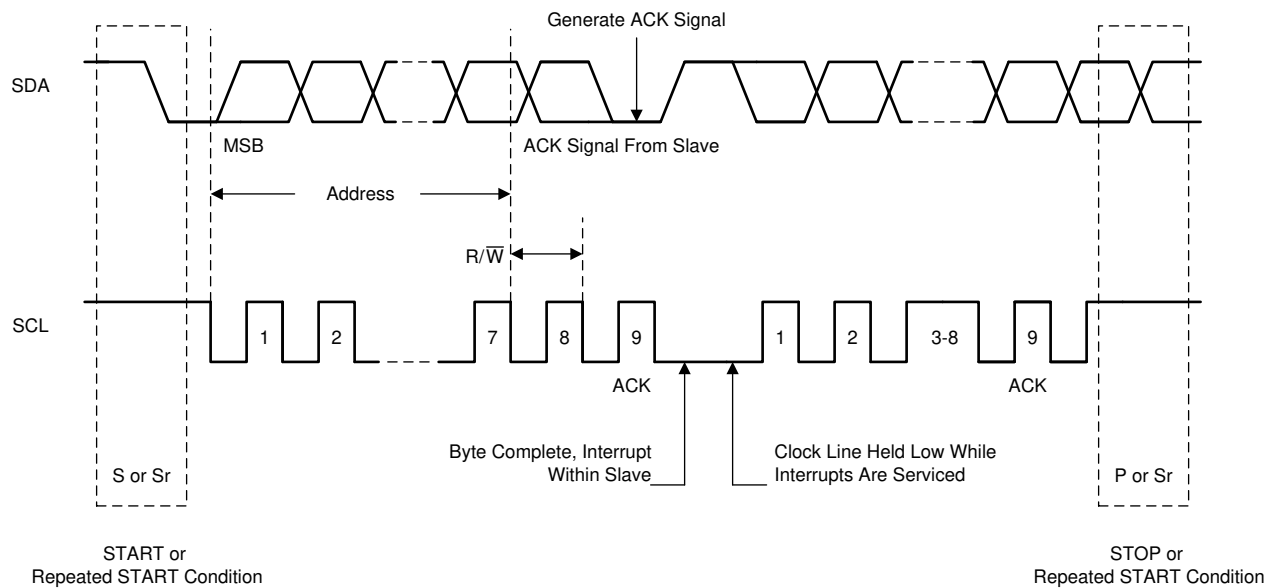
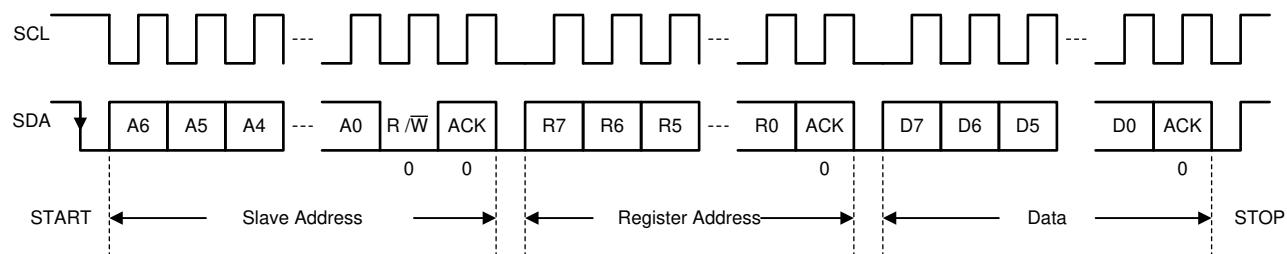
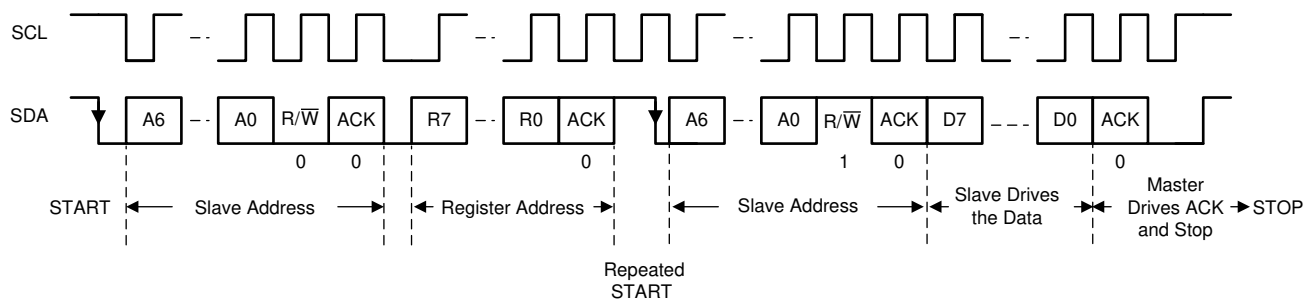


図 7-16. I<sup>2</sup>C Bus Protocol



**図 7-17. I<sup>2</sup>C Interface WRITE to TPS65094x in F/S Mode**



**図 7-18. I<sup>2</sup>C Interface READ from TPS65094x in F/S Mode (Only Repeated START is Supported)**

## 7.6 Register Maps

### 7.6.1

Default value of RESERVED R/W bits must not be written to the opposite value.

### 7.6.2 VENDORID: PMIC Vendor ID Register (offset = 00h) [reset = 0010 0010]

図 7-19. VENDORID Register (offset = 00h) [reset = 0010 0010]

| Bit       | 7           | 6           | 5           | 4           | 3           | 2           | 1           | 0           |
|-----------|-------------|-------------|-------------|-------------|-------------|-------------|-------------|-------------|
| Bit Name  | VENDORID[7] | VENDORID[6] | VENDORID[5] | VENDORID[4] | VENDORID[3] | VENDORID[2] | VENDORID[1] | VENDORID[0] |
| TPS65094x | 0           | 0           | 1           | 0           | 0           | 0           | 1           | 0           |
| Access    | R           | R           | R           | R           | R           | R           | R           | R           |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 7-12. VENDORID Register Field Descriptions

| Bit | Field         | Type | Reset    | Description                    |
|-----|---------------|------|----------|--------------------------------|
| 7–0 | VENDORID[7:0] | R    | 00100010 | Vendor identification register |

### 7.6.3 DEVICEID: PMIC Device and Revision ID Register (offset = 01h) [reset = OTP Dependent]

図 7-20. DEVICEID Register (offset = 01h) [reset = OTP Dependent]

| Bit       | 7        | 6        | 5              | 4              | 3              | 2              | 1              | 0              |
|-----------|----------|----------|----------------|----------------|----------------|----------------|----------------|----------------|
| Bit Name  | REVID[1] | REVID[0] | OTP_VERSION[1] | OTP_VERSION[0] | PART_NUMBER[3] | PART_NUMBER[2] | PART_NUMBER[1] | PART_NUMBER[0] |
| TPS650940 | 0        | 0        | 0              | 0              | 1              | 0              | 0              | 0              |
| TPS650941 | 0        | 0        | 1              | 0              | 1              | 0              | 0              | 1              |
| TPS650942 | 0        | 0        | 0              | 1              | 1              | 0              | 1              | 0              |
| TPS650944 | 0        | 0        | 0              | 0              | 1              | 1              | 0              | 0              |
| TPS650945 | 0        | 0        | 0              | 0              | 1              | 1              | 0              | 1              |
| TPS650947 | 0        | 0        | 0              | 0              | 1              | 1              | 1              | 1              |
| Access    | R        | R        | R              | R              | R              | R              | R              | R              |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 7-13. DEVICEID Register Field Descriptions

| Bit | Field            | Type | Reset | Description  |
|-----|------------------|------|-------|--|
| 7–6 | REVID[1:0]       | R    | OTP   | Silicon revision ID  |
| 5–4 | OTP_VERSION[1:0] | R    | OTP   | OTP variation ID<br>00: A<br>01: B<br>10: C<br>11: D   |
| 3–0 | PART_NUMBER[3:0] | R    | OTP   | Device part number ID<br>1000: TPS650940<br>1001: TPS650941<br>1010: TPS650942<br>1011: TPS650943<br>1100: TPS650944<br>1101: TPS650945<br>1110: TPS650946<br>1111: TPS650947<br>0000: TPS650948 |



#### 7.6.4 IRQ: PMIC Interrupt Register (offset = 02h) [reset = 0000 0000]

図 7-21. IRQ Register (offset = 02h) [reset = 0000 0000]

| Bit       | 7          | 6        | 5        | 4        | 3        | 2        | 1        | 0       |
|-----------|------------|----------|----------|----------|----------|----------|----------|---------|
| Bit Name  | VENDOR_IRQ | RESERVED | RESERVED | RESERVED | ONOFFSRC | RESERVED | RESERVED | DIETEMP |
| TPS65094x | 0          | 0        | 0        | 0        | 0        | 0        | 0        | 0       |
| Access    | R/W        | R        | R        | R        | R/W      | R        | R        | R/W     |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 7-14. IRQ Register Field Descriptions

| Bit | Field      | Type | Reset | Description  |
|-----|------------|------|-------|--|
| 7   | VENDOR_IRQ | R/W  | 0     | Vendor-specific interrupt, indicating fault event occurrence. Asserted when either one of following conditions occurs:<br>A. Deassertion of Power Good of any VR<br>B. Overcurrent detection from BUCK1, BUCK2, BUCK6, or VTT LDO<br>C. Die temperature crosses over the hot temperature threshold ( $T_{HOT}$ )<br>D. Die temperature crosses over the critical temperature threshold ( $T_{CRIT}$ )<br><b>0:</b> Not asserted<br><b>1:</b> Asserted. Host to write 1 to clear. |
| 3   | ONOFFSRC   | R/W  | 0     | Asserted when PMIC shuts down.<br><b>0:</b> Not asserted.<br><b>1:</b> Asserted. Host to write 1 to clear.   |
| 0   | DIETEMP    | R/W  | 0     | Die Temp interrupt. Asserted when PMIC die temperature crosses above the hot temperature threshold ( $T_{HOT}$ ).<br><b>0:</b> Not asserted.<br><b>1:</b> Asserted. Host to write 1 to clear.  |

#### 7.6.5 IRQ\_MASK: PMIC Interrupt Mask Register (offset = 03h) [reset = 1111 1111]

図 7-22. IRQ\_MASK Register (offset = 03h) [reset = 1111 1111]

| Bit       | 7           | 6        | 5        | 4        | 3         | 2        | 1        | 0        |
|-----------|-------------|----------|----------|----------|-----------|----------|----------|----------|
| Bit Name  | MVENDOR_IRQ | RESERVED | RESERVED | RESERVED | MONOFFSRC | RESERVED | RESERVED | MDIETEMP |
| TPS65094x | 1           | 1        | 1        | 1        | 1         | 1        | 1        | 1        |
| Access    | R/W         | R        | R        | R        | R/W       | R        | R        | R/W      |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 7-15. IRQ\_MASK Register Field Descriptions

| Bit | Field       | Type | Reset | Description   |
|-----|-------------|------|-------|---|
| 7   | MVENDOR_IRQ | R/W  | 1     | Vendor-specific fault interrupt mask.<br><b>0:</b> Not masked<br><b>1:</b> Masked |
| 3   | MONOFFSRC   | R/W  | 1     | PMIC shutdown event interrupt mask<br><b>0:</b> Not masked<br><b>1:</b> Masked    |
| 0   | MDIETEMP    | R/W  | 1     | Die temp interrupt mask.<br><b>0:</b> Not masked<br><b>1:</b> Masked              |

### 7.6.6 PMICSTAT: PMIC Status Register (offset = 04h) [reset = 0000 0000]

図 7-23. PMICSTAT Register (offset = 04h) [reset = 0000 0000]

| Bit       | 7        | 6        | 5        | 4        | 3        | 2        | 1        | 0        |
|-----------|----------|----------|----------|----------|----------|----------|----------|----------|
| Bit Name  | RESERVED | RESERVED | RESERVED | RESERVED | RESERVED | RESERVED | RESERVED | SDIETEMP |
| TPS65094x | 0        | 0        | 0        | 0        | 0        | 0        | 0        | 0        |
| Access    | R        | R        | R        | R        | R        | R        | R        | R        |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 7-16. PMICSTAT Register Field Descriptions

| Bit | Field    | Type | Reset | Description  |
|-----|----------|------|-------|--|
| 0   | SDIETEMP | R    | 0     | PMIC die temperature status.<br>0: PMIC die temperature is below $T_{HOT}$ .<br>1: PMIC die temperature is above $T_{HOT}$ . |

### 7.6.7 OFFONSRC: PMIC Power Transition Event Register (offset = 05h) [reset = 0000 0000]

図 7-24. OFFONSRC Register (offset = 05h) [reset = 0000 0000]


| Bit       | 7        | 6        | 5        | 4        | 3       | 2    | 1   | 0        |
|-----------|----------|----------|----------|----------|---------|------|-----|----------|
| Bit Name  | RESERVED | RESERVED | RESERVED | RESERVED | COLDOFF | UVLO | OCP | CRITTEMP |
| TPS65094x | 0        | 0        | 0        | 0        | 0       | 0    | 0   | 0        |
| Access    | R        | R        | R        | R        | R/W     | R/W  | R/W | R/W      |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 7-17. OFFONSRC Register Field Descriptions

| Bit | Field    | Type | Reset | Description   |
|-----|----------|------|-------|---|
| 3   | COLDOFF  | R/W  | 0     | Set by PMIC cleared by host. Host writes 1 to this bit to clear it.<br>0 = Cleared<br>1 = PMIC was shut down by host through PMIC_EN pin.   |
| 2   | UVLO     | R/W  | 0     | Set by PMIC cleared by host. Host writes 1 to this bit to clear it.<br>0 = Cleared<br>1 = PMIC was shut down due to a UVLO event (VSYS less 5.4 V). The setting of this bit sets the ONOFFSRC bit in the PMIC_IRQ register.   |
| 1   | OCP      | R/W  | 0     | Set by PMIC cleared by host. Host writes 1 to this bit to clear it.<br>0 = Cleared<br>1 = PMIC shut down due to a power fault event. The setting of this bit sets the ONOFFSRC bit in the PMIC_IRQ register.  |
| 0   | CRITTEMP | R/W  | 0     | Set by PMIC cleared by host. Host writes 1 to this bit to clear it.<br>0 = Cleared<br>1 = PMIC shut down due to the rise of PMIC die temperature above critical temperature threshold ( $T_{CRIT}$ ). The setting of this bit sets the ONOFFSRC bit in the PMIC_IRQ register. |

### 7.6.8 BUCK1CTRL: BUCK1 Control Register (offset = 20h) [reset = 0011 1000]

 7-25. BUCK1CTRL Register (offset = 20h) [reset = 0011 1000]


| Bit       | 7        | 6            | 5            | 4            | 3            | 2            | 1            | 0            |
|-----------|----------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|
| Bit Name  | RESERVED | BUCK1_VID[6] | BUCK1_VID[5] | BUCK1_VID[4] | BUCK1_VID[3] | BUCK1_VID[2] | BUCK1_VID[1] | BUCK1_VID[0] |
| TPS65094x | 0        | 0            | 1            | 1            | 1            | 0            | 0            | 0            |
| Access    | R/W      | R/W          | R/W          | R/W          | R/W          | R/W          | R/W          | R/W          |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 7-18. BUCK1CTRL Register Field Descriptions

| Bit | Field          | Type | Reset            | Description   |
|-----|----------------|------|------------------|---|
| 6–0 | BUCK1_VID[6:0] | R/W  | 0111000 (1.05 V) | This field sets the BUCK1 regulator output regulation voltage in normal mode. Default = 1.05 V. Note that 0 V is a valid setting and all Power Goods stay high when VID is set to 0x00 and (or) SLP_S0B goes low. See 表 7-3 for full details. |

### 7.6.9 BUCK2CTRL: BUCK2 Control Register (offset = 21h) [reset = 0000 0000]

 7-26. BUCK2CTRL Register (offset = 21h) [reset = 0000 0000]


| Bit       | 7        | 6            | 5            | 4            | 3            | 2            | 1            | 0            |
|-----------|----------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|
| Bit Name  | RESERVED | BUCK2_VID[6] | BUCK2_VID[5] | BUCK2_VID[4] | BUCK2_VID[3] | BUCK2_VID[2] | BUCK2_VID[1] | BUCK2_VID[0] |
| TPS65094x | 0        | 0            | 0            | 0            | 0            | 0            | 0            | 0            |
| Access    | R/W      | R/W          | R/W          | R/W          | R/W          | R/W          | R/W          | R/W          |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 7-19. BUCK2CTRL Register Field Descriptions

| Bit | Field          | Type | Reset         | Description   |
|-----|----------------|------|---------------|---|
| 6–0 | BUCK2_VID[6:0] | R/W  | 0000000 (0 V) | This field sets the BUCK2 regulator output regulation voltage in normal mode. Default = 0 V. Note that 0 V is a valid setting and all Power Goods must stay high when VID is set to 0x00 and (or) SLP_S0B goes low. See 表 7-3 for full details. |

### 7.6.10 BUCK3CTRL: BUCK3 Control Register (offset = 23h) [reset = 0001 0001]

 7-27. BUCK3CTRL Register (offset = 23h) [reset = 0001 0001]

| Bit       | 7        | 6            | 5            | 4            | 3            | 2            | 1            | 0            |
|-----------|----------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|
| Bit Name  | RESERVED | BUCK3_VID[6] | BUCK3_VID[5] | BUCK3_VID[4] | BUCK3_VID[3] | BUCK3_VID[2] | BUCK3_VID[1] | BUCK3_VID[0] |
| TPS65094x | 0        | 0            | 0            | 1            | 0            | 0            | 0            | 1            |
| Access    | R/W      | R/W          | R/W          | R/W          | R/W          | R/W          | R/W          | R/W          |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 7-20. BUCK3CTRL Register Field Descriptions

| Bit | Field          | Type | Reset            | Description  |
|-----|----------------|------|------------------|--|
| 6–0 | BUCK3_VID[6:0] | R/W  | 0010001 (1.05 V) | This field sets the BUCK3 regulator output regulation voltage in normal mode. Default = 1.05 V. Note that 0 V is a valid setting and all Power Goods must stay high when VID is set to 0x00 and (or) SLP_S0B goes low. See 表 7-4 for full details. |

### 7.6.11 BUCK4CTRL: BUCK4 Control Register (offset = 25h) [reset = OTP Dependent]

図 7-28. BUCK4CTRL Register (offset = 25h) [reset = OTP Dependent]

| Bit   | 7        | 6        | 5        | 4        | 3        | 2        | 1          | 0        |
|---|----------|----------|----------|----------|----------|----------|------------|----------|
| Bit Name                                      | RESERVED | RESERVED | RESERVED | RESERVED | RESERVED | RESERVED | BUCK4_MODE | RESERVED |
| TPS650940, TPS650941, TPS65942, and TPS650944 | 0        | 0        | 1        | 1        | 1        | 1        | 0          | 1        |
| TPS650945, and TPS650947                      | 0        | 0        | 1        | 1        | 1        | 1        | 1          | 1        |
| Access  | R        | R        | R/W      | R/W      | R/W      | R/W      | R/W        | R/W      |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 7-21. BUCK4CTRL Register Field Descriptions

| Bit | Field      | Type | Reset  | Description  |
|-----|------------|------|--|--|
| 1   | BUCK4_MODE | R/W  | TPS650940<br>,<br>TPS650941<br>,<br>TPS65942,<br>and<br>TPS650944<br>: 0<br>TPS650945<br>, and<br>TPS650947<br>: 1 | This field sets the BUCK4 regulator operating mode.<br><b>0</b> = Automatic mode<br><b>1</b> = Forced PWM mode |

### 7.6.12 BUCK5CTRL: BUCK5 Control Register (offset = 26h) [reset = OTP Dependent]

図 7-29. BUCK5CTRL Register (offset = 26h) [reset = OTP Dependent]

| Bit   | 7        | 6        | 5        | 4        | 3        | 2        | 1          | 0        |
|---|----------|----------|----------|----------|----------|----------|------------|----------|
| Bit Name                                      | RESERVED | RESERVED | RESERVED | RESERVED | RESERVED | RESERVED | BUCK5_MODE | RESERVED |
| TPS650940, TPS650941, TPS65942, and TPS650944 | 0        | 0        | 1        | 1        | 1        | 1        | 0          | 1        |
| TPS650945, and TPS650947                      | 0        | 0        | 1        | 1        | 1        | 1        | 1          | 1        |
| Access  | R        | R        | R/W      | R/W      | R/W      | R/W      | R/W        | R/W      |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 7-22. BUCK5CTRL Register Field Descriptions

| Bit | Field      | Type | Reset  | Description  |
|-----|------------|------|--|--|
| 1   | BUCK5_MODE | R/W  | TPS650940<br>,<br>TPS650941<br>,<br>TPS65942,<br>and<br>TPS650944<br>: 0<br>TPS650945<br>, and<br>TPS650947<br>: 1 | This field sets the BUCK5 regulator operating mode.<br><b>0</b> = Automatic mode<br><b>1</b> = Forced PWM mode |

### 7.6.13 BUCK6CTRL: BUCK6 Control Register (offset = 27h) [reset = 0011 1101]

**図 7-30. BUCK6CTRL Register (offset = 27h) [reset = 0011 1101]**

| Bit       | 7        | 6        | 5        | 4        | 3        | 2        | 1          | 0        |
|-----------|----------|----------|----------|----------|----------|----------|------------|----------|
| Bit Name  | RESERVED | RESERVED | RESERVED | RESERVED | RESERVED | RESERVED | BUCK6_MODE | RESERVED |
| TPS65094x | 0        | 0        | 1        | 1        | 1        | 1        | 0          | 1        |
| Access    | R        | R        | R/W      | R/W      | R/W      | R/W      | R/W        | R/W      |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**表 7-23. BUCK6CTRL Register Field Descriptions**

| Bit | Field      | Type | Reset | Description  |
|-----|------------|------|-------|--|
| 1   | BUCK6_MODE | R/W  | 0     | This field sets the BUCK6 regulator operating mode.<br><b>0</b> = Automatic mode<br><b>1</b> = Forced PWM mode |

### 7.6.14 DISCHCNT1: Discharge Control1 Register (offset = 40h) [reset = 0101 0101]

All xx\_DIS[1:0] bits automatically set to 00 when the corresponding VR is enabled. Discharge resistance values listed here are approximate.

**図 7-31. DISCHCNT1 Register (offset = 40h) [reset = 0101 0101]**

| Bit       | 7            | 6            | 5            | 4            | 3            | 2            | 1            | 0            |
|-----------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|
| Bit Name  | BUCK4_DIS[1] | BUCK4_DIS[0] | BUCK3_DIS[1] | BUCK3_DIS[0] | BUCK2_DIS[1] | BUCK2_DIS[0] | BUCK1_DIS[1] | BUCK1_DIS[0] |
| TPS65094x | 0            | 1            | 0            | 1            | 0            | 1            | 0            | 1            |
| Access    | R/W          | R/W          | R/W          | R/W          | R/W          | R/W          | R/W          | R/W          |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**表 7-24. DISCHCNT1 Register Field Descriptions**

| Bit | Field          | Type | Reset | Description  |
|-----|----------------|------|-------|--|
| 7–6 | BUCK4_DIS[1:0] | R/W  | 01    | BUCK4 discharge resistance<br><b>00:</b> No discharge<br><b>01:</b> 100 $\Omega$<br><b>10:</b> 200 $\Omega$<br><b>11:</b> 500 $\Omega$ |
| 5–4 | BUCK3_DIS[1:0] | R/W  | 01    | BUCK3 discharge resistance<br><b>00:</b> No discharge<br><b>01:</b> 100 $\Omega$<br><b>10:</b> 200 $\Omega$<br><b>11:</b> 500 $\Omega$ |
| 3–2 | BUCK2_DIS[1:0] | R/W  | 01    | BUCK2 discharge resistance<br><b>00:</b> No discharge<br><b>01:</b> 100 $\Omega$<br><b>10:</b> 200 $\Omega$<br><b>11:</b> 500 $\Omega$ |
| 1–0 | BUCK1_DIS[1:0] | R/W  | 01    | BUCK1 discharge resistance<br><b>00:</b> No discharge<br><b>01:</b> 100 $\Omega$<br><b>10:</b> 200 $\Omega$<br><b>11:</b> 500 $\Omega$ |

### 7.6.15 DISCHCNT2: Discharge Control2 Register (offset = 41h) [reset = 0101 0101]

All xx\_DIS[1:0] bits automatically set to 00 when the corresponding VR is enabled. Discharge resistance values listed here are approximate.

**図 7-32. DISCHCNT2 Register (offset = 41h) [reset = 0101 0101]**

| Bit       | 7            | 6            | 5           | 4           | 3            | 2            | 1            | 0            |
|-----------|--------------|--------------|-------------|-------------|--------------|--------------|--------------|--------------|
| Bit Name  | LDOA2_DIS[1] | LDOA2_DIS[0] | SWA1_DIS[1] | SWA1_DIS[0] | BUCK6_DIS[1] | BUCK6_DIS[0] | BUCK5_DIS[1] | BUCK5_DIS[0] |
| TPS65094x | 0            | 1            | 0           | 1           | 0            | 1            | 0            | 1            |
| Access    | R/W          | R/W          | R/W         | R/W         | R/W          | R/W          | R/W          | R/W          |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**表 7-25. DISCHCNT2 Register Field Descriptions**

| Bit | Field          | Type | Reset | Description   |
|-----|----------------|------|-------|---|
| 7–6 | LDOA2_DIS[1:0] | R/W  | 01    | LDOA2 discharge resistance<br>00: No discharge<br>01: 100 Ω<br>10: 200 Ω<br>11: 500 Ω |
| 5–4 | SWA1_DIS[1:0]  | R/W  | 01    | SWA1 discharge resistance<br>00: No discharge<br>01: 100 Ω<br>10: 200 Ω<br>11: 500 Ω  |
| 3–2 | BUCK6_DIS[1:0] | R/W  | 01    | BUCK6 discharge resistance<br>00: No discharge<br>01: 100 Ω<br>10: 200 Ω<br>11: 500 Ω |
| 1–0 | BUCK5_DIS[1:0] | R/W  | 01    | BUCK5 discharge resistance<br>00: No discharge<br>01: 100 Ω<br>10: 200 Ω<br>11: 500 Ω |

### 7.6.16 DISCHCNT3: Discharge Control3 Register (offset = 42h) [reset = 0000 0101]

All xx\_DIS[1:0] bits automatically set to 00 when the corresponding VR is enabled. Discharge resistance values listed here are approximate.

**図 7-33. DISCHCNT3 Register (offset = 42h) [reset = 0000 0101]**

| Bit       | 7        | 6        | 5        | 4        | 3           | 2           | 1            | 0            |
|-----------|----------|----------|----------|----------|-------------|-------------|--------------|--------------|
| Bit Name  | RESERVED | RESERVED | RESERVED | RESERVED | SWB1_DIS[1] | SWB1_DIS[0] | LDOA3_DIS[1] | LDOA3_DIS[0] |
| TPS65094x | 0        | 0        | 0        | 0        | 0           | 1           | 0            | 1            |
| Access    | R        | R        | R/W      | R/W      | R/W         | R/W         | R/W          | R/W          |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**表 7-26. DISCHCNT3 Register Field Descriptions**

| Bit | Field         | Type | Reset | Description  |
|-----|---------------|------|-------|--|
| 3–2 | SWB1_DIS[1:0] | R/W  | 01    | SWB1 discharge resistance<br>00: No discharge<br>01: 100 Ω<br>10: 200 Ω<br>11: 500 Ω |

表 7-26. DISCHCNT3 Register Field Descriptions (続き)

| Bit | Field          | Type | Reset | Description   |
|-----|----------------|------|-------|---|
| 1–0 | LDOA3_DIS[1:0] | R/W  | 01    | LDOA3 discharge resistance<br><b>00</b> : No discharge<br><b>01</b> : 100 Ω<br><b>10</b> : 200 Ω<br><b>11</b> : 500 Ω |

**7.6.17 POK\_DELAY: PCH\_PWROK Delay Register (offset = 43h) [reset = 0000 0111]**

Programmable Power Good delay for PCH\_PWROK pin, measured from the moment when all VRs reach the regulation range to Power Good assertion.

図 7-34. POK\_DELAY Register (Offset = 43h) [reset = 0000 0111]

| Bit       | 7        | 6        | 5        | 4        | 3        | 2              | 1              | 0              |
|-----------|----------|----------|----------|----------|----------|----------------|----------------|----------------|
| Bit Name  | RESERVED | RESERVED | RESERVED | RESERVED | RESERVED | PWROKDELAY [2] | PWROKDELAY [1] | PWROKDELAY [0] |
| TPS65094x | 0        | 0        | 0        | 0        | 0        | 1              | 1              | 1              |
| Access    | R        | R        | R        | R        | R        | R/W            | R/W            | R/W            |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 7-27. POK\_DELAY Register Field Descriptions

| Bit | Field           | Type | Reset | Description   |
|-----|-----------------|------|-------|---|
| 2–0 | PWROKDELAY[2:0] | R/W  | 111   | Programmable delay measured from the moment all rails have reached regulation voltage to assertion of PCH_PWROK. All values have ±10% variation.<br><b>000</b> = 2.5 ms<br><b>001</b> = 5.0 ms<br><b>010</b> = 10 ms<br><b>011</b> = 15 ms<br><b>100</b> = 20 ms<br><b>101</b> = 50 ms<br><b>110</b> = 75 ms<br><b>111</b> = 100 ms (default) |

**7.6.18 FORCESHUTDN: Force Emergency Shutdown Control Register (offset = 91h) [reset = 0000 0000]**

図 7-35. FORCESHUTDN Register (offset = 91h) [reset = 0000 0000]

| Bit       | 7        | 6        | 5        | 4        | 3        | 2        | 1        | 0    |
|-----------|----------|----------|----------|----------|----------|----------|----------|------|
| Bit Name  | RESERVED | RESERVED | RESERVED | RESERVED | RESERVED | RESERVED | RESERVED | SDWN |
| TPS65094x | 0        | 0        | 0        | 0        | 0        | 0        | 0        | 0    |
| Access    | R        | R        | R        | R        | R        | R        | R        | R/W  |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 7-28. FORCESHUTDN Register Field Descriptions

| Bit | Field | Type | Reset | Description  |
|-----|-------|------|-------|--|
| 0   | SDWN  | R/W  | 0     | Forces reset of the PMIC. The bit is self-clearing.<br><b>0</b> = No action<br><b>1</b> = PMIC is forced to shut down. |

**7.6.19 BUCK4VID: BUCK4 VID Register (offset = 94h) [reset = 0010 1111]**

図 7-36. BUCK4VID Register (offset = 94h) [reset = 0010 1111]

| Bit       | 7        | 6            | 5            | 4            | 3            | 2            | 1            | 0            |
|-----------|----------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|
| Bit Name  | RESERVED | BUCK4_VID[6] | BUCK4_VID[5] | BUCK4_VID[4] | BUCK4_VID[3] | BUCK4_VID[2] | BUCK4_VID[1] | BUCK4_VID[0] |
| TPS65094x | 0        | 0            | 1            | 0            | 1            | 1            | 1            | 1            |



図 7-36. BUCK4VID Register (offset = 94h) [reset = 0010 1111] (続き)

|        |     |     |     |     |     |     |     |     |
|--------|-----|-----|-----|-----|-----|-----|-----|-----|
| Access | R/W | R/W | R/W | R/W | R/W | R/W | R/W | R/W |
|--------|-----|-----|-----|-----|-----|-----|-----|-----|

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 7-29. BUCK4VID Register Field Descriptions

| Bit | Field          | Type | Reset               | Description  |
|-----|----------------|------|---------------------|--|
| 6–0 | BUCK4_VID[6:0] | R/W  | 0101111<br>(1.80 V) | This field sets the BUCK4 regulator output regulation voltage in normal mode. Default = 1.80 V. Note that 0 V is a valid setting and all Power Goods must stay high when VID is set to 0x00. See 表 7-4 for full details. |

#### 7.6.20 BUCK5VID: BUCK5 VID Register (offset = 96h) [reset = 0100 1011]

図 7-37. BUCK5VID Register (Offset = 96h) [reset = 0100 1011]

| Bit       | 7        | 6            | 5            | 4            | 3            | 2            | 1            | 0            |
|-----------|----------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|
| Bit Name  | RESERVED | BUCK5_VID[6] | BUCK5_VID[5] | BUCK5_VID[4] | BUCK5_VID[3] | BUCK5_VID[2] | BUCK5_VID[1] | BUCK5_VID[0] |
| TPS65094x | 0        | 1            | 0            | 0            | 1            | 0            | 1            | 1            |
| Access    | R/W      | R/W          | R/W          | R/W          | R/W          | R/W          | R/W          | R/W          |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 7-30. BUCK5VID Register Field Descriptions

| Bit | Field          | Type | Reset               | Description   |
|-----|----------------|------|---------------------|---|
| 6–0 | BUCK5_VID[6:0] | R/W  | 1001011<br>(1.24 V) | This field sets the BUCK5 regulator output regulation voltage in normal mode. Default = 1.24 V. Note that 0 V is a valid setting and all Power Goods stay high when VID is set to 0x00. See 表 7-3 for full details. |

#### 7.6.21 BUCK6VID: BUCK6 VID Register (offset = 98h) [reset = OTP Dependent]

図 7-38. BUCK6VID Register (Offset = 98h) [reset = OTP Dependent]

| Bit                                      | 7        | 6            | 5            | 4            | 3            | 2            | 1            | 0            |
|--|----------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|
| Bit Name                                 | RESERVED | BUCK6_VID[6] | BUCK6_VID[5] | BUCK6_VID[4] | BUCK6_VID[3] | BUCK6_VID[2] | BUCK6_VID[1] | BUCK6_VID[0] |
| TPS650940,<br>TPS650944 and<br>TPS650945 | 0        | 0            | 1            | 1            | 1            | 1            | 0            | 1            |
| TPS650941                                | 0        | 1            | 0            | 0            | 0            | 1            | 1            | 1            |
| TPS650942 and<br>TPS650947               | 0        | 1            | 0            | 1            | 0            | 1            | 1            | 0            |
| Access                                   | R/W      | R/W          | R/W          | R/W          | R/W          | R/W          | R/W          | R/W          |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 7-31. BUCK6VID Register Field Descriptions

| Bit | Field          | Type | Reset  | Description  |
|-----|----------------|------|--|--|
| 6–0 | BUCK6_VID[6:0] | R/W  | TPS650940, TPS650944,<br>and TPS650945: 0111101<br>(1.1 V)<br>TPS650941: 1000111<br>(1.20 V)<br>TPS650942, and<br>TPS650947: 1010110<br>(1.35 V) | This field sets the BUCK6 regulator output regulation voltage in normal mode. Default = OTP Dependent. Note that 0 V is a valid setting and all Power Goods stay high when VID is set to 0x00. See 表 7-3 for full details. |

### 7.6.22 LDOA2VID: LDOA2 VID Register (offset = 9Ah) [reset = OTP Dependent]

LDOA2\_SLPVID is used when SLP\_S0B is low. Keep LDOA2\_SLPVID equal to LDOA2\_VID if sleep functionality is not desired.

**図 7-39. LDOA2VID Register (offset = 9Ah) [reset = OTP Dependent]**

| Bit   | 7               | 6               | 5               | 4               | 3            | 2            | 1            | 0            |
|---|-----------------|-----------------|-----------------|-----------------|--------------|--------------|--------------|--------------|
| Bit Name  | LDOA2_SLPVID[1] | LDOA2_SLPVID[2] | LDOA2_SLPVID[1] | LDOA2_SLPVID[0] | LDOA2_VID[3] | LDOA2_VID[2] | LDOA2_VID[1] | LDOA2_VID[0] |
| TPS650940, TPS650941, TPS650942, TPS650945, and TPS650947 | 1               | 0               | 1               | 0               | 1            | 0            | 1            | 0            |
| TPS650944   | 0               | 0               | 0               | 0               | 0            | 0            | 0            | 0            |
| Access  | R/W             | R/W             | R/W             | R/W             | R/W          | R/W          | R/W          | R/W          |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**表 7-32. LDOA2VID Register Field Descriptions**

| Bit | Field             | Type | Reset  | Description  |
|-----|-------------------|------|--|--|
| 7–4 | LDOA2_SLPVID[3:0] | R/W  | TPS650940, TPS650941, TPS650942, TPS650945, and TPS650947: 1010 (1.2 V)<br>TPS650944: 0000 (0.7 V) | This field sets the LDOA2 regulator output regulation voltage in sleep mode. Default = OTP Dependent. See 表 7-6 for full details.  |
| 3–0 | LDOA2_VID[3:0]    | R/W  | TPS650940, TPS650941, TPS650942, TPS650945, and TPS650947: 1010 (1.2 V)<br>TPS650944: 0000 (0.7 V) | This field sets the LDOA2 regulator output regulation voltage in normal mode. Default = OTP Dependent. See 表 7-6 for full details. |

### 7.6.23 LDOA3VID: LDOA3 VID Register (offset = 9Bh) [reset = OTP Dependent]

LDOA3\_SLPVID is used when SLP\_S0B is low. Keep LDOA3\_SLPVID equal to LDOA3\_VID if sleep functionality is not desired.

**図 7-40. LDOA3VID Register (offset = 9Bh) [reset = OTP Dependent]**

| Bit   | 7               | 6               | 5               | 4               | 3            | 2            | 1            | 0            |
|---|-----------------|-----------------|-----------------|-----------------|--------------|--------------|--------------|--------------|
| Bit Name  | LDOA3_SLPVID[3] | LDOA3_SLPVID[2] | LDOA3_SLPVID[1] | LDOA3_SLPVID[0] | LDOA3_VID[3] | LDOA3_VID[2] | LDOA3_VID[1] | LDOA3_VID[0] |
| TPS650940, TPS650941, TPS650942, TPS650945, and TPS650947 | 1               | 0               | 1               | 1               | 1            | 0            | 1            | 1            |
| TPS650944   | 0               | 0               | 0               | 0               | 0            | 0            | 0            | 0            |
| Access  | R/W             | R/W             | R/W             | R/W             | R/W          | R/W          | R/W          | R/W          |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**表 7-33. LDOA3VID Register Field Descriptions**

| Bit | Field             | Type | Reset   | Description  |
|-----|-------------------|------|---|--|
| 7–4 | LDOA3_SLPVID[3:0] | R/W  | TPS650940, TPS650941, TPS650942, TPS650945, and TPS650947: 1011 (1.25 V)<br>TPS650944: 0000 (0.7 V) | This field sets the LDOA3 regulator output regulation voltage in sleep mode. Default = OTP Dependent. See 表 7-6 for full details.  |
| 3–0 | LDOA3_VID[3:0]    | R/W  | TPS650940, TPS650941, TPS650942, TPS650945, and TPS650947: 1011 (1.25 V)<br>TPS650944: 0000 (0.7 V) | This field sets the LDOA3 regulator output regulation voltage in normal mode. Default = OTP Dependent. See 表 7-6 for full details. |

#### 7.6.24 VR\_CTRL1: BUCK1-3 Control Register (offset = 9Ch) [reset = OTP Dependent]

 **7-41. VR\_CTRL1 Register (offset = 9Ch) [reset = OTP Dependent]**

| Bit  | 7        | 6        | 5          | 4          | 3          | 2              | 1              | 0              |
|--|----------|----------|------------|------------|------------|----------------|----------------|----------------|
| Bit Name                                       | RESERVED | RESERVED | BUCK3_MODE | BUCK2_MODE | BUCK1_MODE | BUCK3_DISABLEB | BUCK2_DISABLEB | BUCK1_DISABLEB |
| TPS650940, TPS650941, TPS650942, and TPS650944 | 0        | 0        | 0          | 0          | 0          | 1              | 1              | 1              |
| TPS650945, and TPS650947                       | 0        | 0        | 1          | 0          | 0          | 1              | 1              | 1              |
| Access   | R        | R        | R/W        | R/W        | R/W        | R/W            | R/W            | R/W            |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**表 7-34. VR\_CTRL1 Register Field Descriptions**

| Bit | Field          | Type | Reset  | Description  |
|-----|----------------|------|--|--|
| 5   | BUCK3_MODE     | R/W  | TPS650940, TPS650941, TPS650942, and TPS650944: 0<br>TPS650945, and TPS650947: 1 | This field sets the BUCK3 regulator operating mode.<br><b>0</b> = Automatic mode<br><b>1</b> = Forced PWM mode   |
| 4   | BUCK2_MODE     | R/W  | 0  | This field sets the BUCK2 regulator operating mode.<br><b>0</b> = Automatic mode<br><b>1</b> = Forced PWM mode   |
| 3   | BUCK1_MODE     | R/W  | 0  | This field sets the BUCK1 regulator operating mode.<br><b>0</b> = Automatic mode<br><b>1</b> = Forced PWM mode   |
| 2   | BUCK3_DISABLEB | R/W  | 1  | BUCK3 Active Low Disable bit. Writing 0 to this bit forces BUCK3 to turn off regardless of status of enable pins (PMICEN, SLP_Sx). Has priority over BUCK3_EN.<br><b>0</b> : Disabled<br><b>1</b> : BUCK3 operates normally. |
| 1   | BUCK2_DISABLEB | R/W  | 1  | BUCK2 Active Low Disable bit. Writing 0 to this bit forces BUCK2 to turn off regardless of status of enable pins (PMICEN, SLP_Sx). Has priority over BUCK2_EN.<br><b>0</b> : Disabled<br><b>1</b> : BUCK2 operates normally. |

表 7-34. VR\_CTRL1 Register Field Descriptions (続き)

| Bit | Field          | Type | Reset | Description  |
|-----|----------------|------|-------|--|
| 0   | BUCK1_DISABLEB | R/W  | 1     | BUCK1 Active Low DISABLE bit. Writing 0 to this bit forces BUCK1 to turn off regardless of status of enable pins (PMICEN, SLP_Sx). Has priority over BUCK1_EN.<br>0: Disabled<br>1: BUCK1 operates normally. |

## 7.6.25 VR\_CTRL2: VR Enable Register (offset = 9Eh) [reset = 0000 0000]

図 7-42. VR\_CTRL2 Register (offset = 9Eh) [reset = 0000 0000]

| Bit       | 7        | 6       | 5        | 4        | 3        | 2        | 1        | 0        |
|-----------|----------|---------|----------|----------|----------|----------|----------|----------|
| Bit Name  | LDOA2_EN | SWA1_EN | BUCK6_EN | BUCK5_EN | BUCK4_EN | BUCK3_EN | BUCK2_EN | BUCK1_EN |
| TPS65094x | 0        | 0       | 0        | 0        | 0        | 0        | 0        | 0        |
| Access    | R/W      | R/W     | R/W      | R/W      | R/W      | R/W      | R/W      | R/W      |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 7-35. VR\_CTRL2 Register Field Descriptions

| Bit | Field    | Type | Reset | Description   |
|-----|----------|------|-------|---|
| 7   | LDOA2_EN | R/W  | 0     | LDOA2 Enable bit.<br>0: Enabled if LDOLS_EN = 1<br>1: Enabled regardless of LDOLS_EN state  |
| 6   | SWA1_EN  | R/W  | 0     | SWA1 Enable bit.<br>0: Enabled if LDOLS_EN pin or SWA1_EN pin = 1<br>1: Enabled regardless of LDOLS_EN or SWA1_EN state   |
| 5   | BUCK6_EN | R/W  | 0     | BUCK6 Enable bit.<br>0: BUCK6 operates normally.<br>1: Enabled regardless of power sequencing   |
| 4   | BUCK5_EN | R/W  | 0     | BUCK5 Enable bit.<br>0: BUCK5 operates normally.<br>1: Enabled regardless of power sequencing   |
| 3   | BUCK4_EN | R/W  | 0     | BUCK4 Enable bit.<br>0: BUCK4 operates normally.<br>1: Enabled regardless of power sequencing   |
| 2   | BUCK3_EN | R/W  | 0     | BUCK3 Enable bit. BUCK3_DISABLEB has priority over BUCK3_EN.<br>0: BUCK3 operates normally.<br>1: Enabled regardless of power sequencing, unless BUCK3_DISABLEB = 0 |
| 1   | BUCK2_EN | R/W  | 0     | BUCK2 Enable bit. BUCK2_DISABLEB has priority over BUCK2_EN.<br>0: BUCK2 operates normally.<br>1: Enabled regardless of power sequencing, unless BUCK2_DISABLEB = 0 |
| 0   | BUCK1_EN | R/W  | 0     | BUCK1 Enable bit. BUCK1_DISABLEB has priority over BUCK1_EN.<br>0: BUCK1 operates normally.<br>1: Enabled regardless of power sequencing, unless BUCK1_DISABLEB = 0 |

## 7.6.26 VR\_CTRL3: VR Enable/Disable Register (offset = 9Fh) [reset = OTP Dependent]

図 7-43. VR\_CTRL3 Register (Offset = 9Fh) [reset = OTP Dependent]

| Bit                                 | 7        | 6               | 5             | 4            | 3      | 2        | 1         | 0        |
|-------------------------------------|----------|-----------------|---------------|--------------|--------|----------|-----------|----------|
| Bit Name                            | RESERVED | SWB1_2_DISABLEB | SWA1_DISABLEB | VTT_DISABLEB | VTT_EN | RESERVED | SWB1_2_EN | LDOA3_EN |
| TPS650940, TPS650944, and TPS650945 | 0        | 1               | 1             | 0            | 1      | 0        | 0         | 0        |
| TPS650941, TPS650942 and TPS650947  | 0        | 1               | 1             | 1            | 0      | 0        | 0         | 0        |
| Access                              | R/W      | R/W             | R/W           | R/W          | R/W    | R/W      | R/W       | R/W      |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**表 7-36. VR\_CTRL3 Register Field Descriptions**

| Bit | Field           | Type | Reset   | Description  |
|-----|-----------------|------|---|--|
| 6   | SWB1_2_DISABLEB | R/W  | 1   | SWB1_2 Active Low Disable Bit. Writing 0 to this bit forces SWB1_2 to turn off regardless of status of enable pins (PMICEN, SLP_Sx). Has priority over SWB1_2_EN.<br>0: Disabled<br>1: SWB1_2 operates normally. |
| 5   | SWA1_DISABLEB   | R/W  | 1   | SWA1 Active Low Disable Bit. Writing 0 to this bit forces SWA1 to turn off regardless of status of enable pins (PMICEN, SLP_Sx). Has priority over SWA1_EN.<br>0: Disabled<br>1: SWA1 operates normally.         |
| 4   | VTT_DISABLEB    | R/W  | TPS650940, TPS650944, and TPS650945: 0<br>TPS650941, TPS650942 and TPS650947: 1 | VTT_LDO Active Low Disable Bit. Writing 0 to this bit forces VTT_LDO to turn off regardless of status of enable pins (PMICEN, SLP_Sx). Has priority over VTT_EN.<br>0: Disabled<br>1: VTT_LDO operates normally. |
| 3   | VTT_EN          | R/W  | TPS650940, TPS650944 and TPS650945: 1<br>TPS650941, TPS650942 and TPS650947: 0  | VTT_LDO Enable bit. VTT_DISABLEB has priority over VTT_EN.<br>0: VTT_LDO operates normally.<br>1: Enabled regardless of power sequencing, unless VTT_DISABLEB = 0  |
| 1   | SWB1_2_EN       | R/W  | 0   | SWB1_2_Enable bit. SWB1_2_DISABLEB has priority over SWB1_2_EN.<br>0: SWB1_2 operates normally.<br>1: Enabled regardless of power sequencing, unless SWB1_2_DISABLEB = 0   |
| 0   | LDOA3_EN        | R/W  | 0   | LDOA3 Enable bit.<br>0: Enabled if LDOLS_EN = 1<br>1: Enabled regardless of LDOLS_EN state   |

**7.6.27 GPO\_CTRL: GPO Control Register (offset = A1h) [reset = 0010 0000]****図 7-44. GPO\_CTRL Register (offset = A1h) [reset = 0010 0000]**

| Bit       | 7        | 6        | 5       | 4        | 3        | 2        | 1        | 0        |
|-----------|----------|----------|---------|----------|----------|----------|----------|----------|
| Bit Name  | RESERVED | RESERVED | GPO_LVL | RESERVED | RESERVED | RESERVED | RESERVED | RESERVED |
| TPS65094x | 0        | 0        | 1       | 0        | 0        | 0        | 0        | 0        |
| Access    | R/W      | R/W      | R/W     | R/W      | R/W      | R/W      | R/W      | R/W      |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**表 7-37. GPO\_CTRL Register Field Descriptions**

| Bit | Field   | Type | Reset | Description   |
|-----|---------|------|-------|---|
| 5   | GPO_LVL | R/W  | 1     | Open-drain GPO output level bit.<br>0: The pin is driven to logic low.<br>1: The pin is high impedance. |

### 7.6.28 PWR\_FAULT\_MASK1: VR Power Fault Mask1 Register (offset = A2h) [reset = 1100 0000]

**図 7-45. PWR\_FAULT\_MASK1 Register (offset = A2h) [reset = 1100 0000]**

| Bit       | 7            | 6           | 5            | 4            | 3            | 2            | 1            | 0            |
|-----------|--------------|-------------|--------------|--------------|--------------|--------------|--------------|--------------|
| Bit Name  | LDOA2_FLTMSK | SWA1_FLTMSK | BUCK6_FLTMSK | BUCK5_FLTMSK | BUCK4_FLTMSK | BUCK3_FLTMSK | BUCK2_FLTMSK | BUCK1_FLTMSK |
| TPS65094x | 1            | 1           | 0            | 0            | 0            | 0            | 0            | 0            |
| Access    | R/W          | R/W         | R/W          | R/W          | R/W          | R/W          | R/W          | R/W          |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**表 7-38. PWR\_FAULT\_MASK1 Register Field Descriptions**

| Bit | Field        | Type | Reset | Description   |
|-----|--------------|------|-------|---|
| 7   | LDOA2_FLTMSK | R/W  | 1     | LDOA2 Power Fault Mask. When masked, power fault from LDOA2 does not cause PMIC shutdown.<br><b>0:</b> Not masked<br><b>1:</b> Masked |
| 6   | SWA1_FLTMSK  | R/W  | 1     | SWA1 Power Fault Mask. When masked, power fault from SWA1 does not cause PMIC shutdown.<br><b>0:</b> Not masked<br><b>1:</b> Masked   |
| 5   | BUCK6_FLTMSK | R/W  | 0     | BUCK6 Power Fault Mask. When masked, power fault from BUCK6 does not cause PMIC shutdown.<br><b>0:</b> Not masked<br><b>1:</b> Masked |
| 4   | BUCK5_FLTMSK | R/W  | 0     | BUCK5 Power Fault Mask. When masked, power fault from BUCK5 does not cause PMIC shutdown.<br><b>0:</b> Not masked<br><b>1:</b> Masked |
| 3   | BUCK4_FLTMSK | R/W  | 0     | BUCK4 Power Fault Mask. When masked, power fault from BUCK4 does not cause PMIC shutdown.<br><b>0:</b> Not masked<br><b>1:</b> Masked |
| 2   | BUCK3_FLTMSK | R/W  | 0     | BUCK3 Power Fault Mask. When masked, power fault from BUCK3 does not cause PMIC shutdown.<br><b>0:</b> Not masked<br><b>1:</b> Masked |
| 1   | BUCK2_FLTMSK | R/W  | 0     | BUCK2 Power Fault Mask. When masked, power fault from BUCK2 does not cause PMIC shutdown.<br><b>0:</b> Not masked<br><b>1:</b> Masked |
| 0   | BUCK1_FLTMSK | R/W  | 0     | BUCK1 Power Fault Mask. When masked, power fault from BUCK1 does not cause PMIC shutdown.<br><b>0:</b> Not masked<br><b>1:</b> Masked |

### 7.6.29 PWR\_FAULT\_MASK2: VR Power Fault Mask2 Register (offset = A3h) [reset = 0011 0111]

図 7-46. PWR\_FAULT\_MASK2 Register (offset = A3h) [reset = 0011 0111]

| Bit       | 7        | 6        | 5            | 4            | 3          | 2                | 1                | 0            |
|-----------|----------|----------|--------------|--------------|------------|------------------|------------------|--------------|
| Bit Name  | RESERVED | RESERVED | V5ANA_FLTMSK | LDOA1_FLTMSK | VTT_FLTMSK | SWB1_2_FLTMSK[1] | SWB1_2_FLTMSK[0] | LDOA3_FLTMSK |
| TPS65094x | 0        | 0        | 1            | 1            | 0          | 1                | 1                | 1            |
| Access    | R        | R/W      | R/W          | R/W          | R/W        | R/W              | R/W              | R/W          |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 7-39. PWR\_FAULT\_MASK2 Register Field Descriptions

| Bit | Field         | Type | Reset | Description  |
|-----|---------------|------|-------|--|
| 5   | V5ANA_FLTMSK  | R/W  | 1     | V5ANA Power Fault Mask. When masked, power fault from V5ANA does not cause PMIC shutdown.<br><b>0</b> : Not masked<br><b>1</b> : Masked                                |
| 4   | LDOA1_FLTMSK  | R/W  | 1     | LDOA1 Power Fault Mask. When masked, power fault from LDOA1 does not cause PMIC shutdown.<br><b>0</b> : Not masked<br><b>1</b> : Masked                                |
| 3   | VTT_FLTMSK    | R/W  | 0     | VTT LDO Power Fault Mask. When masked, power fault from VTT LDO does not cause PMIC shutdown.<br><b>0</b> : Not Masked<br><b>1</b> : Masked                            |
| 2–1 | SWB1_2_FLTMSK | R/W  | 11    | SWB1_2 Power Fault Mask. When masked, power fault from SWB1_2 does not cause PMIC shutdown.<br><b>00</b> : Not masked<br><b>11</b> : Masked<br><b>01-10</b> = RESERVED |
| 0   | LDOA3_FLTMSK  | R/W  | 1     | LDOA3 Power Fault Mask. When masked, power fault from LDOA3 does not cause PMIC shutdown.<br><b>0</b> : Not masked<br><b>1</b> : Masked                                |

### 7.6.30 DISCHCNT4: Discharge Control4 Register (offset = ADh) [reset = 0110 0001]

図 7-47. DISCHCNT4 Register (offset = ADh) [reset = 0110 0001]

| Bit       | 7        | 6        | 5        | 4       | 3        | 2        | 1        | 0        |
|-----------|----------|----------|----------|---------|----------|----------|----------|----------|
| Bit Name  | RESERVED | RESERVED | RESERVED | VTT_DIS | RESERVED | RESERVED | RESERVED | RESERVED |
| TPS65094x | 0        | 1        | 1        | 0       | 0        | 0        | 0        | 1        |
| Access    | R/W      | R/W      | R/W      | R/W     | R/W      | R/W      | R/W      | R/W      |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 7-40. DISCHNT4 Register Field Descriptions

| Bit | Field   | Type | Reset | Description   |
|-----|---------|------|-------|---|
| 4   | VTT_DIS | R/W  | 0     | VTT_LDO discharge resistance<br><b>0</b> = No discharge<br><b>1</b> = 100 Ω |



### 7.6.31 LDOA1CTRL: LDOA1 Control Register (offset = AEh) [reset = OTP Dependent]

**図 7-48. LDOA1CTRL Register (offset = AEh) [reset = OTP Dependent]**

| Bit  | 7            | 6            | 5                 | 4            | 3            | 2            | 1            | 0        |
|--|--------------|--------------|-------------------|--------------|--------------|--------------|--------------|----------|
| Bit Name   | LDOA1_DIS[1] | LDOA1_DIS[0] | LDOA1_SDWN_CONFIG | LDOA1_VID[3] | LDOA1_VID[2] | LDOA1_VID[1] | LDOA1_VID[0] | LDOA1_EN |
| TPS650940,<br>TPS650941,<br>TPS650942,<br>TPS650945 and<br>TPS650947 | 0            | 1            | 1                 | 1            | 1            | 1            | 0            | 0        |
| TPS650944  | 0            | 1            | 1                 | 0            | 1            | 0            | 0            | 1        |
| Access   | R/W          | R/W          | R/W               | R/W          | R/W          | R/W          | R/W          | R/W      |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**表 7-41. LDOA1CTRL Register Field Descriptions**

| Bit | Field             | Type | Reset   | Description   |
|-----|-------------------|------|---|---|
| 7–6 | LDOA1_DIS[1:0]    | R/W  | 01  | LDOA1 discharge resistance<br><b>00</b> : No discharge<br><b>01</b> : 100 Ω<br><b>10</b> : 200 Ω<br><b>11</b> : 500 Ω   |
| 5   | LDOA1_SDWN_CONFIG | R/W  | 1   | Control for Disabling LDOA1 during Emergency Shutdown<br><b>0</b> : LDOA1 turns off during Emergency Shutdown.<br><b>1</b> : LDOA1 does not turn off during Emergency Shutdown as long as LDOA1_EN = 1. |
| 4–1 | LDOA1_VID[3:0]    | R/W  | TPS650940,<br>TPS650941,<br>TPS650942,<br>TPS650945<br>and<br>TPS650947: 1110 (3.3 V)<br>TPS650944: 0100 (1.8V) | This field sets the LDOA3 regulator output regulation voltage in normal mode. Default = OTP Dependent. See 表 7-5 for full details.  |
| 0   | LDOA1_EN          | R/W  | TPS650940,<br>TPS650941,<br>TPS650942,<br>TPS650945<br>and<br>TPS650947: 0<br>TPS650944: 1                      | LDOA1 Enable Bit.<br><b>0</b> : Disable<br><b>1</b> : Enable  |

### 7.6.32 PG\_STATUS1: Power Good Status1 Register (offset = B0h) [reset = 0000 0000]

**図 7-49. PG\_STATUS1 Register (offset = B0h) [reset = 0000 0000]**

| Bit       | 7           | 6        | 5           | 4           | 3           | 2           | 1           | 0           |
|-----------|-------------|----------|-------------|-------------|-------------|-------------|-------------|-------------|
| Bit Name  | LDOA2_PGOOD | RESERVED | BUCK6_PGOOD | BUCK5_PGOOD | BUCK4_PGOOD | BUCK3_PGOOD | BUCK2_PGOOD | BUCK1_PGOOD |
| TPS65094x | 0           | 0        | 0           | 0           | 0           | 0           | 0           | 0           |
| Access    | R           | R        | R           | R           | R           | R           | R           | R           |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**表 7-42. PG\_STATUS1 Register Field Descriptions**

| Bit | Field       | Type | Reset | Description  |
|-----|-------------|------|-------|--|
| 7   | LDOA2_PGOOD | R    | 0     | LDOA2 Power Good status.<br><b>0</b> : The output is not in target regulation range.<br><b>1</b> : The output is in target regulation range. |

表 7-42. PG\_STATUS1 Register Field Descriptions (続き)

| Bit | Field       | Type | Reset | Description  |
|-----|-------------|------|-------|--|
| 5   | BUCK6_PGOOD | R    | 0     | BUCK6 Power Good status.<br>0: The output is not in target regulation range.<br>1: The output is in target regulation range. |
| 4   | BUCK5_PGOOD | R    | 0     | BUCK5 Power Good status.<br>0: The output is not in target regulation range.<br>1: The output is in target regulation range. |
| 3   | BUCK4_PGOOD | R    | 0     | BUCK4 Power Good status.<br>0: The output is not in target regulation range.<br>1: The output is in target regulation range. |
| 2   | BUCK3_PGOOD | R    | 0     | BUCK3 Power Good status.<br>0: The output is not in target regulation range.<br>1: The output is in target regulation range. |
| 1   | BUCK2_PGOOD | R    | 0     | BUCK2 Power Good status.<br>0: The output is not in target regulation range.<br>1: The output is in target regulation range. |
| 0   | BUCK1_PGOOD | R    | 0     | BUCK1 Power Good status.<br>0: The output is not in target regulation range.<br>1: The output is in target regulation range. |

## 7.6.33 PG\_STATUS2: Power Good Status2 Register (offset = B1h) [reset = 0000 0000]

図 7-50. PG\_STATUS2 Register (offset = B1h) [reset = 0000 0000]

| Bit       | 7        | 6        | 5          | 4           | 3         | 2        | 1        | 0           |
|-----------|----------|----------|------------|-------------|-----------|----------|----------|-------------|
| Bit Name  | RESERVED | RESERVED | LDO5_PGOOD | LDOA1_PGOOD | VTT_PGOOD | RESERVED | RESERVED | LDOA3_PGOOD |
| TPS65094x | 0        | 0        | 0          | 0           | 0         | 0        | 0        | 0           |
| Access    | R        | R        | R          | R           | R         | R        | R        | R           |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 7-43. PG\_STATUS2 Register Field Descriptions

| Bit | Field       | Type | Reset | Description  |
|-----|-------------|------|-------|--|
| 5   | LDO5_PGOOD  | R    | 0     | LDO5 Power Good status.<br>0: The output is not in target regulation range.<br>1: The output is in target regulation range.    |
| 4   | LDOA1_PGOOD | R    | 0     | LDOA1 Power Good status.<br>0: The output is not in target regulation range.<br>1: The output is in target regulation range.   |
| 3   | VTT_PGOOD   | R    | 0     | VTT LDO Power Good status.<br>0: The output is not in target regulation range.<br>1: The output is in target regulation range. |
| 0   | LDOA3_PGOOD | R    | 0     | LDOA3 Power Good status.<br>0: The output is not in target regulation range.<br>1: The output is in target regulation range.   |

## 7.6.33.1 PWR\_FAULT\_STATUS1: Power Fault Status1 Register (offset = B2h) [reset = 0000 0000]

図 7-51. PWR\_FAULT\_STATUS1 Register (offset = B2h) [reset = 0000 0000]

| Bit       | 7            | 6        | 5            | 4            | 3            | 2            | 1            | 0            |
|-----------|--------------|----------|--------------|--------------|--------------|--------------|--------------|--------------|
| Bit Name  | LDOA2_PWRFLT | RESERVED | BUCK6_PWRFLT | BUCK5_PWRFLT | BUCK4_PWRFLT | BUCK3_PWRFLT | BUCK2_PWRFLT | BUCK1_PWRFLT |
| TPS65094x | 0            | 0        | 0            | 0            | 0            | 0            | 0            | 0            |
| Access    | R/W          | R/W      | R/W          | R/W          | R/W          | R/W          | R/W          | R/W          |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**表 7-44. PWR\_FAULT\_STATUS1 Register Field Descriptions**

| Bit | Field        | Type | Reset | Description   |
|-----|--------------|------|-------|---|
| 7   | LDOA2_PWRFLT | R    | 0     | This fields indicates that LDOA2 has lost regulation.<br><b>0:</b> No Fault.<br><b>1:</b> Power fault has occurred. The host to write 1 to clear. |
| 5   | BUCK6_PWRFLT | R    | 0     | This fields indicates that BUCK6 has lost regulation.<br><b>0:</b> No Fault.<br><b>1:</b> Power fault has occurred. The host to write 1 to clear. |
| 4   | BUCK5_PWRFLT | R    | 0     | This fields indicates that BUCK5 has lost regulation.<br><b>0:</b> No Fault.<br><b>1:</b> Power fault has occurred. The host to write 1 to clear. |
| 3   | BUCK4_PWRFLT | R    | 0     | This fields indicates that BUCK4 has lost regulation.<br><b>0:</b> No Fault.<br><b>1:</b> Power fault has occurred. The host to write 1 to clear. |
| 2   | BUCK3_PWRFLT | R    | 0     | This fields indicates that BUCK3 has lost regulation.<br><b>0:</b> No Fault.<br><b>1:</b> Power fault has occurred. The host to write 1 to clear. |
| 1   | BUCK2_PWRFLT | R    | 0     | This fields indicates that BUCK2 has lost regulation.<br><b>0:</b> No Fault.<br><b>1:</b> Power fault has occurred. The host to write 1 to clear. |
| 0   | BUCK1_PWRFLT | R    | 0     | This fields indicates that BUCK1 has lost regulation.<br><b>0:</b> No Fault.<br><b>1:</b> Power fault has occurred. The host to write 1 to clear. |

#### 7.6.33.2 PWR\_FAULT\_STATUS2: Power Fault Status2 Register (offset = B3h) [reset = 0000 0000]

**図 7-52. PWR\_FAULT\_STATUS2 Register (offset = B3h) [reset = 0000 0000]**

| Bit       | 7        | 6        | 5        | 4            | 3          | 2        | 1        | 0            |
|-----------|----------|----------|----------|--------------|------------|----------|----------|--------------|
| Bit Name  | RESERVED | RESERVED | RESERVED | LDOA1_PWRFLT | VTT_PWRFLT | RESERVED | RESERVED | LDOA3_PWRFLT |
| TPS65094x | 0        | 0        | 0        | 0            | 0          | 0        | 0        | 0            |
| Access    | R        | R        | R/W      | R/W          | R/W        | R/W      | R/W      | R/W          |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**表 7-45. PWR\_FAULT\_STATUS2 Register Field Descriptions**

| Bit | Field        | Type | Reset | Description   |
|-----|--------------|------|-------|---|
| 4   | LDOA1_PWRFLT | R/W  | 0     | This fields indicates that LDOA1 has lost regulation.<br><b>0:</b> No Fault.<br><b>1:</b> Power fault has occurred. The host to write 1 to clear.   |
| 3   | VTT_PWRFLT   | R/W  | 0     | This fields indicates that VTT LDO has lost regulation.<br><b>0:</b> No Fault.<br><b>1:</b> Power fault has occurred. The host to write 1 to clear. |
| 0   | LDOA3_PWRFLT | R/W  | 0     | This fields indicates that LDOA3 has lost regulation.<br><b>0:</b> No Fault.<br><b>1:</b> Power fault has occurred. The host to write 1 to clear.   |

### 7.6.34 TEMPHOT: Temperature Hot Status Register (offset = B5h) [reset = 0000 0000]

Asserted when an internal temperature sensor detects rise of die temperature above the HOT temperature threshold ( $T_{HOT}$ ). There are five temperature sensors across the die.

**図 7-53. TEMPHOT Register (offset = B5h) [reset = 0000 0000]**

| Bit       | 7        | 6        | 5        | 4       | 3       | 2             | 1            | 0                |
|-----------|----------|----------|----------|---------|---------|---------------|--------------|------------------|
| Bit Name  | RESERVED | RESERVED | RESERVED | DIE_HOT | VTT_HOT | TOP-RIGHT_HOT | TOP-LEFT_HOT | BOTTOM-RIGHT_HOT |
| TPS65094x | 0        | 0        | 0        | 0       | 0       | 0             | 0            | 0                |
| Access    | R        | R        | R        | R/W     | R/W     | R/W           | R/W          | R/W              |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**表 7-46. TEMPHOT Register Field Descriptions**

| Bit | Field            | Type | Reset | Description  |
|-----|------------------|------|-------|--|
| 4   | DIE_HOT          | R/W  | 0     | Temperature of rest of die has exceeded $T_{HOT}$ .<br><b>0:</b> Not asserted.<br><b>1:</b> Asserted. The host to write 1 to clear.  |
| 3   | VTT_HOT          | R/W  | 0     | Temperature of VTT LDO has exceeded $T_{HOT}$ .<br><b>0:</b> Not asserted.<br><b>1:</b> Asserted. The host to write 1 to clear.  |
| 2   | TOP-RIGHT_HOT    | R/W  | 0     | Temperature of die top-right has exceeded $T_{HOT}$ . Top-right corner of die from top view given pin 1 is in top-left corner.<br><b>0:</b> Not asserted.<br><b>1:</b> Asserted. The host to write 1 to clear.       |
| 1   | TOP-LEFT_HOT     | R/W  | 0     | Temperature of die top-left has exceeded $T_{HOT}$ . Top-left corner of die from top view given pin 1 is in top-left corner.<br><b>0:</b> Not asserted.<br><b>1:</b> Asserted. The host to write 1 to clear.         |
| 0   | BOTTOM-RIGHT_HOT | R/W  | 0     | Temperature of die bottom-right has exceeded $T_{HOT}$ . Bottom-right corner of die from top view given pin 1 is in top-left corner.<br><b>0:</b> Not asserted.<br><b>1:</b> Asserted. The host to write 1 to clear. |

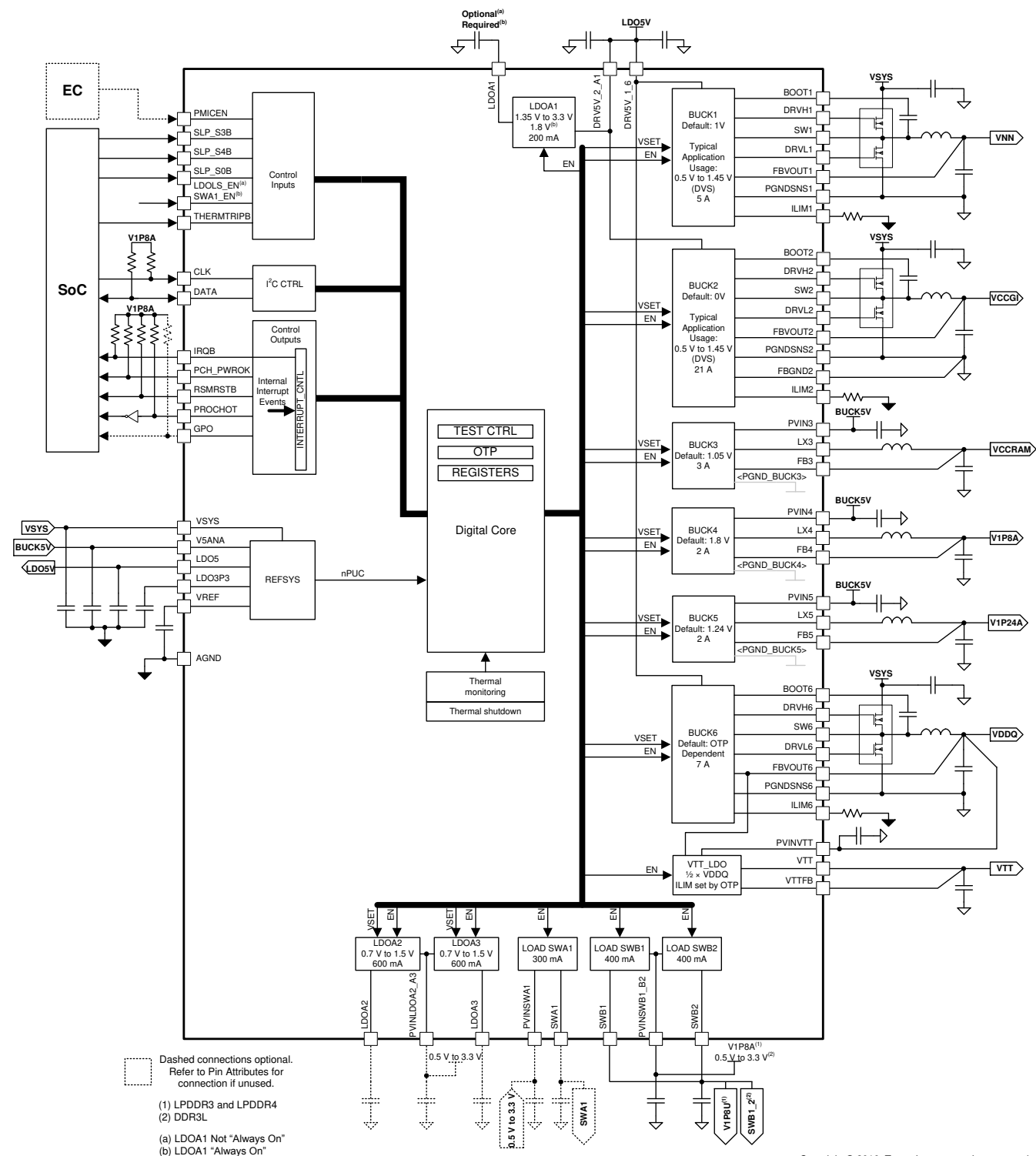
## 8 Application and Implementation

### 注

以下のアプリケーション情報は、TI の製品仕様に含まれるものではなく、TI ではその正確性または完全性を保証いたしません。個々の目的に対する製品の適合性については、お客様の責任で判断していただくことになります。お客様は自身の設計実装を検証しテストすることで、システムの機能を確認する必要があります。

### 8.1 Typical Application

For a detailed description about application usage, refer to the [TPS65094x Design Guide](#) and to the [TPS65094x Schematic Checklist, Layout Checklist, and ILIM Calculator Tool](#) . The TPS65094x can be used in several different applications from computing, industrial interfacing, and much more. This section describes the general application information and provides a more detailed description on the TPS65094x device that powers the Intel Apollo Lake system. The functional block diagram for the device is shown in [図 8-1](#), which outlines the typical external components necessary for proper device functionality.



### 8-1. Functional Block Diagram

### 8.1.1 Design Requirements

The TPS65094x device requires decoupling capacitors on the supply pins. Follow the values for recommended capacitance on these supplies given in the [Specifications](#) section. The controllers, converter, LDOs, and some other features can be adjusted to meet specific application requirements. セクション 8.1.2, *Detailed Design Procedure*, describes how to design and adjust the external components to achieve desired performance.

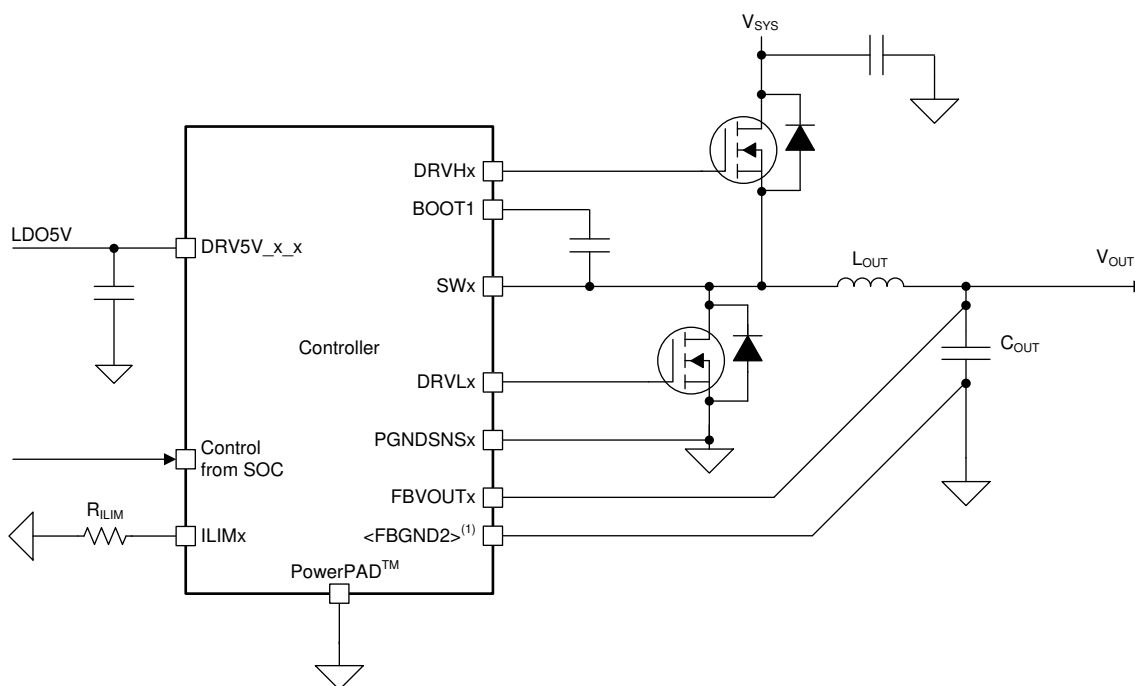
### 8.1.2 Detailed Design Procedure

#### 8.1.2.1 Controller Design Procedure

Designing the controller can be divided into the following steps:

1. Design the output filter.
2. Select the FETs.
3. Select the bootstrap capacitor.
4. Select the input capacitors.
5. Set the current limits.

図 8-2 shows a diagram of the controller. Controllers BUCK1, BUCK2, and BUCK6 require a 5-V supply and capacitors at their corresponding DRV5V\_x\_x pins. For most applications, the DRV5V\_x\_x input must come from the LDO5P0 pin to ensure uninterrupted supply voltage; a 2.2- $\mu$ F, X5R, 20%, 10-V, or similar capacitor must be used for decoupling.



Copyright © 2017, Texas Instruments Incorporated

図 8-2. Controller Diagram

### 8.1.2.1.1 Selecting the Output Capacitors

TI recommends using ceramic capacitors with low ESR values to provide the lowest output voltage ripple. The output capacitor requires either an X7R or an X5R dielectric. Capacitors with Y5V or Z5U dielectrics display a wide variation in capacitance over temperature and become resistive at high frequencies.

At light load currents, the controller operates in PFM mode, and the output voltage ripple is dependent on the output-capacitor value and the PFM peak inductor current. Higher output-capacitor values minimize the voltage ripple in PFM mode. To achieve specified regulation performance and low output voltage ripple, the DC-bias characteristic of ceramic capacitors must be considered. The effective capacitance of ceramic capacitors drops with increasing DC bias voltage.

For the output capacitors of the BUCK controllers, TI recommends placing small ceramic capacitors between the inductor and load with many vias to the PGND plane. This solution typically provides the smallest and lowest cost solution available for DCAP2 controllers.

To meet the transient specifications, the output capacitance must equal or exceed the minimum capacitance listed in the electrical characteristics table for BUCK1, BUCK2, and BUCK6 (assuming quality layout techniques are followed). See [セクション 6.7, Electrical Characteristics: Buck Controllers](#).

### 8.1.2.1.2 Selecting the Inductor

An inductor must be placed between the external FETs and the output capacitors. Together, the inductor and output capacitors make the double-pole that contributes to stability. In addition, the inductor is responsible for the output ripple, efficiency, and transient performance. When the inductance increases, the ripple current decreases, which typically results in an increased efficiency. However, with an increase in inductance, the transient performance decreases. Finally, the inductor selected must be rated for appropriate saturation current, core losses, and DC resistance (DCR).

式 3 shows the calculation for the recommended inductance for the controller.

$$L = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{V_{IN} \times f_{sw} \times I_{OUT(MAX)} \times K_{IND}} \quad (3)$$

where

- $V_{OUT}$  is the typical output voltage.
- $V_{IN}$  is the typical input voltage.
- $f_{sw}$  is the typical switching frequency.
- $I_{OUT(MAX)}$  is the maximum load current.
- $K_{IND}$  is the ratio of  $I_{L(ripple)}$  to the  $I_{OUT(MAX)}$ . For this application, TI recommends that  $K_{IND}$  is set to a value from 0.2 to 0.4.

With the chosen inductance value and the peak current for the inductor in steady state operation,  $I_{L(max)}$  can be calculated using 式 4. The rated saturation current of the inductor must be higher than the  $I_{L(MAX)}$  current.

$$I_{L(MAX)} = I_{OUT(MAX)} + \frac{(V_{IN} - V_{OUT}) \times V_{OUT}}{2 \times V_{IN} \times f_{sw} \times L} \quad (4)$$

Following the previous equations, 表 8-1 lists the preferred inductor selected for the controllers..

**表 8-1. Recommended Inductors**

| MANUFACTURER | PART NUMBER | VALUE        | SIZE                   | HEIGHT |
|--------------|-------------|--------------|------------------------|--------|
| Cyntec       | PIMB061H    | 0.47 $\mu$ H | 6.8 mm $\times$ 7.3 mm | 1.8 mm |
| Cyntec       | PIMB062D    | 0.22 $\mu$ H | 6.8 mm $\times$ 7.3 mm | 2.4 mm |



#### 8.1.2.1.3 Selecting the FETs

This controller is designed to drive two NMOS FETs. Typically, lower  $R_{DS(on)}$  values are better for improving the overall efficiency of the controller. However, higher gate-charge thresholds result in lower efficiency, so the two must be balanced for optimal performance. As the  $R_{DS(on)}$  for the low-side FET decreases, the minimum current limit increases; therefore, ensure selection of the appropriate values for the FETs, inductor, output capacitors, and current-limit resistor. TI's CSD87331Q3D, CSD87381P, and CSD87588N devices are recommended for the controllers, depending on the required maximum current.

#### 8.1.2.1.4 Bootstrap Capacitor

To ensure the internal high-side gate drivers are supplied with a stable low-noise supply voltage, a capacitor must be connected between the SWx pins and the respective BOOTx pins. TI recommends placing ceramic capacitors with the value of 0.1  $\mu$ F for the controllers. During testing, a 0.1- $\mu$ F, size 0402, 10-V capacitor is used for the controllers.

TI recommends reserving a small resistor in series with the bootstrap capacitor in case the turnon and turnoff of the FETs must be slowed to reduce voltage ringing on the switch node, which is a common practice for controller design.

#### 8.1.2.1.5 Selecting the Input Capacitors

Due to the nature of the switching controller with a pulsating input current, a low-ESR input capacitor is required for best input-voltage filtering and also for minimizing the interference with other circuits caused by high input-voltage spikes. For the controller, a typical 2.2- $\mu$ F capacitor can be used for the DRV5V\_x\_x pin to handle the transients on the driver. For the FET input, 10  $\mu$ F of input capacitance (after derating) is recommended for most applications. To achieve the low-ESR requirement, a ceramic capacitor is recommended. However, the voltage rating and DC-bias characteristic of ceramic capacitors must be considered. For better input-voltage filtering, the input capacitor can be increased without any limit.

##### 8.1.2.1.5.1 Setting the Current Limit

The current-limiting resistor value must be chosen based on 式 1.

---

#### 注

Use the correct value for the ceramic capacitor capacitance after derating to achieve the recommended input capacitance.

---

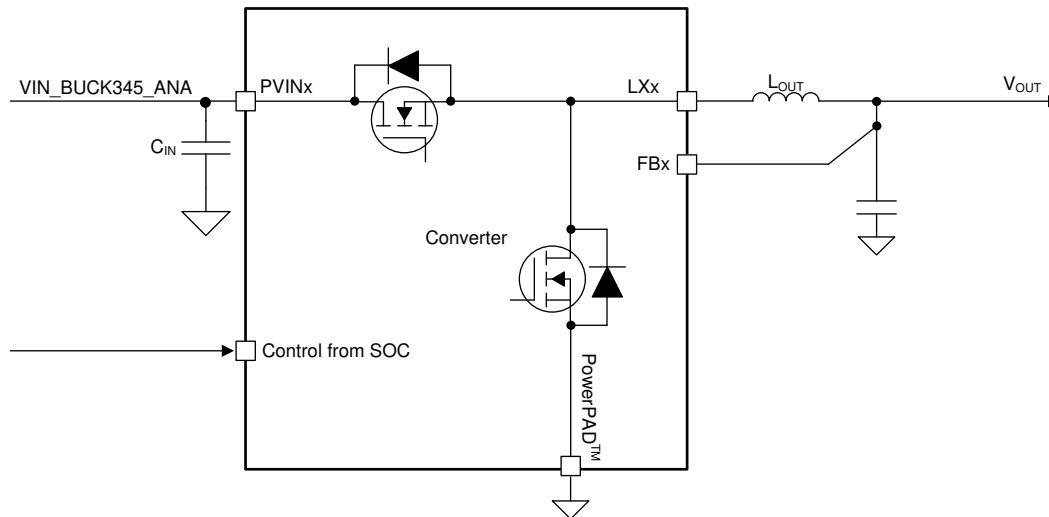
TI recommends placing a ceramic capacitor as close as possible to the FET across the respective V<sub>SY</sub>S and PGND pins of the FETs. The preferred capacitors for the controllers are two Murata GRM21BR61E226ME44: 22  $\mu$ F, 0805, 25 V,  $\pm$ 20%, or similar capacitors.

### 8.1.2.2 Converter Design Procedure

Designing the converter has only the following two steps:

1. Design the output filter.
2. Select the input capacitors.

The converter must be supplied by a 5-V source. [Figure 8-3](#) shows a diagram of the converter.



Copyright © 2017, Texas Instruments Incorporated

**Figure 8-3. Converter Diagram**

#### 8.1.2.2.1 Selecting the Inductor

An inductor must be placed between the external FETs and the output capacitors. Together, the inductor and output capacitors form a double-pole in the control loop that contributes to stability. In addition, the inductor is responsible for the output ripple, efficiency, and transient performance. When the inductance increases, the ripple current decreases, which typically results in an increase in efficiency. However, with an increase in inductance, the transient performance decreases. Finally, the inductor selected must be rated for appropriate saturation current, core losses, and DCR.

#### 注

Internal parameters for the converters are optimized for a 0.47-μH inductor; however, it is possible to use other inductor values as long as they are chosen carefully and thoroughly tested.

[Equation 5](#) shows the calculation for the recommended inductance for the converter.

$$L = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{V_{IN} \times f_{sw} \times I_{OUT(MAX)} \times K_{IND}} \quad (5)$$

where

- $V_{OUT}$  is the typical output voltage.
- $V_{IN}$  is the typical input voltage.
- $f_{sw}$  is the typical switching frequency.
- $I_{OUT(MAX)}$  is the maximum load current.
- $K_{IND}$  is the ratio of  $I_{Lripple}$  to the  $I_{OUT(MAX)}$ . For this application, TI recommends that  $K_{IND}$  is set to a value from 0.2 to 0.4.

With the chosen inductance value and the peak current for the inductor in steady state operation,  $I_{L(MAX)}$  can be calculated using 式 6. The rated saturation current of the inductor must be higher than the  $I_{L(MAX)}$  current.

$$I_{L(MAX)} = I_{OUT(MAX)} + \frac{(V_{IN} - V_{OUT}) \times V_{OUT}}{2 \times V_{IN} \times f_{sw} \times L} \quad (6)$$

Following these equations, 表 8-2 lists the preferred inductor selected for the converters.

**表 8-2. Recommended Inductors**

| MANUFACTURER | PART NUMBER      | VALUE        | SIZE                   | HEIGHT |
|--------------|------------------|--------------|------------------------|--------|
| Cyntec       | PIFE32251B-R47MS | 0.47 $\mu$ H | 3.2 mm $\times$ 2.5 mm | 1.2 mm |

#### 8.1.2.2.2 Selecting the Output Capacitors

TI recommends using ceramic capacitors with low-ESR values are recommended to provide the lowest output voltage ripple. The output capacitor requires either an X7R or an X5R rating. Y5V and Z5U capacitors, aside from the wide variation in capacitance overtemperature, become resistive at high frequencies.

At light load currents, the converter operates in PFM mode and the output voltage ripple is dependent on the output-capacitor value and the PFM peak inductor current. Higher output-capacitor values minimize the voltage ripple in PFM mode. To achieve specified regulation performance and low output voltage ripple, the DC-bias characteristic of ceramic capacitors must be considered. The effective capacitance of ceramic capacitors drops with increasing DC-bias voltage.

For the output capacitors of the BUCK converters, TI recommends placing small ceramic capacitors between the inductor and load with many vias to the PGND plane. This solution typically provides the smallest and lowest-cost solution available for DCAP2 controllers.

To meet the transient specifications, the output capacitance must equal or exceed the minimum capacitance listed for BUCK3, BUCK4, and BUCK5 (assuming quality layout techniques are followed).

#### 8.1.2.2.3 Selecting the Input Capacitors

Due to the nature of the switching converter with a pulsating input current, a low-ESR input capacitor is required for best input-voltage filtering and for minimizing the interference with other circuits caused by high input-voltage spikes. For the PVINx pin, 2.5  $\mu$ F of input capacitance (after derating) is required for most applications. A ceramic capacitor is recommended to achieve the low-ESR requirement. However, the voltage rating and DC-bias characteristic of ceramic capacitors must be considered. For better input-voltage filtering, the input capacitor can be increased without any limit.

#### 注

Use the correct value for the ceramic capacitor capacitance after derating to achieve the recommended input capacitance.

The preferred capacitor for the converters is one Samsung CL05A106MP5NUNC: 10  $\mu$ F, 0402, 10 V,  $\pm$ 20%, or similar capacitor.

#### 8.1.2.3 LDO Design Procedure

The VTT LDO must handle the fast load transients from the DDR memory for termination. Therefore, TI recommends using ceramic capacitors to maintain a high amount of capacitance with low ESR on the VTT LDO outputs and inputs. The preferred output capacitors for the VTT LDO are the GRM188R60J226MEA0 from Murata (22  $\mu$ F, 0603, 6.3 V,  $\pm$ 20%, or similar capacitors). The preferred input capacitor for the VTT LDO is the CL05A106MP5NUNC from Samsung (10  $\mu$ F, 0402, 10 V,  $\pm$ 20%, or similar capacitor).

The remaining LDOs must have input and output capacitors chosen based on the values in セクション 6.9, *Electrical Characteristics: LDOs*.

### 8.1.3 Application Curves

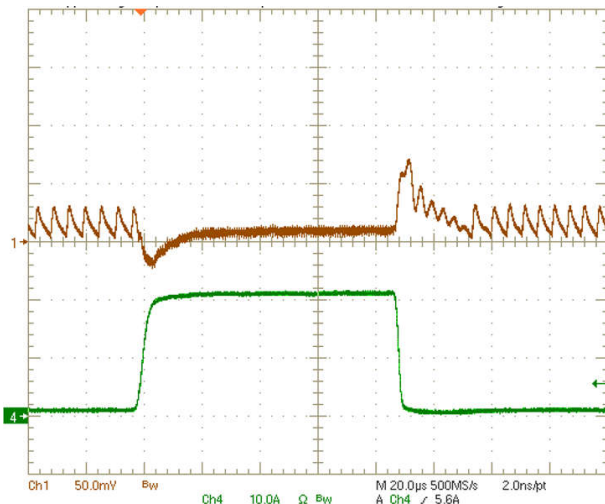


図 8-4. BUCK2 Controller Load Transient

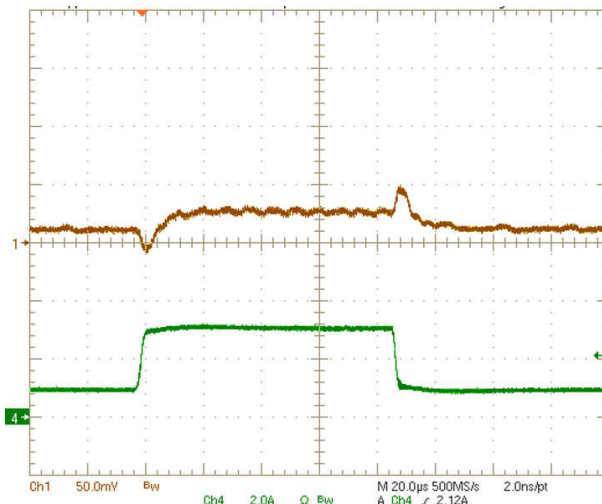


図 8-5. BUCK3 Converter Load Transient

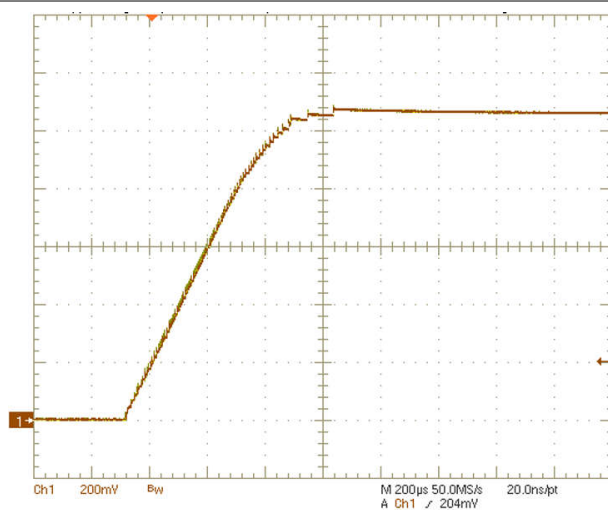


図 8-6. BUCK2 Controller Start-Up

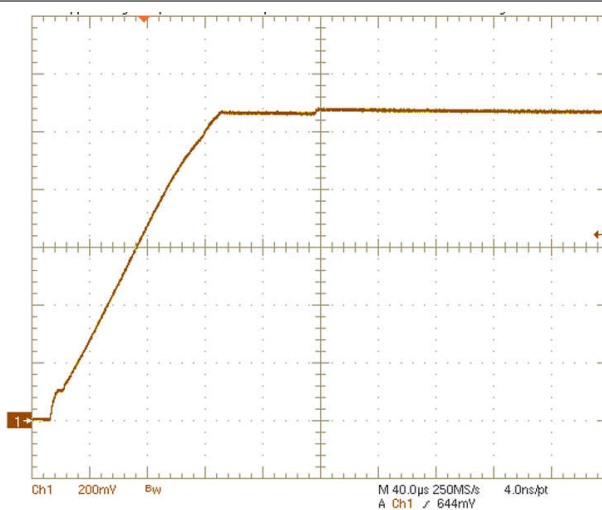
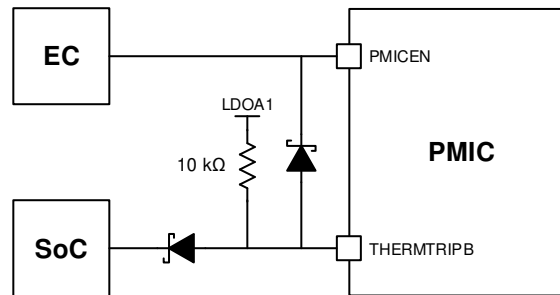


図 8-7. BUCK3 Converter Start-Up

## 8.2 Specific Application for TPS650944

For the TPS650944 device, if register reset is desired when the PMICEN pin is pulled low, an alternate reset condition can be used. There are two simple options. The first option is to write 1 to the SDWN bit in the FORCESHUTDOWN register (see [セクション 7.6.18](#), *FORCESHUTDOWN: Force Emergency Shutdown Control Register*) to force power rails to turn off and reset all registers. The second option is to use the falling edge detection of the THERMTRIPB pin to trigger the device reset. In this case, when the PMICEN pin is pulled low, the THERMTRIPB pin on PMIC must be pulled low simultaneously, which can be done in several ways. One approach is to connect a low-voltage Schottky diode between the PMICEN and THERMTRIPB pins. Because the THERMTRIPB SoC pin is push-pull configured, a second diode is needed to prevent shorting the SoC pin to GND. An example can be seen in [図 8-8](#). Both diodes must have a forward voltage below PMIC  $V_{IL}$  (0.4 V) at the appropriate current. Another approach is to route the THERMTRIPB signal from SoC through the EC and tie PMICEN and THERMTRIPB together at the PMIC.



Not applicable if LDOA1 is not configured to "Always On"

### [図 8-8](#). PMICEN and THERMTRIPB Connection Option for LDOA1 "Always On" Spins

For the TPS650944 device, if both the PVINSWA1 and PVINSWB1\_B2 pins are tied to 2.5 V, LDOA2 and LDOA3 turns on if all VRs and load switches are enabled and have released their Power Good signals. To avoid LDOA2 and LDOA3 turning on unexpectedly, TI recommends using voltages other than 2.5 V on both SWA1 and SWB1\_2.

## 8.3 Dos and Don'ts

- Connect the LDO5V output to the DRV5V\_x\_x inputs for situations where an external 5-V supply is not initially available or is not available the entire time PMIC is on. If the external 5-V supply is always present, then DRV5V\_x\_x can be directly connected to remove the V5ANA-to-LDO5P0 load switch  $R_{DS(on)}$ .
- Ensure that none of the control pins are potentially floating.
- Include 0-Ω resistors on the DRVH and BOOT pins of controllers on prototype boards, which allows for slowing the controllers if the system is unable to handle the noise generated by the large switching or if switching voltage is too large due to layout.
- Do not connect the V5ANA power input to a different source other than PVINx. A mismatch here causes reference circuits to regulate incorrectly.
- Do not supply the V5ANA power input before the VSYS. Reference biasing of the internal FETs may turn on the HS FET and pass the input to the output until VSYS is biased.

## 8.4 Power Supply Recommendations

This device is designed to work with several different input voltages. The minimum voltage on the VSYS pin is 5.6 V for the device to start up; however, this is a low-power rail. The input to the FETs must be from 5.4 V to 21 V as long as the proper BOM choices are made. Input to the converters must be 5 V. For the device to output maximum power, the input power must be sufficient. For the controllers, VIN must be able to supply up to 5 A (typically), though less is acceptable with higher voltages or less usage. For the converters, PVINx must be able to supply 2 A (typically).

A best practice here is to determine power usage by the system and back-calculate the necessary power input based on expected efficiency values.

## 8.5 Layout

### 8.5.1 Layout Guidelines

For a detailed description regarding layout recommendations, refer to the [TPS65094x Design Guide](#) and to the [TPS65094x Schematic Checklist, Layout Checklist, and ILIM Calculator Tool](#). For all switching power supplies, the layout is an important step in the design, especially at high peak currents and high switching frequencies. If the layout is not carefully done, the regulator can have stability problems and EMI issues. Therefore, use wide and short traces for the main current path and for the power ground tracks. The input capacitors, output capacitors, and inductors must be placed as close as possible to the device. Use a common-ground node for power ground and use a different, isolated node for control ground to minimize the effects of ground noise. Connect these ground nodes close to the AGND pin by one or two vias. Use of the design guide is highly encouraged in addition to the following list of other basic requirements:

- Do not allow the AGND, PGND<sub>SNSx</sub>, or FB<sub>GND2</sub> to connect to the thermal pad on the top layer.
- To ensure proper sensing based on FET  $R_{DS(ON)}$ , PGND<sub>SNSx</sub> must not connect to PGND until very close to the PGND pin of the FET.
- All inductors, input/output capacitors, and FETs for the converters and controller must be on the same board layer as the device.
- To achieve the best regulation performance, place feedback connection points near the output capacitors and minimize the control feedback loop as much as possible.
- Bootstrap capacitors must be placed close to the device.
- The input and output capacitors of the internal reference regulators must be placed close to the device pins.
- Route DRVHx and SWx as a differential pair. Ensure that there is a PGND path routed in parallel with DRVLx, which provides optimal driver loops.

### 8.5.2 Layout Example

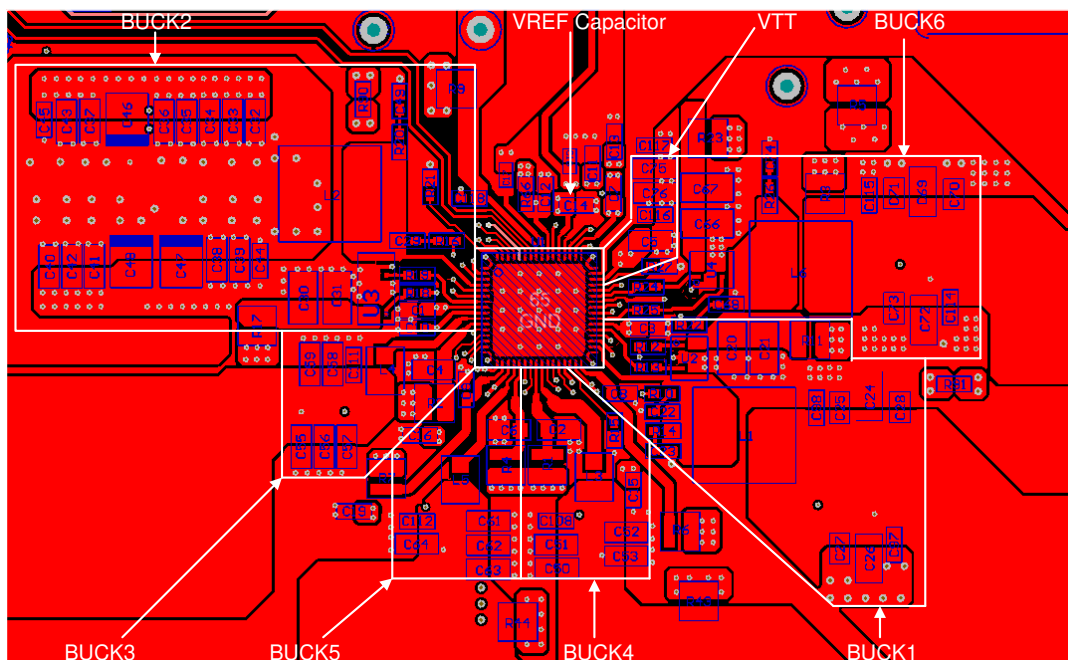


図 8-9. EVM Layout Example With All Components on the Top Layer



## 9 Device and Documentation Support

### 9.1 Device Support

#### 9.1.1 Development Support

See the following for development support:

[TPS65094x Schematic Checklist, Layout Checklist, and ILIM Calculator Tool](#)

### 9.2 Documentation Support

#### 9.2.1 Related Documentation

For related documentation see the following:

- [TPS65094x Design Guide](#)
- [TPS65094x Evaluation Module](#)

### 9.3 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、[www.tij.co.jp](http://www.tij.co.jp) のデバイス製品フォルダを開いてください。[通知] をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取ることができます。変更の詳細については、改訂されたドキュメントに含まれている改訂履歴をご覧ください。

### 9.4 サポート・リソース

[テキサス・インスツルメンツ E2E™ サポート・フォーラム](#)は、エンジニアが検証済みの回答と設計に関するヒントをエキスパートから迅速かつ直接得ることができる場所です。既存の回答を検索したり、独自の質問をしたりすることで、設計に必要な支援を迅速に得ることができます。

リンクされているコンテンツは、各寄稿者により「現状のまま」提供されるものです。これらはテキサス・インスツルメンツの仕様を構成するものではなく、必ずしもテキサス・インスツルメンツの見解を反映したものではありません。テキサス・インスツルメンツの[使用条件](#)を参照してください。

### 9.5 Trademarks

D-CAP2™ and D-CAP™ are trademarks of TI.

ウルトラブック™ and Intel™ are trademarks of Intel Corporation.

NXP™ is a trademark of NXP Semiconductors.

テキサス・インスツルメンツ E2E™ is a trademark of Texas Instruments.

すべての商標は、それぞれの所有者に帰属します。

### 9.6 静電気放電に関する注意事項



この IC は、ESD によって破損する可能性があります。テキサス・インスツルメンツは、IC を取り扱う際には常に適切な注意を払うことを推奨します。正しい取り扱いおよび設置手順に従わない場合、デバイスを破損するおそれがあります。

ESD による破損は、わずかな性能低下からデバイスの完全な故障まで多岐にわたります。精密な IC の場合、パラメータがわずかに変化するだけで公表されている仕様から外れる可能性があるため、破損が発生しやすくなっています。

### 9.7 用語集

[テキサス・インスツルメンツ用語集](#) この用語集には、用語や略語の一覧および定義が記載されています。

## 10 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

### Changes from Revision E (October 2024) to Revision F (January 2025)

**Page**

- Changed minimum storage temperature from –40 °C to –55 °C.....**8**

| Changes from Revision D (May 2019) to Revision E (October 2024)                             | Page |
|---|------|
| ドキュメント全体にわたって表、図、相互参照の採番方法を更新.....  | 1    |
| 実際の過去のリリースを反映するように改訂履歴の日付を更新.....   | 1    |
| 最初のページの内容を、最新の技術およびフォーマット標準に合わせて更新.....   | 1    |
| Added note about Forced PWM Mode to <i>Summary of TPS65094x OTP Differences table</i> ..... | 3    |

| Changes from Revision C (February 2019) to Revision D (May 2019)   | Page |
|--|------|
| Added "TPS650947" column to <i>Summary of TPS65094x OTP Differences table</i> .....  | 3    |
| Changed TPS650945 DEVICEID register to "Dh" and TPS650944 DEVICEID register to "Ch" in <i>Summary of TPS65094x OTP Differences table</i> ..... | 3    |
| Added TPS650947 settings to <a href="#">セクション 7.6</a> .....  | 48   |

| Changes from Revision B (February 2017) to Revision C (February 2019)   | Page |
|---|------|
| Added "BUCK3-5 Mode" row and "TPS650945" column to <i>Summary of TPS65094x OTP Differences table</i> ...  | 3    |
| Changed VSYS to PVIN in the efficiency graphs for BUCK3, BUCK4, and BUCK5 in the <i>Typical Characteristics</i> section.....  | 23   |
| Added to the description of the deassertion condition that causes an emergency shutdown in the <i>Emergency Shutdown</i> section.....   | 43   |
| Added TPS650945 settings to <a href="#">セクション 7.6</a> .....   | 48   |
| Changed OCP event to power fault event in the OCP bit description in the <i>OFFONSRC Register Field Descriptions table</i> .....  | 50   |
| Changed second reference of TPS650940 to TPS650944 for the bit reset values in the <i>LDOA2VID Register Field Descriptions</i> and <i>LDOA3VID Register Field Descriptions tables</i> ..... | 58   |
| Changed the bit values of the LDOA3_SLPVID[0] and LDOA3_VID[0] bits in the <i>LDOA3VID Register figure</i> .....  | 58   |

| Changes from Revision A (June 2016) to Revision B (February 2017)   | Page |
|---|------|
| 記載されている電流がデバイスの制限でないことを示すよう「特長」を変更.....   | 1    |
| Changed the values for LX3, LX4, LX5 from –1 V and 7 V to –2 V and 8 V in the <i>Absolute Maximum Ratings table</i> ..... | 8    |
| Changed the reset value of the LDOA2 VID register (LDOA2VID) to OTP dependent.....  | 58   |

| Changes from Revision * (August 2015) to Revision A (June 2016)  | Page |
|--|------|
| SWCS130B バージョンから SWCS133A バージョンとして完全なデータシートをリリース.....  | 1    |
| デバイスのステータスを「PROD_DATA」に変更.....   | 1    |
| V <sub>IN</sub> の推奨最小値を変更.....   | 1    |
| コンバータの説明を改善するよう「特長」を変更.....  | 1    |
| 「特長」で、負荷スイッチの出力電流を最大 400mA に変更.....  | 1    |
| Changed PROCHOTB to PROCHOT throughout the document.....   | 4    |
| Changed minimum absolute-maximum-rating value for SW1, SW2, and SW6 in <a href="#">セクション 6.1</a> .....                 | 8    |
| Deleted nominal value from PVINVT in <a href="#">セクション 6.3, Recommended Operating Conditions</a> .....                 | 8    |
| Deleted (nu = symbol for efficiency) .....   | 10   |
| Changed BUCK1 DC output voltage step size to show full range and be consistent in <a href="#">セクション 6.7</a> .....      | 10   |
| Changed typo to match correct default of 1 V for ΔV <sub>OUT_TR</sub> in <a href="#">セクション 6.7</a> .....               | 10   |
| Changed BUCK2 DC output voltage to show full range and be consistent in <a href="#">セクション 6.7</a> .....                | 10   |
| Changed set condition for BUCK6 for V <sub>OUT</sub> range in <a href="#">セクション 6.7</a> to match BUCK1 and BUCK2 ..... | 10   |



|   |    |
|---|----|
| • Updated formatting and added new OTP information for BUCK6 in <a href="#">セクション 6.7</a> .....                     | 10 |
| • Updated formatting for BUCK3 DC output voltage in <a href="#">セクション 6.8</a> .....                                 | 14 |
| • Changed DC output voltage formatting for BUCK4 in <a href="#">セクション 6.8</a> .....                                 | 14 |
| • Changed maximum $I_{OUT}$ value for BUCK4 in <a href="#">セクション 6.8</a> to match device capabilities .....         | 14 |
| • Changed $I_{OUT}$ and $\Delta V_{OUT}/\Delta I_{OUT}$ for VTT LDO in <a href="#">セクション 6.9</a> for new OTPs ..... | 17 |
| • Changed test conditions for VTT LDO overcurrent protection in <a href="#">セクション 6.9</a> .....                     | 17 |
| • Changed <a href="#">セクション 6.10</a> to show SWB1_2 $R_{DS(on)}$ is specified per output .....                      | 20 |
| • Changed $f_{SW}$ values in <a href="#">セクション 6.15</a> to provide more values .....                                | 22 |
| • Changed current to 1.9 A to match SoC requirements in <a href="#">表 7-1</a> .....                                 | 25 |
| • Changed BUCK6, LDOA2, LDOA3 typical output voltage range to: OTP Dependent in <a href="#">表 7-1</a> .....         | 25 |
| • Changed table note to include additional DDR types in <a href="#">表 7-1</a> .....                                 | 25 |
| • Changed <i>PMIC Functional Block Diagram</i> to match specifications table .....                                  | 26 |
| • Changed PROCHOTB to PROCHOT in the <i>Apollo Lake Power Map</i> .....   | 26 |
| • Changed current ratings in <i>Apollo Lake Power Map</i> .....   | 26 |
| • Deleted SWBx PG from PG of PCH_PWROK in Power Good Summary.....   | 28 |
| • Deleted SWBx PG from PG of PCH_PWROK in Power Good Summary.....   | 28 |
| • Changed BUCK1–2 to all BUCKs and LDOAs in <a href="#">セクション 7.3.3.3</a> .....                                     | 33 |
| • Added <a href="#">表 7-5</a> and <a href="#">表 7-6</a> to <a href="#">セクション 7.3.4.2</a> .....                      | 34 |
| • Added more DDR values to the table note in <a href="#">表 7-7</a> .....  | 34 |
| • Changed <a href="#">セクション 7.3.5</a> to include LDOA1 and reset information.....                                   | 35 |
| • Changed <a href="#">セクション 7.6</a> to include multiple DDRs.....   | 35 |
| • Changed <a href="#">図 7-7</a> and <a href="#">図 7-8</a> to include alternate SWB1_2 Timing.....                   | 37 |
| • Changed SWB1_2 from: V3P3A to: V1P8U in <a href="#">表 7-10</a> .....  | 37 |
| • Changed VDDQ voltage to OTP Dependent and SWBx to SWB1_2 in <a href="#">表 7-11</a> .....                          | 40 |
| • Updated <a href="#">図 7-10</a> to include alternate SWB1_2 Timing.....  | 41 |
| • Changed <a href="#">セクション 7.3.5.5</a> to include alternate SWB1_2 Timing.....                                     | 42 |
| • Changed <a href="#">セクション 7.3.5.6</a> to include THERMTRIPB .....   | 43 |
| • Added the TPS65094x family OTP values to <a href="#">セクション 7.6</a> .....  | 48 |
| • Replaced VID values with link to full VID table in <a href="#">表 7-18</a> and <a href="#">表 7-19</a> .....        | 51 |
| • Updated naming of bits in the TEMPHOT register.....   | 68 |

## 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

## 重要なお知らせと免責事項

テキサス・インスツルメンツは、技術データと信頼性データ (データシートを含みます)、設計リソース (リファレンス デザインを含みます)、アプリケーションや設計に関する各種アドバイス、Web ツール、安全性情報、その他のリソースを、欠陥が存在する可能性のある「現状のまま」提供しており、商品性および特定目的に対する適合性の黙示保証、第三者の知的財産権の非侵害保証を含むいかなる保証も、明示的または黙示的にかかわらず拒否します。

これらのリソースは、テキサス・インスツルメンツ製品を使用する設計の経験を積んだ開発者への提供を意図したものです。(1) お客様のアプリケーションに適した テキサス・インスツルメンツ製品の選定、(2) お客様のアプリケーションの設計、検証、試験、(3) お客様のアプリケーションに該当する各種規格や、その他のあらゆる安全性、セキュリティ、規制、または他の要件への確実な適合に関する責任を、お客様のみが単独で負うものとします。

上記の各種リソースは、予告なく変更される可能性があります。これらのリソースは、リソースで説明されている テキサス・インスツルメンツ製品を使用するアプリケーションの開発の目的でのみ、テキサス・インスツルメンツはその使用をお客様に許諾します。これらのリソースに関して、他の目的で複製することや掲載することは禁止されています。テキサス・インスツルメンツや第三者の知的財産権のライセンスが付与されている訳ではありません。お客様は、これらのリソースを自身で使用した結果発生するあらゆる申し立て、損害、費用、損失、責任について、テキサス・インスツルメンツおよびその代理人を完全に補償するものとし、テキサス・インスツルメンツは一切の責任を拒否します。

テキサス・インスツルメンツの製品は、[テキサス・インスツルメンツの販売条件](#)、または [ti.com](https://www.ti.com) やかかる テキサス・インスツルメンツ製品の関連資料などのいずれかを通じて提供する適用可能な条項の下で提供されています。テキサス・インスツルメンツがこれらのリソースを提供することは、適用されるテキサス・インスツルメンツの保証または他の保証の放棄の拡大や変更を意味するものではありません。

お客様がいかなる追加条項または代替条項を提案した場合でも、テキサス・インスツルメンツはそれらに異議を唱え、拒否します。

郵送先住所: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265  
Copyright © 2025, Texas Instruments Incorporated

**PACKAGING INFORMATION**

| Orderable part number           | Status<br>(1) | Material type<br>(2) | Package   Pins  | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|---------------------------------|---------------|----------------------|-----------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| <a href="#">TPS650940A0RSKR</a> | Active        | Production           | VQFN (RSK)   64 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | T650940A0<br>PG1.0  |
| TPS650940A0RSKR.A               | Active        | Production           | VQFN (RSK)   64 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | T650940A0<br>PG1.0  |
| <a href="#">TPS650940A0RSKT</a> | Active        | Production           | VQFN (RSK)   64 | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | T650940A0<br>PG1.0  |
| TPS650940A0RSKT.A               | Active        | Production           | VQFN (RSK)   64 | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | T650940A0<br>PG1.0  |
| <a href="#">TPS650941A0RSKR</a> | Active        | Production           | VQFN (RSK)   64 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | T650941A0<br>PG1.0  |
| TPS650941A0RSKR.A               | Active        | Production           | VQFN (RSK)   64 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | T650941A0<br>PG1.0  |
| <a href="#">TPS650941A0RSKT</a> | Active        | Production           | VQFN (RSK)   64 | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | T650941A0<br>PG1.0  |
| TPS650941A0RSKT.A               | Active        | Production           | VQFN (RSK)   64 | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | T650941A0<br>PG1.0  |
| <a href="#">TPS650942A0RSKR</a> | Active        | Production           | VQFN (RSK)   64 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | T650942A0<br>PG1.0  |
| TPS650942A0RSKR.A               | Active        | Production           | VQFN (RSK)   64 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | T650942A0<br>PG1.0  |
| <a href="#">TPS650942A0RSKT</a> | Active        | Production           | VQFN (RSK)   64 | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | T650942A0<br>PG1.0  |
| TPS650942A0RSKT.A               | Active        | Production           | VQFN (RSK)   64 | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | T650942A0<br>PG1.0  |
| <a href="#">TPS650944A0RSKR</a> | Active        | Production           | VQFN (RSK)   64 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | T650944A0<br>PG1.0  |
| TPS650944A0RSKR.A               | Active        | Production           | VQFN (RSK)   64 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | T650944A0<br>PG1.0  |
| <a href="#">TPS650944A0RSKT</a> | Active        | Production           | VQFN (RSK)   64 | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | T650944A0<br>PG1.0  |
| TPS650944A0RSKT.A               | Active        | Production           | VQFN (RSK)   64 | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | T650944A0<br>PG1.0  |

| Orderable part number           | Status<br>(1) | Material type<br>(2) | Package   Pins  | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|---------------------------------|---------------|----------------------|-----------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| <a href="#">TPS650945A0RSKR</a> | Active        | Production           | VQFN (RSK)   64 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | T650945A0<br>PG1.0  |
| TPS650945A0RSKR.A               | Active        | Production           | VQFN (RSK)   64 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | T650945A0<br>PG1.0  |
| <a href="#">TPS650945A0RSKT</a> | Active        | Production           | VQFN (RSK)   64 | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | T650945A0<br>PG1.0  |
| TPS650945A0RSKT.A               | Active        | Production           | VQFN (RSK)   64 | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | T650945A0<br>PG1.0  |
| <a href="#">TPS650947A0RSKR</a> | Active        | Production           | VQFN (RSK)   64 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | T650947A0<br>PG1.0  |
| TPS650947A0RSKR.A               | Active        | Production           | VQFN (RSK)   64 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | T650947A0<br>PG1.0  |
| <a href="#">TPS650947A0RSKT</a> | Active        | Production           | VQFN (RSK)   64 | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | T650947A0<br>PG1.0  |
| TPS650947A0RSKT.A               | Active        | Production           | VQFN (RSK)   64 | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | T650947A0<br>PG1.0  |

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

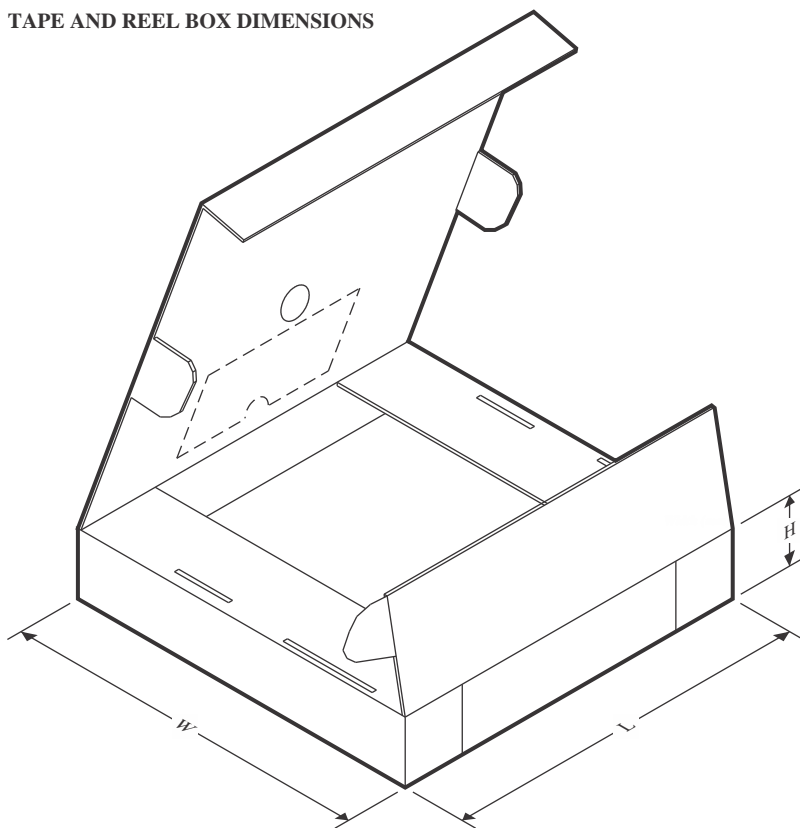
## TAPE AND REEL INFORMATION



\*All dimensions are nominal

| Device          | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-----------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TPS650940A0RSKR | VQFN         | RSK             | 64   | 2000 | 330.0              | 16.4               | 8.3     | 8.3     | 1.1     | 12.0    | 16.0   | Q2            |
| TPS650940A0RSKT | VQFN         | RSK             | 64   | 250  | 180.0              | 16.4               | 8.3     | 8.3     | 1.1     | 12.0    | 16.0   | Q2            |
| TPS650941A0RSKR | VQFN         | RSK             | 64   | 2000 | 330.0              | 16.4               | 8.3     | 8.3     | 1.1     | 12.0    | 16.0   | Q2            |
| TPS650941A0RSKT | VQFN         | RSK             | 64   | 250  | 180.0              | 16.4               | 8.3     | 8.3     | 1.1     | 12.0    | 16.0   | Q2            |
| TPS650942A0RSKR | VQFN         | RSK             | 64   | 2000 | 330.0              | 16.4               | 8.3     | 8.3     | 1.1     | 12.0    | 16.0   | Q2            |
| TPS650942A0RSKT | VQFN         | RSK             | 64   | 250  | 180.0              | 16.4               | 8.3     | 8.3     | 1.1     | 12.0    | 16.0   | Q2            |
| TPS650944A0RSKR | VQFN         | RSK             | 64   | 2000 | 330.0              | 16.4               | 8.3     | 8.3     | 1.1     | 12.0    | 16.0   | Q2            |
| TPS650944A0RSKT | VQFN         | RSK             | 64   | 250  | 180.0              | 16.4               | 8.3     | 8.3     | 1.1     | 12.0    | 16.0   | Q2            |
| TPS650945A0RSKR | VQFN         | RSK             | 64   | 2000 | 330.0              | 16.4               | 8.3     | 8.3     | 1.1     | 12.0    | 16.0   | Q2            |
| TPS650945A0RSKT | VQFN         | RSK             | 64   | 250  | 180.0              | 16.4               | 8.3     | 8.3     | 1.1     | 12.0    | 16.0   | Q2            |
| TPS650947A0RSKR | VQFN         | RSK             | 64   | 2000 | 330.0              | 16.4               | 8.3     | 8.3     | 1.1     | 12.0    | 16.0   | Q2            |
| TPS650947A0RSKT | VQFN         | RSK             | 64   | 250  | 180.0              | 16.4               | 8.3     | 8.3     | 1.1     | 12.0    | 16.0   | Q2            |

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

| Device          | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|-----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TPS650940A0RSKR | VQFN         | RSK             | 64   | 2000 | 367.0       | 367.0      | 38.0        |
| TPS650940A0RSKT | VQFN         | RSK             | 64   | 250  | 210.0       | 185.0      | 35.0        |
| TPS650941A0RSKR | VQFN         | RSK             | 64   | 2000 | 367.0       | 367.0      | 38.0        |
| TPS650941A0RSKT | VQFN         | RSK             | 64   | 250  | 210.0       | 185.0      | 35.0        |
| TPS650942A0RSKR | VQFN         | RSK             | 64   | 2000 | 367.0       | 367.0      | 38.0        |
| TPS650942A0RSKT | VQFN         | RSK             | 64   | 250  | 210.0       | 185.0      | 35.0        |
| TPS650944A0RSKR | VQFN         | RSK             | 64   | 2000 | 367.0       | 367.0      | 38.0        |
| TPS650944A0RSKT | VQFN         | RSK             | 64   | 250  | 210.0       | 185.0      | 35.0        |
| TPS650945A0RSKR | VQFN         | RSK             | 64   | 2000 | 367.0       | 367.0      | 38.0        |
| TPS650945A0RSKT | VQFN         | RSK             | 64   | 250  | 210.0       | 185.0      | 35.0        |
| TPS650947A0RSKR | VQFN         | RSK             | 64   | 2000 | 367.0       | 367.0      | 38.0        |
| TPS650947A0RSKT | VQFN         | RSK             | 64   | 250  | 210.0       | 185.0      | 35.0        |

## GENERIC PACKAGE VIEW

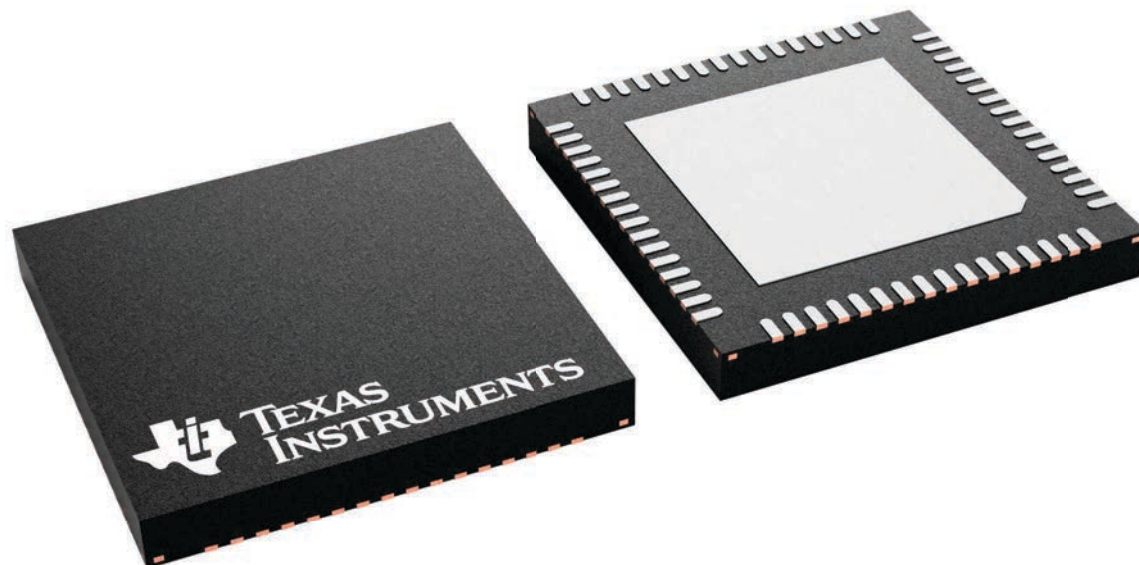
**RSK 64**

**VQFN - 1 mm max height**

8 x 8, 0.4 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

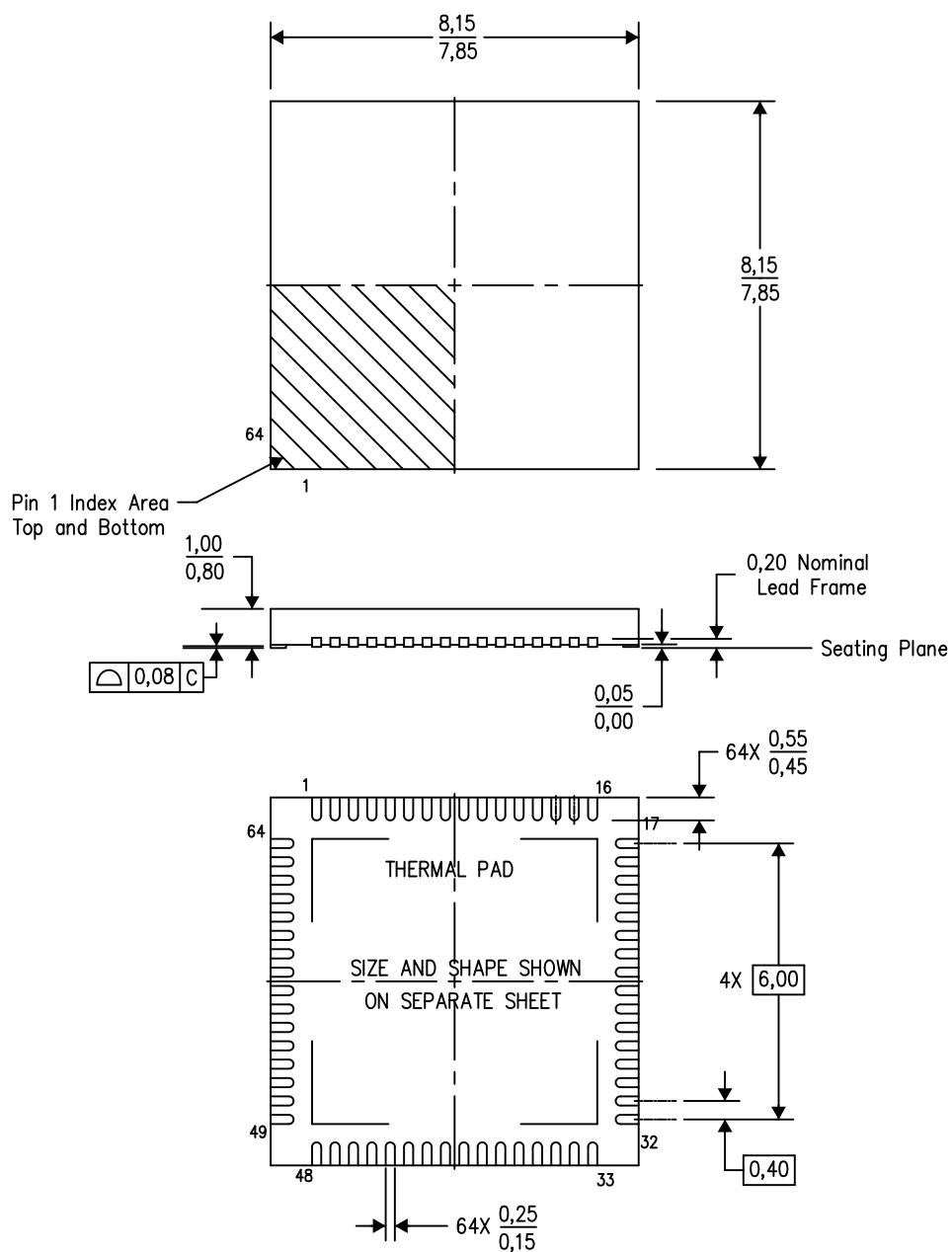
This image is a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.





RSK (S-PVQFN-N64)

PLASTIC QUAD FLATPACK NO-LEAD



Bottom View

4207547/C 04/12

- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5–1994.
  - B. This drawing is subject to change without notice.
  - C. QFN (Quad Flatpack No–Lead) Package configuration.
  - D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
  - E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.

RSK (S-PVQFN-N64)

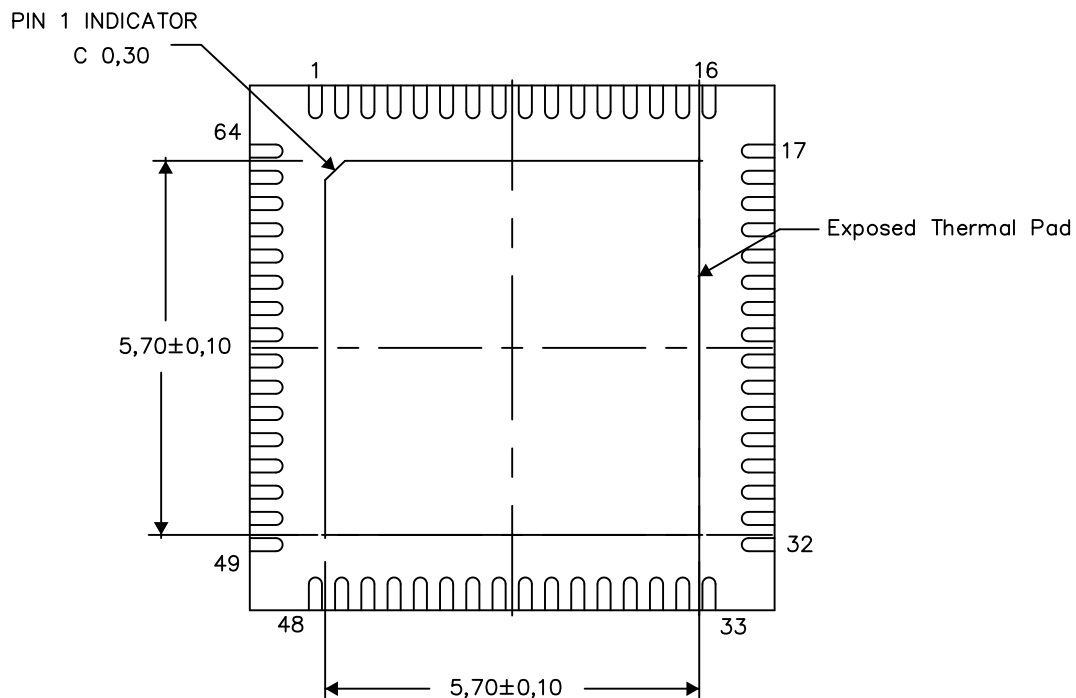
PLASTIC QUAD FLATPACK NO-LEAD

## THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at [www.ti.com](http://www.ti.com).

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

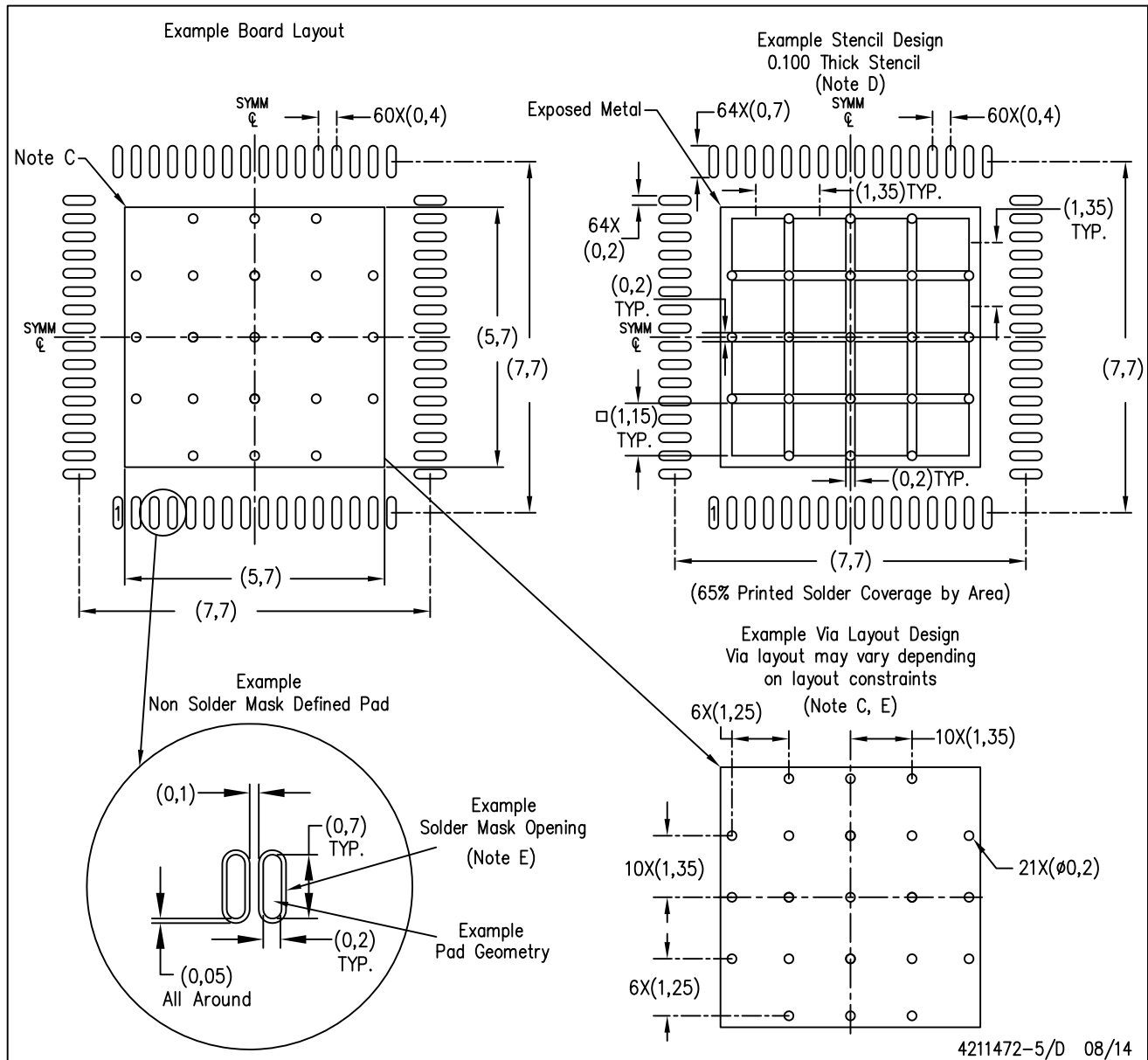
Exposed Thermal Pad Dimensions

4208001-5/H 08/14

NOTE: A. All linear dimensions are in millimeters

RSK (S-PVQFN-N64)

PLASTIC QUAD FLATPACK NO-LEAD



- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack Packages, Texas Instruments Literature No. SCBA017, SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at [www.ti.com](http://www.ti.com) <<http://www.ti.com>>.
  - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
  - Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for any larger diameter vias placed in the thermal pad.

## 重要なお知らせと免責事項

TI は、技術データと信頼性データ (データシートを含みます)、設計リソース (リファレンス デザインを含みます)、アプリケーションや設計に関する各種アドバイス、Web ツール、安全性情報、その他のリソースを、欠陥が存在する可能性のある「現状のまま」提供しており、商品性および特定目的に対する適合性の黙示保証、第三者の知的財産権の非侵害保証を含むいかなる保証も、明示的または黙示的にかかわらず拒否します。

これらのリソースは、TI 製品を使用する設計の経験を積んだ開発者への提供を意図したものです。(1) お客様のアプリケーションに適した TI 製品の選定、(2) お客様のアプリケーションの設計、検証、試験、(3) お客様のアプリケーションに該当する各種規格や、その他のあらゆる安全性、セキュリティ、規制、または他の要件への確実な適合に関する責任を、お客様のみが単独で負うものとしします。

上記の各種リソースは、予告なく変更される可能性があります。これらのリソースは、リソースで説明されている TI 製品を使用するアプリケーションの開発の目的でのみ、TI はその使用をお客様に許諾します。これらのリソースに関して、他の目的で複製することや掲載することは禁止されています。TI や第三者の知的財産権のライセンスが付与されている訳ではありません。お客様は、これらのリソースを自身で使用した結果発生するあらゆる申し立て、損害、費用、損失、責任について、TI およびその代理人を完全に補償するものとし、TI は一切の責任を拒否します。

TI の製品は、[TI の販売条件](#)、[TI の総合的な品質ガイドライン](#)、[ti.com](https://www.ti.com) または TI 製品などに関連して提供される他の適用条件に従い提供されます。TI がこれらのリソースを提供することは、適用される TI の保証または他の保証の放棄の拡大や変更を意味するものではありません。TI がカスタム、またはカスタマー仕様として明示的に指定していない限り、TI の製品は標準的なカタログに掲載される汎用機器です。

お客様がいかなる追加条項または代替条項を提案する場合も、TI はそれらに異議を唱え、拒否します。

Copyright © 2025, Texas Instruments Incorporated

最終更新日：2025 年 10 月